

STM32F302xB STM32F302xC

ARM[®]-based Cortex[®]-M4 32b MCU+FPU, up to 256KB Flash+ 40KB SRAM, 2 ADCs, 1 DAC ch., 4 comp, 2 PGA, timers, 2.0-3.6 V

Features

- Core: ARM[®] Cortex[®]-M4 32-bit CPU with FPU (72 MHz max), single-cycle multiplication and HW division, DSP instruction and MPU (memory protection unit)
- Operating conditions: .
- V_{DD}, V_{DDA} voltage range: 2.0 V to 3.6 V
- Memories
 - 128 to 256 Kbytes of Flash memory
 - Up to 40 Kbytes of SRAM, with HW parity check implemented on the first 16 Kbytes.
- CRC calculation unit
- Reset and supply management
 - Power-on/Power-down reset (POR/PDR)
 - Programmable voltage detector (PVD)
 - Low-power modes: Sleep, Stop and Standby
 - V_{BAT} supply for RTC and backup registers
- Clock management
 - 4 to 32 MHz crystal oscillator
 - 32 kHz oscillator for RTC with calibration
 - Internal 8 MHz RC with x 16 PLL option
 - Internal 40 kHz oscillator
- Up to 87 fast I/Os
 - All mappable on external interrupt vectors
- Several 5 V-tolerant
- Interconnect matrix
- 12-channel DMA controller
- Two ADCs 0.20 µS (up to 17 channels) with selectable resolution of 12/10/8/6 bits, 0 to 3.6 V conversion range, single ended/differential input, separate analog supply from 2 to 3.6 V
- One 12-bit DAC channel with analog supply from 2.4 to 3.6 V
- Four fast rail-to-rail analog comparators with analog supply from 2 to 3.6 V
- Two operational amplifiers that can be used in PGA mode, all terminals accessible with analog supply from 2.4 to 3.6 V
- Up to 24 capacitive sensing channels supporting touchkey, linear and rotary touch sensors





Datasheet - production data

- Up to 11 timers
 - One 32-bit timer and two 16-bit timers with up to 4 IC/OC/PWM or pulse counter and guadrature (incremental) encoder input
 - One 16-bit 6-channel advanced-control timer, with up to 6 PWM channels, deadtime generation and emergency stop
 - One 16-bit timer with 2 IC/OCs, 1 OCN/PWM, deadtime generation and emergency stop
 - Two 16-bit timers with IC/OC/OCN/PWM. deadtime generation and emergency stop
 - Two watchdog timers (independent, window)
 - SysTick timer: 24-bit downcounter
 - One 16-bit basic timer to drive the DAC
- Calendar RTC with Alarm, periodic wakeup from Stop/Standby
- Communication interfaces
 - CAN interface (2.0B Active)
 - Two I²C Fast mode plus (1 Mbit/s) with 20 mA current sink, SMBus/PMBus, wakeup from STOP
 - Up to five USART/UARTs (ISO 7816 interface, LIN, IrDA, modem control)
 - Up to three SPIs, two with multiplexed half/full duplex I2S interface, 4 to 16 programmable bit frames
 - USB 2.0 full speed interface
 - Infrared transmitter
- Serial wire debug, Cortex[®]-M4 with FPU ETM, JTAG
- 96-bit unique ID

Table 1. Device summary

Reference	Part number
STM32F302xB	STM32F302CB, STM32F302RB, STM32F302VB
STM32F302xC	STM32F302CC, STM32F302RC, STM32F302VC

This is information on a product in full production.

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1 Introduction

This datasheet provides the ordering information and mechanical device characteristics of the STM32F302xB/STM32F302xC microcontrollers.

This STM32F302xB/STM32F302xC datasheet should be read in conjunction with the STM32F302xx reference manual (RM0365). The reference manual is available from the STMicroelectronics website *www.st.com*.

For information on the Cortex[®]-M4 core with FPU, please refer to:

- **Cortex[®]-M4 with FPU Technical Reference Manual**, available from ARM website www.arm.com.
- STM32F3xxx and STM32F4xxx Cortex[®]-M4 programming manual (PM0214) available from our website *www.st.com*.



2 Description

The STM32F302xB/STM32F302xC family is based on the high-performance ARM[®] Cortex[®]-M4 32-bit RISC core with FPU operating at a frequency of up to 72 MHz, and embedding a floating point unit (FPU), a memory protection unit (MPU) and an embedded trace macrocell (ETM). The family incorporates high-speed embedded memories (up to 256 Kbytes of Flash memory, up to 40 Kbytes of SRAM) and an extensive range of enhanced I/Os and peripherals connected to two APB buses.

The devices offer up to two fast 12-bit ADCs (5 Msps), four comparators, two operational amplifiers, up to one DAC channel, a low-power RTC, up to five general-purpose 16-bit timers, one general-purpose 32-bit timer, and one timer dedicated to motor control. They also feature standard and advanced communication interfaces: up to two I²Cs, up to three SPIs (two SPIs are with multiplexed full-duplex I2Ss), three USARTs, up to two UARTs, CAN and USB. To achieve audio class accuracy, the I2S peripherals can be clocked via an external PLL.

The STM32F302xB/STM32F302xC family operates in the -40 to +85 °C and -40 to +105 °C temperature ranges from a 2.0 to 3.6 V power supply. A comprehensive set of power-saving mode allows the design of low-power applications.

The STM32F302xB/STM32F302xC family offers devices in three packages ranging from 48 pins to 100 pins.

The set of included peripherals changes with the device chosen.



Perip	STM32F302Cx		STM32F302Rx		STM32F302Vx		
Flash (Kbytes)		128	256	128	256	128	256
SRAM (Kbytes)	on data bus	32	40	32	40	32	40
	Advanced control	1 (16-bit)					
Timers General purpose				5 (16-b 1 (32-b			
	Basic			1 (16-b	oit)		
PWM channels (all) ⁽¹⁾			26			
PWM channels (complementary)	except			20			
	SPI (I2S) ⁽²⁾			3 (2)			
	l ² C			2			
Communication	USART			3			
interfaces	UART	0 2					
	CAN			1			
	USB			1			
0.510	Normal I/Os (TC, TTa)	20 27		7	45		
GPIOs	5-volt tolerant I/Os (FT, FTf)	17 25		42	2		
DMA channels		12					
Capacitive sensing channels		17 18		24	1		
12-bit ADCs		2					
Number of channels		9 16		17	7		
12-bit DAC chan	nels	1					
Analog comparat	tor	4					
Operational amplifiers		2					
CPU frequency		72 MHz					
Operating voltage	е	2.0 to 3.6 V					
Operating temperature		Ambient operating temperature: - 40 to 85 °C / - 40 to 105 °C Junction temperature: - 40 to 125 °C					
Packages		LQF	P48	LQF	P64	LQFF	2100

1. This total number considers also the PWMs generated on the complementary output channels

2. The SPI interfaces can work in an exclusive way in either the SPI mode or the I^2S audio mode.





Figure 1.STM32F302xB/STM32F302xC block diagram

1. AF: alternate function on I/O pins.



3 Functional overview

3.1 ARM[®] Cortex[®]-M4 core with FPU with embedded Flash and SRAM

The ARM Cortex-M4 processor with FPU is the latest generation of ARM processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts.

The ARM Cortex-M4 32-bit RISC processor with FPU features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The processor supports a set of DSP instructions which allow efficient signal processing and complex algorithm execution.

Its single precision FPU speeds up software development by using metalanguage development tools, while avoiding saturation.

With its embedded ARM core, the STM32F302xB/STM32F302xC family is compatible with all ARM tools and software.

Figure 1 shows the general block diagram of the STM32F302xB/STM32F302xC family devices.

3.2 Memory protection unit (MPU)

The memory protection unit (MPU) is used to separate the processing of tasks from the data protection. The MPU can manage up to 8 protection areas that can all be further divided up into 8 subareas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The memory protection unit is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

3.3 Embedded Flash memory

All STM32F302xB/STM32F302xC devices feature up to 256 Kbytes of embedded Flash memory available for storing programs and data. The Flash memory access time is adjusted to the CPU clock frequency (0 wait state from 0 to 24 MHz, 1 wait state from 24 to 48 MHz and 2 wait states above).



3.4 Embedded SRAM

STM32F302xB/STM32F302xC devices feature up to 40 Kbytes of embedded SRAM with hardware parity check on first 16 Kbytes of SRAM. The memory can be accessed in read/write at CPU clock speed with 0 wait states.

3.5 Boot modes

At startup, Boot0 pin and Boot1 option bit are used to select one of three boot options:

- Boot from user Flash
- Boot from system memory
- Boot from embedded SRAM

The boot loader is located in the system memory. It is used to reprogram the Flash memory by using USART1 (PA9/PA10), USART2 (PD5/PD6) or USB (PA11/PA12) through DFU (device firmware upgrade).

3.6 Cyclic redundancy check (CRC)

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code using a configurable generator polynomial value and size.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at linktime and stored at a given memory location.



3.7 **Power management**

3.7.1 Power supply schemes

- V_{SS} , V_{DD} = 2.0 to 3.6 V: external power supply for I/Os and the internal regulator. It is provided externally through V_{DD} pins.
- V_{SSA}, V_{DDA} = 2.0 to 3.6 V: external analog power supply for ADC, DAC, comparators operational amplifiers, reset blocks, RCs and PLL. The minimum voltage to be applied to V_{DDA} differs from one analog peripheral to another. *Table 3* provides the summary of the V_{DDA} ranges for analog peripherals. The V_{DDA} voltage level must be always greater or equal to the V_{DD} voltage level and must be provided first.
- V_{BAT} = 1.65 to 3.6 V: power supply for RTC, external clock 32 kHz oscillator and backup registers (through power switch) when V_{DD} is not present.

Analog peripheral	Minimum V _{DDA} supply	Maximum V _{DDA} supply	
ADC / COMP	2.0 V	3.6 V	
DAC / OPAMP	2.4 V	3.6V	

 Table 3. External analog supply values for analog peripherals

3.7.2 Power supply supervision

The device has an integrated power-on reset (POR) and power-down reset (PDR) circuits. They are always active, and ensure proper operation above a threshold of 2 V. The device remains in reset mode when the monitored supply voltage is below a specified threshold, VPOR/PDR, without the need for an external reset circuit.

- The POR monitors only the V_{DD} supply voltage. During the startup phase it is required that V_{DDA} should arrive first and be greater than or equal to V_{DD}.
- The PDR monitors both the V_{DD} and V_{DDA} supply voltages, however the V_{DDA} power supply supervisor can be disabled (by programming a dedicated Option bit) to reduce the power consumption if the application design ensures that V_{DDA} is higher than or equal to V_{DD}.

The device features an embedded programmable voltage detector (PVD) that monitors the V_{DD} power supply and compares it to the VPVD threshold. An interrupt can be generated when V_{DD} drops below the V_{PVD} threshold and/or when V_{DD} is higher than the V_{PVD} threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

3.7.3 Voltage regulator

The regulator has three operation modes: main (MR), low-power (LPR), and power-down.

- The MR mode is used in the nominal regulation mode (Run)
- The LPR mode is used in Stop mode.
- The power-down mode is used in Standby mode: the regulator output is in high impedance, and the kernel circuitry is powered down thus inducing zero consumption.

The voltage regulator is always enabled after reset. It is disabled in Standby mode.



3.7.4 Low-power modes

The STM32F302xB/STM32F302xC supports three low-power modes to achieve the best compromise between low-power consumption, short startup time and available wakeup sources:

Sleep mode

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.

• Stop mode

Stop mode achieves the lowest power consumption while retaining the content of SRAM and registers. All clocks in the 1.8 V domain are stopped, the PLL, the HSI RC and the HSE crystal oscillators are disabled. The voltage regulator can also be put either in normal or in low-power mode.

The device can be woken up from Stop mode by any of the EXTI line. The EXTI line source can be one of the 16 external lines, the PVD output, the USB wakeup, the RTC alarm, COMPx, I2Cx or U(S)ARTx.

• Standby mode

The Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire 1.8 V domain is powered off. The PLL, the HSI RC and the HSE crystal oscillators are also switched off. After entering Standby mode, SRAM and register contents are lost except for registers in the Backup domain and Standby circuitry.

The device exits Standby mode when an external reset (NRST pin), an IWDG reset, a rising edge on the WKUP pin or an RTC alarm occurs.

Note: The RTC, the IWDG and the corresponding clock sources are not stopped by entering Stop or Standby mode.

3.8 Interconnect matrix

Several peripherals have direct connections between them. This allows autonomous communication between peripherals, saving CPU resources thus power supply consumption. In addition, these hardware connections allow fast and predictable latency.

Interconnect source	Interconnect destination	Interconnect action
	TIMx	Timers synchronization or chaining
TIMx	ADCx DAC1	Conversion triggers
	DMA	Memory to memory transfer trigger
	Compx	Comparator output blanking
COMPx	COMPx TIMx Timer input: OCREF_CLR input, inpu	
ADCx	TIMx	Timer triggered by analog watchdog

Table 4. STM32F302xB/STM32F302xC peripheral interconnect matrix



Interconnect source destination		Interconnect action	
GPIO RTCCLK HSE/32 MC0	TIM16	Clock source used as input channel for HSI and LSI calibration	
CSS CPU (hard fault) COMPx PVD GPIO	TIM1, TIM15, 16, 17	Timer break	
	TIMx	External trigger, timer break	
GPIO	ADCx DAC1	Conversion external trigger	
DAC1	COMPx	Comparator inverting input	

Table 4. STM32F302xB/STM32F302xC peripheral interconnect matrix (continued)

Note: For more details about the interconnect actions, please refer to the corresponding sections in the reference manual RM0365.



3.9 Clocks and startup

System clock selection is performed on startup, however the internal RC 8 MHz oscillator is selected as default CPU clock on reset. An external 4-32 MHz clock can be selected, in which case it is monitored for failure. If failure is detected, the system automatically switches back to the internal RC oscillator. A software interrupt is generated if enabled. Similarly, full interrupt management of the PLL clock entry is available when necessary (for example with failure of an indirectly used external oscillator).

Several prescalers allow to configure the AHB frequency, the high speed APB (APB2) and the low speed APB (APB1) domains. The maximum frequency of the AHB and the high speed APB domains is 72 MHz, while the maximum allowed frequency of the low speed APB domain is 36 MHz.



Figure 2.Clock tree



Δ7/

3.10 General-purpose input/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high current capable except for analog inputs.

The I/Os alternate function configuration can be locked if needed following a specific sequence in order to avoid spurious writing to the I/Os registers.

Fast I/O handling allows I/O toggling up to 36 MHz.

3.11 Direct memory access (DMA)

The flexible general-purpose DMA is able to manage memory-to-memory, peripheral-tomemory and memory-to-peripheral transfers. The DMA controller supports circular buffer management, avoiding the generation of interrupts when the controller reaches the end of the buffer.

Each of the 12 DMA channels is connected to dedicated hardware DMA requests, with software trigger support for each channel. Configuration is done by software and transfer sizes between source and destination are independent.

The DMA can be used with the main peripherals: SPI, I²C, USART, general-purpose timers, DAC and ADC.

3.12 Interrupts and events

3.12.1 Nested vectored interrupt controller (NVIC)

The STM32F302xB/STM32F302xC devices embed a nested vectored interrupt controller (NVIC) able to handle up to 66 maskable interrupt channels and 16 priority levels.

The NVIC benefits are the following:

- Closely coupled NVIC gives low latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Closely coupled NVIC core interface
- Allows early processing of interrupts
- Processing of late arriving higher priority interrupts
- Support for tail chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

The NVIC hardware block provides flexible interrupt management features with minimal interrupt latency.



3.13 Fast analog-to-digital converter (ADC)

Two fast analog-to-digital converters 5 MSPS, with selectable resolution between 12 and 6 bit, are embedded in the STM32F302xB/STM32F302xC family devices. The ADCs have up to 17 external channels (5 channels multiplexed between ADC1 and ADC2). Channels can be configured to be either single-ended input or differential input. The ADCs can perform conversions in single-shot or scan modes. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADCs have also internal channels: Temperature sensor connected to ADC1 channel 16, $V_{BAT/2}$ connected to ADC1 channel 17, Voltage reference V_{REFINT} connected to the 2 ADCs channel 18, VREFOPAMP1 connected to ADC1 channel 15 and VREFOPAMP2 connected to ADC2 channel 17.

Additional logic functions embedded in the ADC interface allow:

- Simultaneous sample and hold
- Interleaved sample and hold
- Single-shunt phase current reading techniques.

The ADC can be served by the DMA controller. 3 analog watchdogs per ADC are available.

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

The events generated by the general-purpose timers and the advanced-control timer (TIM1) can be internally connected to the ADC start trigger and injection trigger, respectively, to allow the application to synchronize A/D conversion and timers.

3.13.1 Temperature sensor

The temperature sensor (TS) generates a voltage $V_{\mbox{SENSE}}$ that varies linearly with temperature.

The temperature sensor is internally connected to the ADC1_IN16 input channel which is used to convert the sensor output voltage into a digital value.

The sensor provides good linearity but it has to be calibrated to obtain good overall accuracy of the temperature measurement. As the offset of the temperature sensor varies from chip to chip due to process variation, the uncalibrated internal temperature sensor is suitable for applications that detect temperature changes only.

To improve the accuracy of the temperature sensor measurement, each device is individually factory-calibrated by ST. The temperature sensor factory calibration data are stored by ST in the system memory area, accessible in read-only mode.

3.13.2 Internal voltage reference (V_{REFINT})

The internal voltage reference (V_{REFINT}) provides a stable (bandgap) voltage output for the ADC and Comparators. V_{REFINT} is internally connected to the ADCx_IN18, x=1...2 input channel. The precise voltage of V_{REFINT} is individually measured for each part by ST during production test and stored in the system memory area. It is accessible in read-only mode.



3.13.3 V_{BAT} battery voltage monitoring

This embedded hardware feature allows the application to measure the V_{BAT} battery voltage using the internal ADC channel ADC1_IN17. As the V_{BAT} voltage may be higher than V_{DDA}, and thus outside the ADC input range, the V_{BAT} pin is internally connected to a bridge divider by 2. As a consequence, the converted digital value is half the V_{BAT} voltage.

3.13.4 OPAMP reference voltage (VREFOPAMP)

Every OPAMP reference voltage can be measured using a corresponding ADC internal channel: VREFOPAMP1 connected to ADC1 channel 15, VREFOPAMP2 connected to ADC2 channel 17.

3.14 Digital-to-analog converter (DAC)

A single 12-bit buffered DAC channel can be used to convert digital signals into analog voltage signal outputs. The chosen design structure is composed of integrated resistor strings and an amplifier in inverting configuration.

This digital interface supports the following features:

- One DAC output channel
- 8-bit or 10-bit monotonic output
- Left or right data alignment in 12-bit mode
- Noise-wave generation
- Triangular-wave generation
- DMA capability
- External triggers for conversion

3.15 **Operational amplifier (OPAMP)**

The STM32F302xB/STM32F302xC embeds two operational amplifiers with external or internal follower routing and PGA capability (or even amplifier and filter capability with external components). When an operational amplifier is selected, an external ADC channel is used to enable output measurement.

The operational amplifier features:

- 8.2 MHz bandwidth
- 0.5 mA output capability
- Rail-to-rail input/output
- In PGA mode, the gain can be programmed to be 2, 4, 8 or 16.

3.16 Fast comparators (COMP)

The STM32F302xB/STM32F302xC devices embed four fast rail-to-rail comparators with programmable reference voltage (internal or external), hysteresis and speed (low speed for low-power) and with selectable output polarity.



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The reference voltage can be one of the following:

- External I/O
- DAC output pin
- Internal reference voltage or submultiple (1/4, 1/2, 3/4). Refer to *Table 28: Embedded internal reference voltage on page 59* for the value and precision of the internal reference voltage.

All comparators can wake up from STOP mode, generate interrupts and breaks for the timers and can be also combined per pair into a window comparator

3.17 Timers and watchdogs

The STM32F302xB/STM32F302xC includes one advanced control timer, up to six generalpurpose timers, one basic timer, two watchdog timers and a SysTick timer. The table below compares the features of the advanced control, general purpose and basic timers.

Timer type	Timer	Counter resolution	Counter type	Prescaler factor	DMA request generation	Capture/ compare Channels	Complementary outputs
Advanced	TIM1	16-bit	Up, Down, Up/Down	Any integer between 1 and 65536	Yes	4	Yes
General- purpose	TIM2	32-bit	Up, Down, Up/Down	Any integer between 1 and 65536	Yes	4	No
General- purpose	TIM3, TIM4	16-bit	Up, Down, Up/Down	Any integer between 1 and 65536	Yes	4	No
General- purpose	TIM15	16-bit	Up	Any integer between 1 and 65536	Yes	2	1
General- purpose	TIM16, TIM17	16-bit	Up	Any integer between 1 and 65536	Yes	1	1
Basic	TIM6	16-bit	Up	Any integer between 1 and 65536	Yes	0	No

Table 5. Timer feature comparison

Note: TIM1/8 can have PLL as clock source, and therefore can be clocked at 144 MHz.

3.17.1 Advanced timer (TIM1)

The advanced-control timer, TIM1, can be seen as a three-phase PWM multiplexed on six channels. It has a complementary PWM output with programmable inserted dead-times. It can also be seen as a complete general-purpose timer. The four independent channels can be used for:

- Input capture
- Output compare
- PWM generation (edge or center-aligned modes) with full modulation capability (0-100%)
- One-pulse mode output

In debug mode, the advanced-control timer counter can be frozen and the PWM outputs disabled to turn off any power switches driven by these outputs.

Many features are shared with those of the general-purpose TIM timers (described in *Section 3.17.2* using the same architecture, so the advanced-control timers can work together with the TIM timers via the Timer Link feature for synchronization or event chaining.

3.17.2 General-purpose timers (TIM2, TIM3, TIM4, TIM15, TIM16, TIM17)

There are up to six synchronizable general-purpose timers embedded in the STM32F302xB/STM32F302xC (see *Table 5* for differences). Each general-purpose timer can be used to generate PWM outputs, or act as a simple time base.

• TIM2, 3, and TIM4

These are full-featured general-purpose timers:

- TIM2 has a 32-bit auto-reload up/downcounter and 32-bit prescaler
- TIM3 and 4 have 16-bit auto-reload up/downcounters and 16-bit prescalers.

These timers all feature 4 independent channels for input capture/output compare, PWM or one-pulse mode output. They can work together, or with the other general-purpose timers via the Timer Link feature for synchronization or event chaining.

The counters can be frozen in debug mode.

All have independent DMA request generation and support quadrature encoders.

• TIM15, 16 and 17

These three timers general-purpose timers with mid-range features:

- They have 16-bit auto-reload upcounters and 16-bit prescalers.
- TIM15 has 2 channels and 1 complementary channel
- TIM16 and TIM17 have 1 channel and 1 complementary channel

All channels can be used for input capture/output compare, PWM or one-pulse mode output.

The timers can work together via the Timer Link feature for synchronization or event chaining. The timers have independent DMA request generation.

The counters can be frozen in debug mode.

3.17.3 Basic timer (TIM6)

This timer is mainly used for DAC trigger generation. It can also be used as a generic 16-bit time base.



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3.17.4 Independent watchdog (IWDG)

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from an independent 40 kHz internal RC and as it operates independently from the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free running timer for application timeout management. It is hardware or software configurable through the option bytes. The counter can be frozen in debug mode.

3.17.5 Window watchdog (WWDG)

The window watchdog is based on a 7-bit downcounter that can be set as free running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in debug mode.

3.17.6 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard down counter. It features:

- A 24-bit down counter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0.
- Programmable clock source

3.18 Real-time clock (RTC) and backup registers

The RTC and the 16 backup registers are supplied through a switch that takes power from either the V_{DD} supply when present or the V_{BAT} pin. The backup registers are sixteen 32-bit registers used to store 64 bytes of user application data when V_{DD} power is not present.

They are not reset by a system or power reset, or when the device wakes up from Standby mode.

The RTC is an independent BCD timer/counter.It supports the following features:

- Calendar with subsecond, seconds, minutes, hours (12 or 24 format), week day, date, month, year, in BCD (binary-coded decimal) format.
- Reference clock detection: a more precise second source clock (50 or 60 Hz) can be used to enhance the calendar precision.
- Automatic correction for 28, 29 (leap year), 30 and 31 days of the month.
- Two programmable alarms with wake up from Stop and Standby mode capability.
- On-the-fly correction from 1 to 32767 RTC clock pulses. This can be used to synchronize it with a master clock.
- Digital calibration circuit with 1 ppm resolution, to compensate for quartz crystal inaccuracy.
- Three anti-tamper detection pins with programmable filter. The MCU can be woken up from Stopand Standby modes on tamper event detection.
- Timestamp feature which can be used to save the calendar content. This function can be triggered by an event on the timestamp pin, or by a tamper event. The MCU can be woken up from Stop and Standby modes on timestamp event detection.



• 17-bit Auto-reload counter for periodic interrupt with wakeup from STOP/STANDBY capability.

The RTC clock sources can be:

- A 32.768 kHz external crystal
- A resonator or oscillator
- The internal low-power RC oscillator (typical frequency of 40 kHz)
- The high-speed external clock divided by 32.

3.19 Inter-integrated circuit interface (I²C)

Up to two I^2C bus interfaces can operate in multimaster and slave modes. They can support standard (up to 100 KHz), fast (up to 400 KHz) and fast mode + (up to 1 MHz) modes.

Both support 7-bit and 10-bit addressing modes, multiple 7-bit slave addresses (2 addresses, 1 with configurable mask). They also include programmable analog and digital noise filters.

	Analog filter	Digital filter
Pulse width of suppressed spikes	³ 50 ns	Programmable length from 1 to 15 I2C peripheral clocks
Benefits	Available in Stop mode	 Extra filtering capability vs. standard requirements. Stable length
Drawbacks	Variations depending on temperature, voltage, process	Wakeup from Stop on address match is not available when digital filter is enabled.

Table 6.Comparison of I2C analog and digital filters

In addition, they provide hardware support for SMBUS 2.0 and PMBUS 1.1: ARP capability, Host notify protocol, hardware CRC (PEC) generation/verification, timeouts verifications and ALERT protocol management. They also have a clock domain independent from the CPU clock, allowing the I2Cx (x=1,2) to wake up the MCU from Stop mode on address match.

The I2C interfaces can be served by the DMA controller.

Refer to *Table 7* for the features available in I2C1 and I2C2.

I2C features ⁽¹⁾	I2C1	I2C2
7-bit addressing mode		Х
10-bit addressing mode	Х	Х
Standard mode (up to 100 kbit/s)	Х	Х
Fast mode (up to 400 kbit/s)	Х	Х
Fast Mode Plus with 20mA output drive I/Os (up to 1 Mbit/s)	Х	Х
Independent clock	Х	Х



I2C features ⁽¹⁾	I2C1	I2C2
SMBus	Х	Х
Wakeup from STOP	X	Х

	Table 7.STM32F302xB/STM32F302xC I ² C	implementation	(continued)
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1. X = supported.

3.20 Universal synchronous/asynchronous receiver transmitter (USART)

The STM32F302xB/STM32F302xC devices have three embedded universal synchronous/asynchronous receiver transmitters (USART1, USART2 and USART3).

The USART interfaces are able to communicate at speeds of up to 9 Mbits/s.

They provide hardware management of the CTS and RTS signals, they support IrDA SIR ENDEC, the multiprocessor communication mode, the single-wire half-duplex communication mode and have LIN Master/Slave capability. The USART interfaces can be served by the DMA controller.

3.21 Universal asynchronous receiver transmitter (UART)

The STM32F302xB/STM32F302xC devices have 2 embedded universal asynchronous receiver transmitters (UART4, and UART5). The UART interfaces support IrDA SIR ENDEC, multiprocessor communication mode and single-wire half-duplex communication mode. The UART4 interface can be served by the DMA controller.

Refer to Table 8 for the features available in all U(S)ART interfaces.

USART modes/features ⁽¹⁾	USART1	USART2	USART3	UART4	UART5
Hardware flow control for modem	Х	Х	Х	-	-
Continuous communication using DMA	Х	Х	Х	Х	-
Multiprocessor communication	Х	Х	Х	Х	Х
Synchronous mode	Х	Х	Х	-	-
Smartcard mode	Х	Х	Х	-	-
Single-wire half-duplex communication	Х	Х	Х	Х	Х
IrDA SIR ENDEC block	Х	Х	Х	Х	Х
LIN mode	Х	Х	Х	Х	Х
Dual clock domain and wakeup from Stop mode	Х	Х	Х	Х	Х
Receiver timeout interrupt	Х	Х	Х	Х	Х
Modbus communication	Х	Х	Х	Х	Х
Auto baud rate detection	Х	Х	Х	-	-
Driver Enable	Х	Х	Х	-	-

Table 8.USART features

1. X = supported.



3.22 Serial peripheral interface (SPI)/Inter-integrated sound interfaces (I2S)

Up to three SPIs are able to communicate up to 18 Mbits/s in slave and master modes in full-duplex and half-duplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame size is configurable from 4 bits to 16 bits.

Two standard I2S interfaces (multiplexed with SPI2 and SPI3) supporting four different audio standards can operate as master or slave at half-duplex and full duplex communication modes. They can be configured to transfer 16 and 24 or 32 bits with 16-bit or 32-bit data resolution and synchronized by a specific signal. Audio sampling frequency from 8 kHz up to 192 kHz can be set by 8-bit programmable linear prescaler. When operating in master mode it can output a clock for an external audio component at 256 times the sampling frequency.

Refer to Table 9 for the features available in SPI1, SPI2 and SPI3.

SPI features ⁽¹⁾	SPI1	SPI2	SPI3
Hardware CRC calculation	Х	Х	Х
Rx/Tx FIFO	Х	Х	Х
NSS pulse mode	Х	Х	Х
I2S mode	-	Х	Х
TI mode	Х	Х	Х

1. X = supported.

3.23 Controller area network (CAN)

The CAN is compliant with specifications 2.0A and B (active) with a bit rate up to 1 Mbit/s. It can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers. It has three transmit mailboxes, two receive FIFOs with 3 stages and 14 scalable filter banks.

3.24 Universal serial bus (USB)

The STM32F302xB/STM32F302xC devices embed an USB device peripheral compatible with the USB full-speed 12 Mbs. The USB interface implements a full-speed (12 Mbit/s) function interface. It has software-configurable endpoint setting and suspend/resume support. The dedicated 48 MHz clock is generated from the internal main PLL (the clock source must use a HSE crystal oscillator). The USB has a dedicated 512-bytes SRAM memory for data transmission and reception.



3.25 Infrared Transmitter

The STM32F302xB/STM32F302xC devices provide an infrared transmitter solution. The solution is based on internal connections between TIM16 and TIM17 as shown in the figure below.

TIM17 is used to provide the carrier frequency and TIM16 provides the main signal to be sent. The infrared output signal is available on PB9 or PA13.

To generate the infrared remote control signals, TIM16 channel 1 and TIM17 channel 1 must be properly configured to generate correct waveforms. All standard IR pulse modulation modes can be obtained by programming the two timers output compare channels.



Figure 3.Infrared transmitter

3.26 Touch sensing controller (TSC)

The STM32F302xB/STM32F302xC devices provide a simple solution for adding capacitive sensing functionality to any application. These devices offer up to 24 capacitive sensing channels distributed over 8 analog I/O groups.

Capacitive sensing technology is able to detect the presence of a finger near a sensor which is protected from direct touch by a dielectric (glass, plastic, ...). The capacitive variation introduced by the finger (or any conductive object) is measured using a proven implementation based on a surface charge transfer acquisition principle. It consists of charging the sensor capacitance and then transferring a part of the accumulated charges into a sampling capacitor until the voltage across this capacitor has reached a specific threshold. To limit the CPU bandwidth usage this acquisition is directly managed by the hardware touch sensing controller and only requires few external components to operate.

The touch sensing controller is fully supported by the STMTouch touch sensing firmware library which is free to use and allows touch sensing functionality to be implemented reliably in the end application.



Group	Capacitive sensing signal name	Pin name	Group	Capacitive sensing signal name	Pin name
	TSC_G1_IO1	PA0		TSC_G5_IO1	PB3
1	TSC_G1_IO2	PA1	5	TSC_G5_IO2	PB4
1	TSC_G1_IO3	PA2	5	TSC_G5_IO3	PB6
	TSC_G1_IO4	PA3		TSC_G5_IO4	PB7
	TSC_G2_IO1	PA4		TSC_G6_IO1	PB11
2	TSC_G2_IO2	PA5	6	TSC_G6_IO2	PB12
2	TSC_G2_IO3	PA6	0	TSC_G6_IO3	PB13
	TSC_G2_IO4	PA7		TSC_G6_IO4	PB14
	TSC_G3_IO1	PC5	PC5 PB0 PB1	TSC_G7_IO1	PE2
3	TSC_G3_IO2	PB0		TSC_G7_IO2	PE3
5	TSC_G3_IO3	PB1		TSC_G7_IO3	PE4
	TSC_G3_IO4	PB2		TSC_G7_IO4	PE5
	TSC_G4_IO1 PA9		TSC_G8_IO1	PD12	
4	TSC_G4_IO2	PA10	8	TSC_G8_IO2	PD13
-	TSC_G4_IO3	PA13	0	TSC_G8_IO3	PD14
	TSC_G4_IO4	PA14		TSC_G8_IO4	PD15

Table 10.Capacitive sensing GPIOs available on STM32F302xB/STM32F302xC devices

Table 11.No. of capacitive sensing channels available on STM32F302xB/STM32F302xC devices

	Number of capacitive sensing channels				
Analog I/O group	STM32F302Vx	STM32F302Rx	STM32F302Cx		
G1	3	3	3		
G2	3	3	3		
G3	3	3	2		
G4	3	3	3		
G5	3	3	3		
G6	3	3	3		
G7	3	0	0		
G8	3	0	0		
Number of capacitive sensing channels	24	18	17		



3.27 Development support

3.27.1 Serial wire JTAG debug port (SWJ-DP)

The ARM SWJ-DP Interface is embedded, and is a combined JTAG and serial wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target.

The JTAG TMS and TCK pins are shared respectively with SWDIO and SWCLK and a specific sequence on the TMS pin is used to switch between JTAG-DP and SW-DP.

3.27.2 Embedded trace macrocell™

The ARM embedded trace macrocell provides a greater visibility of the instruction and data flow inside the CPU core by streaming compressed data at a very high rate from the STM32F302xB/STM32F302xC through a small number of ETM pins to an external hardware trace port analyzer (TPA) device. The TPA is connected to a host computer using a high-speed channel. Real-time instruction and data flow activity can be recorded and then formatted for display on the host computer running debugger software. TPA hardware is commercially available from common development tool vendors. It operates with third party debugger software tools.



4 Pinouts and pin description



Figure 4.STM32F302xB/STM32F302xC LQFP48 pinout





Figure 5.STM32F302xB/STM32F302xC LQFP64 pinout





Figure 6.STM32F302xB/STM32F302xC LQFP100 pinout



Na	me	Abbreviation Definition			
Pin name			Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name		
		S	Supply pin		
Pin	type	I	Input only pin		
		I/O	Input / output pin		
		FT	5 V tolerant I/O		
		FTf	FTf 5 V tolerant I/O, FM+ capable		
I/O atr	ucture	TTa 3.3 V tolerant I/O directly connected to ADC			
i/O str	uclure	TC Standard 3.3V I/O			
		B Dedicated BOOT0 pin			
		RST Bidirectional reset pin with embedded weak pull-up res			
Notes		Unless otherwise specified by a note, all I/Os are set as floating inputs d and after reset			
Alternate		Functions selected through GPIOx_AFR registers			
Pin functions	Additional functions	Functions	directly selected/enabled through peripheral registers		

Table 12.Legend/abbreviations used in the pinout table





Pin number			Pin name				Pin functions	
LQFP100	LQFP64	LQFP48	(function after reset)	Pin type I/O structure	I/O structu	Notes	Alternate functions	Additional functions
1	-	I	PE2	I/O	FT	(1)	TRACECK, TIM3_CH1, TSC_G7_IO1, EVENTOUT	-
2	-	-	PE3	I/O	FT	(1)	TRACED0, TIM3_CH2, TSC_G7_IO2, EVENTOUT	-
3	-	-	PE4	I/O	FT	(1)	TRACED1, TIM3_CH3, TSC_G7_IO3, EVENTOUT	-
4	-	-	PE5	I/O	FT	(1)	TRACED2, TIM3_CH4, TSC_G7_IO4, EVENTOUT	-
5	-	-	PE6	I/O	FT	(1)	TRACED3, EVENTOUT	WKUP3, RTC_TAMP3
6	1	1	V _{BAT}	S	-	-	Backup power supply	
7	2	2	PC13 ⁽²⁾	I/O	тс	-	TIM1_CH1N	WKUP2, RTC_TAMP1, RTC_TS, RTC_OUT
8	3	3	PC14 ⁽²⁾ OSC32_IN (PC14)	I/O	тс	-	-	OSC32_IN
9	4	4	PC15 ⁽²⁾ OSC32_ OUT (PC15)	I/O	тс	-	-	OSC32_OUT
10	-	-	PF9	I/O	FT	(1)	TIM15_CH1, SPI2_SCK, EVENTOUT	-
11	-	-	PF10	I/O	FT	(1)	TIM15_CH2, SPI2_SCK, EVENTOUT	-
12	5	5	PF0- OSC_IN (PF0)	I/O	FTf	-	TIM1_CH3N, I2C2_SDA,	OSC_IN
13	6	6	PF1- OSC_OUT (PF1)	I/O	FTf	-	I2C2_SCL	OSC_OUT
14	7	7	NRST	I/O	RST		Device reset input / internal reset output (active low)	
15	8	-	PC0	I/O	TTa	(1)	EVENTOUT	ADC12_IN6
16	9	-	PC1	I/O	TTa	(1)	EVENTOUT	ADC12_IN7
17	10	-	PC2	I/O	TTa	(1)	EVENTOUT	ADC12_IN8
18	11	-	PC3	I/O	TTa	(1)	TIM1_BKIN2, EVENTOUT	ADC12_IN9
19	-	-	PF2	I/O	TTa	(1)	EVENTOUT	ADC12_IN10
20	12	8	VSSA/ VREF-	S	-	-	Analog ground/Negative reference voltage	
21	-	-	VREF+ ⁽³⁾	S	-	-	Positive reference voltage	
22	-	-	VDDA	S	-	-	Analog power supply	
-	13	9	VDDA/ VREF+	S	-	-	Analog power supply/Positive reference voltage	

Table 13.STM32F302xB/STM32F302xC pin definitions



Pin number							M32F302xC pin definitions (continued) Pin functions		
LQFP100	LQFP64	LQFP48	Pin name (function after reset)	Pin type	I/O structure	Notes	Alternate functions	Additional functions	
23	14	10	PA0	I/O	ТТа	-	USART2_CTS, TIM2_CH1_ETR, TSC_G1_IO1, COMP1_OUT, EVENTOUT	ADC1_IN1, COMP1_INM, RTC_ TAMP2, WKUP1	
24	15	11	PA1	I/O	ТТа	-	USART2_RTS_DE, TIM2_CH2, TSC_G1_IO2, TIM15_CH1N, RTC_REFIN, EVENTOUT	ADC1_IN2, COMP1_INP, OPAMP1_VINP	
25	16	12	PA2	I/O	ТТа	(4)	USART2_TX, TIM2_CH3, TIM15_CH1, TSC_G1_IO3, COMP2_OUT, EVENTOUT	ADC1_IN3, COMP2_INM, OPAMP1_VOUT	
26	17	13	PA3	I/O	TTa	-	USART2_RX, TIM2_CH4, TIM15_CH2, TSC_G1_IO4, EVENTOUT	ADC1_IN4, OPAMP1_VINP, COMP2_INP, OPAMP1_VINM	
27	18	-	PF4	I/O	TTa	(1)	COMP1_OUT, EVENTOUT	ADC1_IN5	
28	19	-	VDD_4	S	-	-	-	-	
29	20	14	PA4	I/O	TTa	(4)	SPI1_NSS, SPI3_NSS,I2S3_WS, USART2_CK, TSC_G2_IO1, TIM3_CH2, EVENTOUT	ADC2_IN1, DAC1_OUT1, COMP1_INM, COMP2_INM, COMP4_INM, COMP6_INM	
30	21	15	PA5	I/O	тта	(4)	SPI1_SCK, TIM2_CH1_ETR, TSC_G2_IO2, EVENTOUT	ADC2_IN2 OPAMP1_VINP, OPAMP2_VINM COMP1_INM, COMP2_INM, COMP4_INM,COMP6_INM	
31	22	16	PA6	I/O	ТТа	(4)	SPI1_MISO, TIM3_CH1, TIM1_BKIN, TIM16_CH1, COMP1_OUT, TSC_G2_IO3, EVENTOUT	ADC2_IN3, OPAMP2_VOUT	
32	23	17	PA7	I/O	TTa	-	SPI1_MOSI, TIM3_CH2, TIM17_CH1, TIM1_CH1N, TSC_G2_IO4, COMP2_OUT, EVENTOUT	ADC2_IN4, COMP2_INP, OPAMP2_VINP, OPAMP1_VINP	
33	24	-	PC4	I/O	TTa	(1)	USART1_TX, EVENTOUT	ADC2_IN5	
34	25	-	PC5	I/O	ТТа	(1)	USART1_RX, TSC_G3_IO1, EVENTOUT	ADC2_IN11, OPAMP2_VINM, OPAMP1_VINM	
35	26	18	PB0	I/O	TTa	-	TIM3_CH3, TIM1_CH2N, TSC_G3_IO2, EVENTOUT	COMP4_INPOPAMP2_VINP	
36	27	19	PB1	I/O	ТТа	(4)	TIM3_CH4, TIM1_CH3N, COMP4_OUT, TSC_G3_IO3, EVENTOUT	-	
37	28	20	PB2	I/O	TTa	-	TSC_G3_IO4, EVENTOUT	ADC2_IN12, COMP4_INM	
38	-	-	PE7	I/O	TTa	(1)	TIM1_ETR, EVENTOUT	COMP4_INP	
39	-	-	PE8	I/O	TTa	(1)	TIM1_CH1N, EVENTOUT	COMP4_INM	

Table 13.STM32F302xB/STM32F302xC pin definitions (continued)


D :-	Pin number						M32F302xC pin definitions	unctions
	n numi	ber	Pin name	e	ture	s		
LQFP100	LQFP64	LQFP48	(function after reset)	Pin type	I/O structure	Notes	Alternate functions	Additional functions
40	-	-	PE9	I/O	TTa	(1)	TIM1_CH1, EVENTOUT	
41	-	-	PE10	I/O	TTa	(1)	TIM1_CH2N, EVENTOUT	
42	-	-	PE11	I/O	TTa	(1)	TIM1_CH2, EVENTOUT	
43	-	-	PE12	I/O	TTa	(1)	TIM1_CH3N, EVENTOUT	
44	-	-	PE13	I/O	TTa	(1)	TIM1_CH3, EVENTOUT	
45	-	-	PE14	I/O	TTa	(1)	TIM1_CH4, TIM1_BKIN2, EVENTOUT	
46	-	-	PE15	I/O	ТТа	(1)	USART3_RX, TIM1_BKIN, EVENTOUT	
47	29	21	PB10	I/O	ТТа	-	USART3_TX, TIM2_CH3, TSC_SYNC, EVENTOUT	
48	30	22	PB11	I/O	тта	-	USART3_RX, TIM2_CH4, TSC_G6_IO1, EVENTOUT	COMP6_INP
49	31	23	VSS_2	S	-	-	Digita	al ground
50	32	24	VDD_2	S	-	-	Digital po	ower supply
51	33	25	PB12	I/O	ТТа	(4)	SPI2_NSS, I2S2_WS,I2C2_SMBA, USART3_CK, TIM1_BKIN, TSC_G6_IO2, EVENTOUT	
52	34	26	PB13	I/O	ТТа	-	SPI2_SCK,I2S2_CK,USART 3_CTS, TIM1_CH1N, TSC_G6_IO3, EVENTOUT	
53	35	27	PB14	I/O	ТТа	-	SPI2_MISO,I2S2ext_SD, USART3_RTS_DE, TIM1_CH2N, TIM15_CH1, TSC_G6_IO4, EVENTOUT	OPAMP2_VINP
54	36	28	PB15	I/O	ТТа	-	SPI2_MOSI, I2S2_SD, TIM1_CH3N, RTC_REFIN, TIM15_CH1N, TIM15_CH2, EVENTOUT	COMP6_INM
55	-	-	PD8	I/O	TTa	(1)	USART3_TX, EVENTOUT	
56	-	-	PD9	I/O	TTa	(1)	USART3_RX, EVENTOUT	
57	-	-	PD10	I/O	TTa	(1)	USART3_CK, EVENTOUT	COMP6_INM
58	-	-	PD11	I/O	TTa	(1)	USART3_CTS, EVENTOUT	COMP6_INP
59	-	-	PD12	I/O	TTa	(1)	USART3_RTS_DE, TIM4_CH1, TSC_G8_IO1, EVENTOUT	
60	-	-	PD13	I/O	ТТа	(1)	TIM4_CH2, TSC_G8_IO2, EVENTOUT	
61	-	-	PD14	I/O	ТТа	(1)	TIM4_CH3, TSC_G8_IO3, EVENTOUT	OPAMP2_VINP



Pir	n numt					2,01	M32F302xC pin definitions	Inctions
			Pin name (function	pe	ctur	S		
LQFP100	LQFP64	LQFP48	after reset)	Pin type	I/O structure	Notes	Alternate functions	Additional functions
62	-	-	PD15	I/O	ТТа	(1)	SPI2_NSS, TIM4_CH4, TSC_G8_IO4, EVENTOUT	
63	37	-	PC6	I/O	FT	(1)	I2S2_MCK, COMP6_OUT TIM3_CH1, EVENTOUT	-
64	38	-	PC7	I/O	FT	(1)	I2S3_MCK, TIM3_CH2, EVENTOUT	-
65	39	-	PC8	I/O	FT	(1)	TIM3_CH3, EVENTOUT	-
66	40	-	PC9	I/O	FT	(1)	TIM3_CH4, I2S_CKIN, EVENTOUT	-
67	41	29	PA8	I/O	FT	-	I2C2_SMBA, I2S2_MCK, USART1_CK, TIM1_CH1, TIM4_ETR, MCO, EVENTOUT	-
68	42	30	PA9	I/O	FTf	-	I2C2_SCL, I2S3_MCK, USART1_TX, TIM1_CH2, TIM2_CH3, TIM15_BKIN, TSC_G4_IO1, EVENTOUT	-
69	43	31	PA10	I/O	FTf	-	I2C2_SDA, USART1_RX, TIM1_CH3, TIM2_CH4, TIM17_BKIN, TSC_G4_IO2, COMP6_OUT, EVENTOUT	-
70	44	32	PA11	I/O	FT	-	USART1_CTS, USB_DM, CAN_RX, TIM1_CH1N, TIM1_CH4, TIM1_BKIN2, TIM4_CH1, COMP1_OUT, EVENTOUT	-
71	45	33	PA12	I/O	FT	-	USART1_RTS_DE, USB_DP, CAN_TX, TIM1_CH2N, TIM1_ETR, TIM4_CH2, TIM16_CH1, COMP2_OUT, EVENTOUT	-
72	46	34	PA13	I/O	FT	-	USART3_CTS, TIM4_CH3, TIM16_CH1N, TSC_G4_IO3, IR_OUT, SWDIO-JTMS, EVENTOUT	-
73	-	-	PF6	I/O	FTf	(1)	I2C2_SCL, USART3_RTS_DE, TIM4_CH4, EVENTOUT	-
74	47	35	VSS_3	S	-	-	Gr	ound
75	48	36	VDD_3	S	-	-	Digital po	ower supply
76	49	37	PA14	I/O	FTf	-	I2C1_SDA, USART2_TXTIM1_BKIN, TSC_G4_IO4,SWCLK-JTCK, EVENTOUT	-



Pir	n numl		Pin name				M32F302xC pin definitions Pin fu	nctions
LQFP100	LQFP64	LQFP48	(function after reset)	Pin type	I/O structure	Notes	Alternate functions	Additional functions
77	50	38	PA15	I/O	FTf	-	I2C1_SCL, SPI1_NSS, SPI3_NSS, I2S3_WS, JTDI, USART2_RX, TIM1_BKIN, TIM2_CH1_ETR, EVENTOUT	-
78	51	-	PC10	I/O	FT	(1)	SPI3_SCK, I2S3_CK, USART3_TX, UART4_TX, EVENTOUT	-
79	52	-	PC11	I/O	FT	(1)	SPI3_MISO, I2S3ext_SD, USART3_RX, UART4_RX, EVENTOUT	-
80	53	-	PC12	I/O	FT	(1)	SPI3_MOSI, I2S3_SD, USART3_CK, UART5_TX, EVENTOUT	-
81	-	-	PD0	I/O	FT	(1)	CAN_RX, EVENTOUT	-
82	-	-	PD1	I/O	FT	(1)	CAN_TX, EVENTOUT	-
83	54	-	PD2	I/O	FT	(1)	UART5_RX, TIM3_ETR, EVENTOUT	-
84	-	-	PD3	I/O	FT	(1)	USART2_CTS, TIM2_CH1_ETR, EVENTOUT	-
85	-	-	PD4	I/O	FT	(1)	USART2_RTS_DE, TIM2_CH2, EVENTOUT	-
86	-	-	PD5	I/O	FT	(1)	USART2_TX, EVENTOUT	-
87	-	-	PD6	I/O	FT	(1)	USART2_RX, TIM2_CH4, EVENTOUT	-
88	-	-	PD7	I/O	FT	(1)	USART2_CK, TIM2_CH3, EVENTOUT	-
89	55	39	PB3	I/O	FT	_	SPI3_SCK, I2S3_CK, SPI1_SCK, USART2_TX, TIM2_CH2, TIM3_ETR, TIM4_ETR, TSC_G5_IO1, JTDO-TRACESWO, EVENTOUT	-
90	56	40	PB4	I/O	FT	-	SPI3_MISO, I2S3ext_SD, SPI1_MISO, USART2_RX, TIM3_CH1, TIM16_CH1, TIM17_BKIN, TSC_G5_IO2, NJTRST, EVENTOUT	-
91	57	41	PB5	I/O	FT	-	SPI3_MOSI, SPI1_MOSI, I2S3_SD, I2C1_SMBA, USART2_CK, TIM16_BKIN, TIM3_CH2, TIM17_CH1, EVENTOUT	-



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Pir	n numt	ber	Pin name	e	ure		Pin fu	inctions			
LQFP100	LQFP64	LQFP48	(function after reset)	Pin type	I/O structure	Notes	Alternate functions	Additional functions			
92	58	42	PB6	I/O	FTf	-	I2C1_SCL, USART1_TX, TIM16_CH1N, TIM4_CH1, TSC_G5_IO3EVENTOUT	-			
93	59	43	PB7	I/O	FTf	-	I2C1_SDA, USART1_RX, TIM3_CH4, TIM4_CH2, TIM17_CH1N, TSC_G5_IO4, EVENTOUT	-			
94	60	44	BOOT0	Ι	В	-	Boot mem	ory selection			
95	61	45	PB8	I/O	FTf	-	I2C1_SCL, CAN_RX, TIM16_CH1, TIM4_CH3 TIM1_BKIN, TSC_SYNC, COMP1_OUT, EVENTOUT	_			
96	62	46	PB9	I/O	FTf	-	I2C1_SDA, CAN_TX, TIM17_CH1, TIM4_CH4, IR_OUT, COMP2_OUT, EVENTOUT	-			
97	-	-	PE0	I/O	FT	(1)	USART1_TX, TIM4_ETR, TIM16_CH1, EVENTOUT	-			
98	-	-	PE1	I/O	FT	(1)	USART1_RX, TIM17_CH1, EVENTOUT	-			
99	99 63 47 VSS_1			S	-	-	- Ground				
100				S	-	- Digital power supply					

 Function availability depends on the chosen device. When using the small packages (48 and 64 pin packages), the GPIO pins which are not present on these packages, must not be configured in analog mode.

2. PC13, PC14 and PC15 are supplied through the power switch. Since the switch sinks only a limited amount of current

(3 mA), the use of GPIO PC13 to PC15 in output mode is limited:

- The speed should not exceed 2 MHz with a maximum load of 30 pF

- These GPIOs must not be used as current sources (e.g. to drive an LED).

After the first backup domain power-up, PC13, PC14 and PC15 operate as GPIOs. Their function then depends on the content of the Backup registers which is not reset by the main reset. For details on how to manage these GPIOs, refer to the Battery backup domain and BKP register description sections in the RM0365 reference manual.

3. The VREF+ functionality is available only on the 100 pin package. On the 64-pin and 48-pin packages, the VREF+ is internally connected to VDDA.

4. These GPIOs offer a reduced touch sensing sensitivity. It is thus recommended to use them as sampling capacitor I/O.



STM32F302xB STM32F302xC

Pinouts and pin description

Port & Pin Name	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF14	A
PA0	-	TIM2_ CH1_ ETR	-	TSC_ G1_IO1	-	-	-	USART2_ CTS	COMP1 _OUT			-	-	-	EV OL
PA1	RTC_ REFIN	TIM2_ CH2	-	TSC_ G1_IO2	-	-	-	USART2_ RTS_DE		TIM15_ CH1N	-	-	-	-	EV OL
PA2	-	TIM2_ CH3	-	TSC_ G1_IO3	-	-	-	USART2_ TX	COMP2 _OUT	TIM15_ CH1	-	-	-	-	EV OL
PA3	-	TIM2_ CH4	-	TSC_ G1_IO4	-	-	-	USART2_ RX	-	TIM15_ CH2	-	-	-	-	EV OL
PA4	-	-	TIM3_ CH2	TSC_ G2_IO1	-	SPI1_ NSS	SPI3_NSS, I2S3_WS	USART2_ CK	-	-	-	-	-	-	EV OL
PA5	-	TIM2_ CH1_ ETR	-	TSC_ G2_IO2	-	SPI1_ SCK	-	-	-	-	-	-	-	-	EV OL
PA6	-	TIM16_ CH1	TIM3_ CH1	TSC_ G2_IO3		SPI1_ MISO	TIM1_BKIN	-	COMP1 _OUT	-	-	-	-	-	EV OL
PA7	-	TIM17_ CH1	TIM3_ CH2	TSC_ G2_IO4		SPI1_ MOSI	TIM1_CH1N	-	COMP2 _OUT	-	-	-	-	-	EV OL
PA8	мсо	-	-	-	I2C2_ SMBA	I2S2_ MCK	TIM1_CH1	USART1_ CK		-	TIM4_ ETR	-	-	-	EV OL
PA9	-	-	-	TSC_ G4_IO1	I2C2_ SCL	12S3_ MCK	TIM1_CH2	USART1_ TX		TIM15_ BKIN	TIM2_ CH3	-	-	-	EV OL
PA10	-	TIM17_ BKIN	-	TSC_ G4_IO2	I2C2_ SDA	-	TIM1_CH3	USART1_ RX	COMP6 _OUT	-	TIM2_ CH4		-	-	EV OL
PA11	-	-	-	-	-	-	TIM1_CH1N	USART1_ CTS	COMP1 _OUT	CAN_RX	TIM4_ CH1	TIM1_CH4	TIM1_ BKIN2	USB_ DM	EV OL

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					Tab	le 14.Al	ternate funct	tions for p	ort A (co	ntinued)					
Port & Pin Name	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF14	AF15
PA12	-	TIM16_ CH1	-	-	-	-	TIM1_CH2N	USART1_ RTS_DE	COMP2 _OUT	CAN_TX	TIM4_ CH2	TIM1_ETR	-	USB_ DP	EVENT OUT
PA13	SWDIO -JTMS	TIM16_ CH1N	-	TSC_ G4_IO3	-	IR_ OUT	-	USART3_ CTS	-	-	TIM4_ CH3	-	-	-	EVENT OUT
PA14	SWCLK -JTCK	-	-	TSC_ G4_IO4	I2C1_ SDA		TIM1_BKIN	USART2_ TX	-	-	-	-	-	-	EVENT OUT
PA15	JTDI	TIM2_ CH1_ ETR		-	I2C1_ SCL	SPI1_ NSS	SPI3_NSS, I2S3_WS	USART2_ RX	-	TIM1_ BKIN	-	-	-	-	EVENT OUT

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Pinouts and pin description

Port & Pin Name	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF12	AF15
PB0	-	-	TIM3_ CH3	TSC_ G3_IO2		-	TIM1_CH2N	-	-	-	-	-	EVENT OUT
PB1	-	-	TIM3_ CH4	TSC_ G3_IO3		-	TIM1_CH3N	-	COMP4_ OUT	-	-	-	EVENT OUT
PB2	-	-	-	TSC_ G3_IO4	-	-	-	-	-	-	-	-	EVENT OUT
PB3	JTDO- TRACES WO	TIM2_ CH2	TIM4_ ETR	TSC_ G5_IO1		SPI1_ SCK	SPI3_SCK, I2S3_CK	USART2_ TX	-	-	TIM3_ ETR	-	EVENT OUT
PB4	NJTRST	TIM16_ CH1	TIM3_ CH1	TSC_ G5_IO2		SPI1_ MISO	SPI3_MISO, I2S3ext_SD	USART2_ RX	-	-	TIM17_ BKIN	-	EVENT OUT
PB5	-	TIM16_ BKIN	TIM3_ CH2		I2C1_ SMBA	SPI1_ MOSI	SPI3_MOSI, I2S3_SD	USART2_ CK	-	-	TIM17_ CH1	-	EVENT OUT
PB6	-	TIM16_ CH1N	TIM4_ CH1	TSC_ G5_IO3	I2C1_SCL			USART1_ TX	-	-		-	EVENT OUT
PB7	-	TIM17_ CH1N	TIM4_ CH2	TSC_ G5_IO4	I2C1_ SDA		-	USART1_ RX	-	-	TIM3_ CH4	-	EVENT OUT
PB8	-	TIM16_ CH1	TIM4_ CH3	TSC_ SYNC	I2C1_SCL	-	-	-	COMP1_ OUT	CAN_RX		TIM1_ BKIN	EVENT OUT
PB9	-	TIM17_ CH1	TIM4_ CH4		I2C1_ SDA	-	IR_OUT	-	COMP2_ OUT	CAN_TX		-	EVENT OUT
PB10	-	TIM2_ CH3	-	TSC_ SYNC	-	-	-	USART3_ TX	-	-	-	-	EVENT OUT
PB11	-	TIM2_ CH4	-	TSC_ G6_IO1	-	-	-	USART3_ RX	-	-	-	-	EVENT OUT
PB12	-	-	-	TSC_ G6_IO2	I2C2_ SMBA	SPI2_NSS, I2S2_WS	TIM1_ BKIN	USART3_ CK	-	-	-	-	EVENT OUT

Table 15.Alternate functions for port B

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					Table 15.A	Iternate func	tions for por	t B (contin	ued)				
Port & Pin Name	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF12	AF15
PB13	-	-	-	TSC_ G6_IO3	-	SPI2_SCK, I2S2_CK	TIM1_ CH1N	USART3_ CTS	-	-	-	-	EVENT OUT
PB14	-	TIM15_ CH1	-	TSC_ G6_IO4	-	SPI2_MISO, I2S2ext_SD	TIM1_ CH2N	USART3_ RTS_DE	-	-	-	-	EVENT OUT
PB15	RTC_ REFIN	TIM15_ CH2	TIM15_ CH1N	-	TIM1_ CH3N	SPI2_MOSI, I2S2_SD	-	-	-	-	-	-	EVENT OUT

Pinouts and pin description

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			Table 1	6.Alternate fund	tions for port (C	
Port & Pin Name	AF1	AF2	AF3	AF4	AF5	AF6	AF7
PC0	EVENTOUT	-	-	-	-	-	-
PC1	EVENTOUT	-	-	-	-	-	-
PC2	EVENTOUT	-	COMP7_OUT	-	-	-	-
PC3	EVENTOUT	-	-	-	-	TIM1_BKIN2	-
PC4	EVENTOUT	-	-	-	-	-	USART1_TX
PC5	EVENTOUT	-	TSC_G3_IO1	-	-	-	USART1_RX
PC6	EVENTOUT	TIM3_CH1	-		-	I2S2_MCK	COMP6_OUT
PC7	EVENTOUT	TIM3_CH2	-		-	I2S3_MCK	
PC8	EVENTOUT	TIM3_CH3	-		-	-	
PC9	EVENTOUT	TIM3_CH4	-		I2S_CKIN		-
PC10	EVENTOUT	-	-		UART4_TX	SPI3_SCK, I2S3_CK	USART3_TX
PC11	EVENTOUT	-	-		UART4_RX	SPI3_MISO, I2S3ext_SD	USART3_RX
PC12	EVENTOUT	-	-		UART5_TX	SPI3_MOSI, I2S3_SD	USART3_CK
PC13	-	-	-	TIM1_CH1N	-	-	-
PC14	-	-	-	-	-	-	-
PC15	-	-	-	-	-	-	-

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	Table 17.Alternate functions for port D											
Port & Pin Name	AF1	AF2	AF3	AF4	AF5	AF6	AF7					
PD0	EVENTOUT	-	-	-	-	-	CAN_RX					
PD1	EVENTOUT	-	-		-		CAN_TX					
PD2	EVENTOUT	TIM3_ETR	-		UART5_RX	-	-					
PD3	EVENTOUT	TIM2_CH1_ETR	-	-	-	-	USART2_CTS					
PD4	EVENTOUT	TIM2_CH2	-	-	-	-	USART2_RTS_DE					
PD5	EVENTOUT	-	-	-	-	-	USART2_TX					
PD6	EVENTOUT	TIM2_CH4	-	-	-	-	USART2_RX					
PD7	EVENTOUT	TIM2_CH3	-	-	-	-	USART2_CK					
PD8	EVENTOUT	-	-	-	-	-	USART3_TX					
PD9	EVENTOUT	-	-	-	-	-	USART3_RX					
PD10	EVENTOUT	-	-	-	-	-	USART3_CK					
PD11	EVENTOUT	-	-	-	-	-	USART3_CTS					
PD12	EVENTOUT	TIM4_CH1	TSC_G8_IO1	-	-	-	USART3_RTS_DE					
PD13	EVENTOUT	TIM4_CH2	TSC_G8_IO2	-	-	-	-					
PD14	EVENTOUT	TIM4_CH3	TSC_G8_IO3	-	-	-	-					
PD15	EVENTOUT	TIM4_CH4	TSC_G8_IO4	-	-	SPI2_NSS	-					

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			Table 18.Alternate	e functions for po	rt E		
Port & Pin Name	AF0	AF1	AF2	AF3	AF4	AF6	AF7
PE0	-	EVENTOUT	TIM4_ETR	-	TIM16_CH1	-	USART1_TX
PE1	-	EVENTOUT	-	-	TIM17_CH1	-	USART1_RX
PE2	TRACECK	EVENTOUT	TIM3_CH1	TSC_G7_IO1	-	-	-
PE3	TRACED0	EVENTOUT	TIM3_CH2	TSC_G7_IO2	-	-	-
PE4	TRACED1	EVENTOUT	TIM3_CH3	TSC_G7_IO3	-	-	-
PE5	TRACED2	EVENTOUT	TIM3_CH4	TSC_G7_IO4	-	-	-
PE6	TRACED3	EVENTOUT		-	-	-	-
PE7	-	EVENTOUT	TIM1_ETR	-	-	-	-
PE8	-	EVENTOUT	TIM1_CH1N	-	-	-	-
PE9	-	EVENTOUT	TIM1_CH1	-	-	-	-
PE10	-	EVENTOUT	TIM1_CH2N	-	-	-	-
PE11	-	EVENTOUT	TIM1_CH2	-	-	-	-
PE12	-	EVENTOUT	TIM1_CH3N	-	-	-	-
PE13	-	EVENTOUT	TIM1_CH3	-	-	-	-
PE14	-	EVENTOUT	TIM1_CH4	-	-	TIM1_BKIN2	-
PE15	-	EVENTOUT	TIM1_BKIN	-	-	-	USART3_RX

47/137

Pinouts and pin description

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	Table 19.Alternate functions for port F								
Port & Pin Name	AF1	AF2	AF3	AF4	AF5	AF6	AF7		
PF0	-	-	-	I2C2_SDA	-	TIM1_CH3N	-		
PF1	-	-	-	I2C2_SCL	-	-	-		
PF2	EVENTOUT	-	-	-	-	-	-		
PF4	EVENTOUT	COMP1_OUT	-	-	-	-	-		
PF6	EVENTOUT	TIM4_CH4	-	I2C2_SCL	-	-	USART3_RTS_DE		
PF9	EVENTOUT	-	TIM15_CH1	-	SPI2_SCK	-	-		
PF10	EVENTOUT	-	TIM15_CH2	-	SPI2_SCK	-	-		

5 Memory mapping



Figure 7.STM32F302xB/STM32F302xC memory map



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BusBoundary addressSize (bytes)Peripheral0x5000 0400 - 0x5000 07FF1 KReservedAHB30x5000 0000 - 0x5000 03FF1 KADC1 - ADC20x4800 1800 - 0x4FFF FFFF~132 MReserved0x4800 1000 - 0x4800 17FF1 KGPIOF0x4800 0000 - 0x4800 017FF1 KGPIOE0x4800 0000 - 0x4800 017FF1 KGPIOD0x4800 0000 - 0x4800 017FF1 KGPIOD0x4800 0000 - 0x4800 017FF1 KGPIOD0x4800 0000 - 0x4800 017FF1 KGPIOA0x4800 0000 - 0x4800 017FF1 KCRC0x4002 1000 - 0x4002 217FF3 KReserved0x4002 1000 - 0x4002 017FF1 KFlash interface0x4002 1000 - 0x4002 017FF1 KDMA10x4002 1000 - 0x4002 017FF1 KDMA10x4002 1000 - 0x4002 017FF1 KDMA10x4002 1000 - 0x4002 017FF1 KDMA10x4001 1000 - 0x4002 017FF1 KTIM170x4001 1000 - 0x4001 017FFF1 KTIM170x4001 1000 - 0x40		addres		
AHB3 0x5000 000 - 0x5000 03FF 1 K ADC1 - ADC2 0x4800 1800 - 0x4FFF FFFF ~132 M Reserved 0x4800 1000 - 0x4800 17FF 1 K GPIOF 0x4800 1000 - 0x4800 07FF 1 K GPIOE 0x4800 0000 - 0x4800 07FF 1 K GPIOD 0x4800 0000 - 0x4800 07FF 1 K GPIOD 0x4800 0000 - 0x4800 07FF 1 K GPIOA 0x4800 0000 - 0x4800 03FF 1 K GPIOA 0x4002 4000 - 0x4800 03FF 1 K GPIOA 0x4002 4000 - 0x4800 03FF 1 K GPIOA 0x4002 4000 - 0x4800 33FF 1 K GPIOA 0x4002 4000 - 0x4002 33FF 1 K TSC 0x4002 3000 - 0x4002 33FF 1 K CRC 0x4002 2000 - 0x4002 33FF 1 K Flash interface 0x4002 1000 - 0x4002 23FF 1 K Flash interface 0x4002 1000 - 0x4002 1FF 3 K Reserved 0x4002 1000 - 0x4002 07FF 1 K Reserved 0x4002 0000 - 0x4002 07FF 1 K DMA1 0x4002 0000 - 0x4002 07FF 1 K <t< th=""><th>Bus</th><th>Boundary address</th><th></th><th>Peripheral</th></t<>	Bus	Boundary address		Peripheral
0x4800 1800 - 0x4FFF FFFF ~132 M Reserved 0x4800 1400 - 0x4800 17FF 1 K GPIOF 0x4800 1000 - 0x4800 013FF 1 K GPIOE 0x4800 0000 - 0x4800 0FFF 1 K GPIOD 0x4800 0000 - 0x4800 0BFF 1 K GPIOD 0x4800 0000 - 0x4800 0BFF 1 K GPIOD 0x4800 0000 - 0x4800 03FF 1 K GPIOA 0x4800 0000 - 0x4800 03FF 1 K GPIOA 0x4002 4000 - 0x47FF FFFF ~128 M Reserved 0x4002 4000 - 0x4002 3FF 1 K TSC 0x4002 3000 - 0x4002 3FF 3 K Reserved 0x4002 3000 - 0x4002 3FF 3 K Reserved 0x4002 2000 - 0x4002 3FF 3 K Reserved 0x4002 2000 - 0x4002 3FF 3 K Reserved 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 1FF 1 K Flash interface 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 0FFF 2 K Reserved 0x4002 0000 - 0x4002 0FFF 2 K Reserved		0x5000 0400 - 0x5000 07FF	1 K	Reserved
AHB2 0x4800 1400 - 0x4800 17FF 1 K GPIOF 0x4800 1000 - 0x4800 0FF 1 K GPIOE 0x4800 0C00 - 0x4800 0FFF 1 K GPIOD 0x4800 0000 - 0x4800 0FFF 1 K GPIOC 0x4800 0000 - 0x4800 0FFF 1 K GPIOA 0x4800 0000 - 0x4800 0FFF 1 K GPIOA 0x4800 0000 - 0x4800 03FF 1 K GPIOA 0x4002 4400 - 0x47FF FFFF ~128 M Reserved 0x4002 4000 - 0x4002 3FF 3 K Reserved 0x4002 3000 - 0x4002 3FF 3 K Reserved 0x4002 2000 - 0x4002 3FF 3 K Reserved 0x4002 2000 - 0x4002 3FF 3 K Reserved 0x4002 2000 - 0x4002 3FF 3 K Reserved 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 0FFF 2 K Reserved 0x4002 0000 - 0x4002 0FFF 2 K Reserved 0x4002 0000 - 0x4002 0FFF 3 K Reserved 0x4001 8000 - 0x4001 0FFFF 1 K <t< td=""><td>AHB3</td><td>0x5000 0000 - 0x5000 03FF</td><td>1 K</td><td>ADC1 - ADC2</td></t<>	AHB3	0x5000 0000 - 0x5000 03FF	1 K	ADC1 - ADC2
AHB2 0x4800 1000 - 0x4800 13FF 1 K GPIOE 0x4800 0C00 - 0x4800 0FFF 1 K GPIOD 0x4800 0800 - 0x4800 0FFF 1 K GPIOC 0x4800 0000 - 0x4800 0FFF 1 K GPIOB 0x4800 0000 - 0x4800 07FF 1 K GPIOB 0x4800 0000 - 0x4800 03FF 1 K GPIOA 0x4002 4400 - 0x4002 43FF 1 K GPIOA 0x4002 4000 - 0x4002 3FFF 3 K Reserved 0x4002 3000 - 0x4002 3FF 3 K Reserved 0x4002 2000 - 0x4002 2FFF 3 K Reserved 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 0FFF 2 K Reserved 0x4002 0000 - 0x4002 0FFF 2 K Reserved 0x4002 0000 - 0x4002 0FFF 2 K Reserved 0x4002 0000 - 0x4002 0FFF 3 K Reserved 0x4001 8000 - 0x4001 0FFF 3 K		0x4800 1800 - 0x4FFF FFFF	~132 M	Reserved
AHB2 Dx4800 0C00 - 0x4800 0FFF 1 K GPIOD 0x4800 0800 - 0x4800 0BFF 1 K GPIOD 0x4800 0400 - 0x4800 03FF 1 K GPIOB 0x4800 0000 - 0x4800 03FF 1 K GPIOA 0x4002 4400 - 0x47FF FFFF ~128 M Reserved 0x4002 4000 - 0x4002 43FF 1 K TSC 0x4002 3400 - 0x4002 3FFF 3 K Reserved 0x4002 2000 - 0x4002 3FFF 3 K Reserved 0x4002 2000 - 0x4002 2FFF 3 K Reserved 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 0FFF 2 K Reserved 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0800 - 0x4002 07FF 1 K DMA2 0x4001 8000 - 0x4001 0FFF 2 K Reserved 0x4001 8000 - 0x4001 7FFF 1 K DMA1 0x4001 4800 - 0x4001 7FFF 1 K TIM17 0x4001 4800 - 0x4001 48FF 1 K		0x4800 1400 - 0x4800 17FF	1 K	GPIOF
AHB2 Initial control of the second of the seco		0x4800 1000 - 0x4800 13FF	1 K	GPIOE
NAME 0x4800 0800 - 0x4800 0BFF 1 K GPIOC 0x4800 0400 - 0x4800 07FF 1 K GPIOB 0x4002 4400 - 0x47FF FFFF ~128 M Reserved 0x4002 4000 - 0x4002 43FF 1 K TSC 0x4002 3000 - 0x4002 3FF 3 K Reserved 0x4002 2000 - 0x4002 2FFF 3 K Reserved 0x4002 1000 - 0x4002 1FF 3 K Reserved 0x4002 1000 - 0x4002 1FF 3 K Reserved 0x4002 1000 - 0x4002 1FF 3 K Reserved 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0800 - 0x4002 0FFF 1 K DMA2 0x4002 0000 - 0x4002 07FF 1 K DMA1 0x4001 8000 - 0x4001 7FFF 1 K DMA1 0x4001 4000 - 0x4001 7FFF 1 K TIM17 0x4001 4200 - 0x4001 7FFF 1 K TIM16 0x4001 4200 - 0x4001 43FF 1 K TIM16 <td></td> <td>0x4800 0C00 - 0x4800 0FFF</td> <td>1 K</td> <td>GPIOD</td>		0x4800 0C00 - 0x4800 0FFF	1 K	GPIOD
Ox4800 0000 - 0x4800 03FF 1 K GPIOA 0x4002 4400 - 0x47FF FFFF ~128 M Reserved 0x4002 4000 - 0x4002 43FF 1 K TSC 0x4002 3400 - 0x4002 3FFF 3 K Reserved 0x4002 3000 - 0x4002 3FFF 3 K Reserved 0x4002 2000 - 0x4002 3FFF 3 K Reserved 0x4002 2000 - 0x4002 2FFF 3 K Reserved 0x4002 2000 - 0x4002 2FFF 3 K Reserved 0x4002 1400 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 13FF 1 K Flash interface 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0400 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 FFFF 32 K Reserved 0x4001 4000 - 0x4001 7FFF 13 K Reserved 0x4001 4200 - 0x4001 48FF 1 K TIM17 0x4001 4400 - 0x4001 48FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 </td <td>ALIDZ</td> <td>0x4800 0800 - 0x4800 0BFF</td> <td>1 K</td> <td>GPIOC</td>	ALIDZ	0x4800 0800 - 0x4800 0BFF	1 K	GPIOC
Initial of the original original of the original original original original original or		0x4800 0400 - 0x4800 07FF	1 K	GPIOB
AHB1 DAA DAA 0x4002 4000 - 0x4002 43FF 1 K TSC 0x4002 3400 - 0x4002 3FFF 3 K Reserved 0x4002 3000 - 0x4002 33FF 1 K CRC 0x4002 2400 - 0x4002 2FFF 3 K Reserved 0x4002 2000 - 0x4002 23FF 1 K Flash interface 0x4002 1400 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 13FF 1 K Reserved 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 03FF 3 K Reserved 0x4001 4000 - 0x4001 7FFF 1 K DMA1 0x4001 4000 - 0x4001 7FFF 1 K TIM17 0x4001 4800 - 0x4001 48FF 1 K TIM17 0x4001 4400 - 0x4001 43FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4800 0000 - 0x4800 03FF	1 K	GPIOA
AHB1 Number of the served 0x4002 3400 - 0x4002 3FFF 3 K Reserved 0x4002 3000 - 0x4002 3FF 1 K CRC 0x4002 2400 - 0x4002 2FFF 3 K Reserved 0x4002 2000 - 0x4002 23FF 1 K Flash interface 0x4002 1400 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 07FF 1 K Reserved 0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 07FF 1 K DMA1 0x4002 0000 - 0x4002 07FF 1 K DMA1 0x4001 8000 - 0x4001 07FF 1 K DMA1 0x4001 8000 - 0x4001 7FFF 13 K Reserved 0x4001 4800 - 0x4001 48FF 1 K TIM17 0x4001 4400 - 0x4001 43FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4		0x4002 4400 - 0x47FF FFFF	~128 M	Reserved
AHB1 0x4002 3000 - 0x4002 33FF 1 K CRC 0x4002 2400 - 0x4002 2FFF 3 K Reserved 0x4002 2000 - 0x4002 23FF 1 K Flash interface 0x4002 1400 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 13FF 1 K RCC 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 7FFF 32 K Reserved 0x4001 4000 - 0x4001 7FFF 1 K TIM17 0x4001 4800 - 0x4001 48FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM16 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 4000 - 0x4002 43FF	1 K	TSC
AHB1 Dx4002 2400 - 0x4002 2FFF 3 K Reserved 0x4002 2000 - 0x4002 23FF 1 K Flash interface 0x4002 1400 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 13FF 1 K Reserved 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0400 - 0x4002 0FFF 2 K Reserved 0x4002 0000 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 7FFF 32 K Reserved 0x4001 4000 - 0x4001 7FFF 13 K Reserved 0x4001 4200 - 0x4001 48FF 1 K TIM17 0x4001 4400 - 0x4001 47FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 3400 - 0x4002 3FFF	3 K	Reserved
AHB1 0x4002 2000 - 0x4002 23FF 1 K Flash interface 0x4002 1400 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 13FF 1 K RCC 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 FFFF 32 K Reserved 0x4001 4000 - 0x4001 7FFF 13 K Reserved 0x4001 4200 - 0x4001 4BFF 1 K TIM17 0x4001 4400 - 0x4001 43FF 1 K TIM16 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 3000 - 0x4002 33FF	1 K	CRC
AHB1 0x4002 1400 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 13FF 1 K RCC 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4002 03FF 1 K DMA1 0x4001 4000 - 0x4001 7FFF 32 K Reserved 0x4001 4C00 - 0x4001 7FFF 13 K Reserved 0x4001 4200 - 0x4001 7FFF 1 K TIM17 0x4001 4400 - 0x4001 4BFF 1 K TIM16 0x4001 4400 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 2400 - 0x4002 2FFF	3 K	Reserved
0x4002 1400 - 0x4002 1FFF 3 K Reserved 0x4002 1000 - 0x4002 13FF 1 K RCC 0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 03FF 32 K Reserved 0x4001 4000 - 0x4001 7FFF 13 K Reserved 0x4001 4200 - 0x4001 4BFF 1 K TIM17 0x4001 4400 - 0x4001 43FF 1 K TIM16 0x4001 4000 - 0x4001 3FFF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 2000 - 0x4002 23FF	1 K	Flash interface
0x4002 0800 - 0x4002 0FFF 2 K Reserved 0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 7FFF 32 K Reserved 0x4001 4C00 - 0x4001 7FFF 13 K Reserved 0x4001 4200 - 0x4001 7FFF 1 K TIM17 0x4001 4800 - 0x4001 4BFF 1 K TIM17 0x4001 4400 - 0x4001 47FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved	АПВТ	0x4002 1400 - 0x4002 1FFF	3 K	Reserved
0x4002 0400 - 0x4002 07FF 1 K DMA2 0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 FFFF 32 K Reserved 0x4001 4C00 - 0x4001 7FFF 13 K Reserved 0x4001 4800 - 0x4001 4BFF 1 K TIM17 0x4001 4400 - 0x4001 4FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 1000 - 0x4002 13FF	1 K	RCC
0x4002 0000 - 0x4002 03FF 1 K DMA1 0x4001 8000 - 0x4001 FFFF 32 K Reserved 0x4001 4C00 - 0x4001 7FFF 13 K Reserved 0x4001 4800 - 0x4001 7FFF 13 K TIM17 0x4001 4800 - 0x4001 48FF 1 K TIM17 0x4001 4400 - 0x4001 47FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 0800 - 0x4002 0FFF	2 K	Reserved
0x4001 8000 - 0x4001 FFFF 32 K Reserved 0x4001 4C00 - 0x4001 7FFF 13 K Reserved 0x4001 4800 - 0x4001 4BFF 1 K TIM17 0x4001 4400 - 0x4001 47FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 0400 - 0x4002 07FF	1 K	DMA2
0x4001 4C00 - 0x4001 7FFF 13 K Reserved 0x4001 4800 - 0x4001 4BFF 1 K TIM17 0x4001 4400 - 0x4001 47FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4002 0000 - 0x4002 03FF	1 K	DMA1
0x4001 4800 - 0x4001 4BFF 1 K TIM17 0x4001 4400 - 0x4001 47FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4001 8000 - 0x4001 FFFF	32 K	Reserved
0x4001 4400 - 0x4001 47FF 1 K TIM16 0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4001 4C00 - 0x4001 7FFF	13 K	Reserved
0x4001 4000 - 0x4001 43FF 1 K TIM15 0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4001 4800 - 0x4001 4BFF	1 K	TIM17
0x4001 3C00 - 0x4001 3FFF 1 K Reserved		0x4001 4400 - 0x4001 47FF	1 K	TIM16
		0x4001 4000 - 0x4001 43FF	1 K	TIM15
		0x4001 3C00 - 0x4001 3FFF	1 K	Reserved
UX4001 3800 - UX4001 3BFF 1 K USART1		0x4001 3800 - 0x4001 3BFF	1 K	USART1
APB2 0x4001 3400 - 0x4001 37FF 1 K Reserved	APB2	0x4001 3400 - 0x4001 37FF	1 K	Reserved
0x4001 3000 - 0x4001 33FF 1 K SPI1		0x4001 3000 - 0x4001 33FF	1 K	SPI1
0x4001 2C00 - 0x4001 2FFF 1 K TIM1		0x4001 2C00 - 0x4001 2FFF	1 K	TIM1
0x4001 0800 - 0x4001 2BFF 9 K Reserved		0x4001 0800 - 0x4001 2BFF	9 K	Reserved
0x4001 0400 - 0x4001 07FF 1 K EXTI		0x4001 0400 - 0x4001 07FF	1 K	EXTI
0x4001 0000 - 0x4001 03FF 1 K SYSCFG + COMP + OPA		0x4001 0000 - 0x4001 03FF	1 K	SYSCFG + COMP + OPAMP

Table 20.STM32F302xB/STM32F302xC memory map, peripheral register boundary addresses

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	addresses (d		
Bus	Boundary address	Size (bytes)	Peripheral
	0x4000 8000 - 0x4000 FFFF	32 K	Reserved
	0x4000 7800 - 0x4000 7FFF	2 K	Reserved
	0x4000 7400 - 0x4000 77FF	1 K	DAC
	0x4000 7000 - 0x4000 73FF	1 K	PWR
	0x4000 6800 - 0x4000 6FFF	2 K	Reserved
	0x4000 6400 - 0x4000 67FF	1 K	bxCAN
	0x4000 6000 - 0x4000 63FF	1 K	USB SRAM 512 bytes
	0x4000 5C00 - 0x4000 5FFF	1 K	USB device FS
	0x4000 5800 - 0x4000 5BFF	1 K	I2C2
	0x4000 5400 - 0x4000 57FF	1 K	I2C1
	0x4000 5000 - 0x4000 53FF	1 K	UART5
	0x4000 4C00 - 0x4000 4FFF	1 K	UART4
	0x4000 4800 - 0x4000 4BFF	1 K	USART3
	0x4000 4400 - 0x4000 47FF	1 K	USART2
APB1	0x4000 4000 - 0x4000 43FF	1 K	I2S3ext
AFDI	0x4000 3C00 - 0x4000 3FFF	1 K	SPI3/I2S3
	0x4000 3800 - 0x4000 3BFF	1 K	SPI2/I2S2
	0x4000 3400 - 0x4000 37FF	1 K	I2S2ext
	0x4000 3000 - 0x4000 33FF	1 K	IWDG
	0x4000 2C00 - 0x4000 2FFF	1 K	WWDG
	0x4000 2800 - 0x4000 2BFF	1 K	RTC
	0x4000 1800 - 0x4000 27FF	4 K	Reserved
	0x4000 1400 - 0x4000 17FF	1 K	Reserved
	0x4000 1000 - 0x4000 13FF	1 K	TIM6
	0x4000 0C00 - 0x4000 0FFF	1 K	Reserved
	0x4000 0800 - 0x4000 0BFF	1 K	TIM4
	0x4000 0400 - 0x4000 07FF	1 K	TIM3
	0x4000 0000 - 0x4000 03FF	1 K	TIM2

Table 20.STM32F302xB/STM32F302xC memory map, peripheral register boundary addresses (continued)



6 Electrical characteristics

6.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to V_{SS} .

6.1.1 Minimum and maximum values

Unless otherwise specified, the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at $T_A = 25$ °C and $T_A = T_A max$ (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean±3ơ).

6.1.2 Typical values

Unless otherwise specified, typical data are based on $T_A = 25$ °C, $V_{DD} = V_{DDA} = 3.3$ V. They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean±2 σ).

6.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

6.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in *Figure 8*.

6.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in Figure 9.



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6.1.6 Power supply scheme



Figure 10. Power supply scheme

- 1. Dotted lines represent the internal connections on low pin count packages, joining the dedicated supply pins.
- Caution: Each power supply pair (V_{DD}/V_{SS} , V_{DDA}/V_{SSA} etc..) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below the appropriate pins on the underside of the PCB to ensure the good functionality of the device.

6.1.7 **Current consumption measurement**







6.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in *Table 21: Voltage characteristics*, *Table 22: Current characteristics*, and *Table 23: Thermal characteristics* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Symbol	Ratings	Min	Мах	Unit
V _{DD} -V _{SS}	External main supply voltage (including $V_{DDA,} \; V_{BAT}$ and $V_{DD})$	-0.3	4.0	
V _{DD} –V _{DDA}	Allowed voltage difference for $V_{DD} > V_{DDA}$	-	0.4	
V _{REF+} -V _{DDA} ⁽²⁾	Allowed voltage difference for $V_{REF+} > V_{DDA}$	-	0.4	
	Input voltage on FT and FTf pins	V _{SS} –0.3	V _{DD} + 4.0	V
V (3)	V _{IN} ⁽³⁾ Input voltage on TTa pins		4.0	
V _{IN} ⁽³⁾ Input voltage on any other pin		V _{SS} –0.3	4.0	
	Input voltage on Boot0 pin		9	
$ \Delta V_{DDx} $	Variations between different V _{DD} power pins	-	50	mV
V _{SSX} –V _{SS}	Variations between all the different ground pins	-	50	
V _{ESD(HBM)}	Electrostatic discharge voltage (human body model)	see Section 6.3.12: Electrical sensitivity characteristics		-

Table 21.	Voltage	characteristics ⁽¹⁾
-----------	---------	--------------------------------

1. All main power (V_{DD}, V_{DDA}) and ground (V_{SS}, V_{SSA}) pins must always be connected to the external power supply, in the permitted range. The following relationship must be respected between V_{DDA} and V_{DD}: V_{DDA} must power on before or at the same time as V_{DD} in the power up sequence. V_{DDA} must be greater than or equal to V_{DD}.

2. V_{REF+} must be always lower or equal than V_{DDA} ($V_{REF+} \leq V_{DDA}$). If unused then it must be connected to V_{DDA} .

3. V_{IN} maximum must always be respected. Refer to *Table 22: Current characteristics* for the maximum allowed injected current values.



Symbol	Ratings	Max.	Unit
ΣI_{VDD}	Total current into sum of all VDD_x power lines (source)	160	
ΣI_{VSS}	Total current out of sum of all VSS_x ground lines (sink)	-160	1
I _{VDD}	Maximum current into each V _{DD_x} power line (source) ⁽¹⁾	100	
I _{VSS}	Maximum current out of each V _{SS_x} ground line (sink) ⁽¹⁾	-100	
	Output current sunk by any I/O and control pin	25	
I _{IO(PIN)}	Output current source by any I/O and control pin	-25	
Σl	Total output current sunk by sum of all IOs and control pins ⁽²⁾	80	- mA
$\Sigma I_{IO(PIN)}$	Total output current sourced by sum of all IOs and control pins ⁽²⁾	-80	
	Injected current on FT, FTf and B pins ⁽³⁾	-5/+0	
I _{INJ(PIN)}	Injected current on TC and RST pin ⁽⁴⁾	± 5	
	Injected current on TTa pins ⁽⁵⁾	± 5	1
$\Sigma I_{INJ(PIN)}$	Total injected current (sum of all I/O and control pins) ⁽⁶⁾	± 25	1

Table 22. Current characteristics

1. All main power (V_{DD} , V_{DDA}) and ground (V_{SS} and V_{SSA}) pins must always be connected to the external power supply, in the permitted range.

2. This current consumption must be correctly distributed over all I/Os and control pins. The total output current must not be sunk/sourced between two consecutive power supply pins referring to high pin count LQFP packages.

3. Positive injection is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.

4. A positive injection is induced by V_{IN} > V_{DD} while a negative injection is induced by V_{IN} < V_{SS}. I_{INJ(PIN)} must never be exceeded. Refer to *Table 21: Voltage characteristics* for the maximum allowed input voltage values.

 A positive injection is induced by V_{IN} > V_{DDA} while a negative injection is induced by V_{IN} < V_{SS}. I_{INJ}(PIN) must never be exceeded. Refer also to *Table 21: Voltage characteristics* for the maximum allowed input voltage values. Negative injection disturbs the analog performance of the device. See note ⁽²⁾ below *Table 70*.

 When several inputs are submitted to a current injection, the maximum ΣI_{INJ(PIN)} is the absolute sum of the positive and negative injected currents (instantaneous values).

Table 23. Thermal characteristics

Symbol	Ratings	Value	Unit
T _{STG}	Storage temperature range	-65 to +150	°C
TJ	Maximum junction temperature	150	°C



6.3 Operating conditions

6.3.1 General operating conditions

Table 24.	General	operating	conditions
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Symbol	Parameter	Conditions	Min	Мах	Unit	
f _{HCLK}	Internal AHB clock frequency	-	0	72		
f _{PCLK1}	Internal APB1 clock frequency	-	0	36	MHz	
f _{PCLK2}	Internal APB2 clock frequency	-	0	72		
V _{DD}	Standard operating voltage	-	2	3.6	V	
V	Analog operating voltage (OPAMP and DAC not used)	Must have a potential equal to or higher than	2	3.6	V	
V _{DDA}	Analog operating voltage (OPAMP and DAC used)	V _{DD}	2.4	3.6	v	
V _{BAT}	Backup operating voltage	-	1.65	3.6	V	
		TC I/O	-0.3	V _{DD} +0.3		
V	I/O input voltage	TTa I/O	-0.3	V _{DD} +0.3 V _{DDA} +0.3 5.5	V	
V_{IN}	no input voltage	FT and FTf I/O ⁽¹⁾	-0.3	5.5	v	
		BOOT0	0	5.5		
	Power dissipation at T _A =	LQFP100	-	488		
P _D	85 °C for suffix 6 or $T_A =$ 105 °C for suffix 7 ⁽²⁾	LQFP64	-	444	mW	
	105 °C for suffix $7^{(2)}$	LQFP48	-	364		
	Ambient temperature for 6 Maximum power dissipation		-40	85	°C	
TA		Low-power dissipation ⁽³⁾	-40	-40 105		
	Ambient temperature for 7	Maximum power dissipation	-40	105	°C	
		mbient temperature for 6 uffix versiondissipation-4085Low-power dissipationLow-power dissipation105mbient temperature for 7 uffix versionMaximum power dissipation-40105Low-power dissipation-40125				
TJ	Junction temperature range	6 suffix version	-40	105	°C	
IJ		7 suffix version	-40	125	U	

1. To sustain a voltage higher than $V_{\text{DD}}\text{+}0.3$ V, the internal pull-up/pull-down resistors must be disabled.

2. If T_A is lower, higher P_D values are allowed as long as T_J does not exceed T_{Jmax} (see Section 7.4: Thermal characteristics).

 In low-power dissipation state, T_A can be extended to this range as long as T_J does not exceed T_{Jmax} (see Section 7.4: Thermal characteristics).



6.3.2 Operating conditions at power-up / power-down

The parameters given in *Table 25* are derived from tests performed under the ambient temperature condition summarized in *Table 24*.

Symbol	Parameter	Conditions	Min	Мах	Unit
+	V _{DD} rise time rate		0	8	
t _{VDD}	V _{DD} fall time rate		20	8	μs/V
+	V _{DDA} rise time rate		0	8	μ5/ν
t _{VDDA}	V _{DDA} fall time rate	-	20	8	

Table 25. Operating conditions at power-up / power-down

6.3.3 Embedded reset and power control block characteristics

The parameters given in *Table 26* are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 24*.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{POR/PDR} ⁽¹⁾	Power on/power down	Falling edge	1.8 ⁽²⁾	1.88	1.96	V
POR/PDR	reset threshold	Rising edge	1.84	1.92	2.0	V
V _{PDRhyst} ⁽¹⁾	PDR hysteresis	-	-	40	-	mV
t _{RSTTEMPO} ⁽³⁾	POR reset temporization	-	1.5	2.5	4.5	ms

 Table 26. Embedded reset and power control block characteristics

1. The PDR detector monitors V_{DD} and also V_{DDA} (if kept enabled in the option bytes). The POR detector monitors only $V_{DD}.$

2. The product behavior is guaranteed by design down to the minimum $V_{\text{POR/PDR}}$ value.

3. Guaranteed by design, not tested in production.



		able voltage detector d	1	115005		
Symbol	Parameter	Conditions	Min ⁽¹⁾	Тур	Max ⁽¹⁾	Unit
V	PVD threshold 0	Rising edge	2.1	2.18	2.26	
V _{PVD0}		Falling edge	2	2.08	2.16	
V	PVD threshold 1	Rising edge	2.19	2.28	2.37	
V _{PVD1}		Falling edge	2.09	2.18	2.27	
V	PVD threshold 2	Rising edge	2.28	2.38	2.48	
V _{PVD2}		Falling edge	2.18	2.28	2.38	
V _{PVD3}	PVD threshold 3	Rising edge	2.38	2.48	2.58	
		Falling edge	2.28	2.38	2.48	V
	PVD threshold 4	Rising edge	2.47	2.58	2.69	v
V _{PVD4}		Falling edge	2.37	2.48	2.59	
V	PVD threshold 5	Rising edge	2.57	2.68	2.79	
V _{PVD5}		Falling edge	2.47	2.58	2.69	
N/	PVD threshold 6	Rising edge	2.66	2.78	2.9	
V _{PVD6}		Falling edge	2.56	2.68	2.8	
V	PVD threshold 7	Rising edge	2.76	2.88	3	
V _{PVD7}		Falling edge	2.66	2.78	2.9	
V _{PVDhyst} ⁽²⁾	PVD hysteresis	-	-	100	-	mV
IDD(PVD)	PVD current consumption	-	-	0.15	0.26	μA

Table 27. Programmable voltage detector characteristics

1. Data based on characterization results only, not tested in production.

2. Guaranteed by design, not tested in production.



6.3.4 Embedded reference voltage

The parameters given in *Table 28* are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 24*.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{REFINT}	Internal reference voltage	–40 °C < T _A < +105 °C	1.16	1.2	1.25	V
	Internal reference voltage	–40 °C < T _A < +85 °C	1.16	1.2	1.24 ⁽¹⁾	V
T _{S_vrefint}	ADC sampling time when reading the internal reference voltage	-	2.2	-	-	μs
V _{RERINT}	Internal reference voltage spread over the temperature range	V _{DD} = 3 V ±10 mV	-	-	10 ⁽²⁾	mV
T _{Coeff}	Temperature coefficient	-	-	-	100 ⁽²⁾	ppm/°C

Table 28. Embedde	ed internal i	reference	voltage
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1. Data based on characterization results, not tested in production.

2. Guaranteed by design, not tested in production.

Table 29. Inte	ernal reference voltage calibi	ration values
Calibration value name	Description	Memory address
V _{REFINT_CAL}	Raw data acquired at temperature of 30 °C	0x1FFF F7BA - 0x1FFF F7BB

V_{DDA}= 3.3 V

Table 29. Internal reference voltage calibration values

6.3.5 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in *Figure 11: Current consumption measurement scheme*.

All Run-mode current consumption measurements given in this section are performed with a reduced code that gives a consumption equivalent to CoreMark code.

Typical and maximum current consumption

The MCU is placed under the following conditions:

- All I/O pins are in input mode with a static value at V_{DD} or V_{SS} (no load)
- All peripherals are disabled except when explicitly mentioned
- The Flash memory access time is adjusted to the f_{HCLK} frequency (0 wait state from 0 to 24 MHz, 1 wait state from 24 to 48 MHz and 2 wait states from 48 to 72 MHz)
- Prefetch in ON (reminder: this bit must be set before clock setting and bus prescaling)
- When the peripherals are enabled $f_{PCLK2} = f_{HCLK}$ and $f_{PCLK1} = f_{HCLK/2}$
- When f_{HCLK} > 8 MHz, the PLL is ON and the PLL input is equal to HSI/2 (4 MHz) or HSE (8 MHz) in bypass mode.



The parameters given in *Table 30* to *Table 34* are derived from tests performed under ambient temperature and supply voltage conditions summarized in *Table 24*.

				All	periphe	erals en	abled	All	periphe	erals dis	abled	
Symbol	Parameter	Conditions	f _{HCLK}	T	М	ax @ T	4 ⁽¹⁾	.	м	ax @ T,	4 ⁽¹⁾	Unit
				Тур	25 °C	85 °C	105 °C	Тур	25 °C	85 °C	105 °C	
			72 MHz	61.2	65.8	67.6	68.5	27.8	30.3	30.7	31.5	
			64 MHz	54.7	59.1	60.2	61.1	24.6	27.2	27.6	28.3	
		External	48 MHz	41.7	45.1	46.2	47.2	19.2	21.1	21.4	21.8	
		clock (HSE	32 MHz	28.1	31.5	32.5	32.7	12.9	14.6	14.8	15.3	
	Supply	bypass)	24 MHz	21.4	23.7	24.4	25.2	10.0	11.4	11.4	12.1	
	current in		8 MHz	7.4	8.4	8.6	9.4	3.6	4.1	4.4	5.0	
	Run mode, executing		1 MHz	1.3	1.6	1.8	2.6	0.8	1.0	1.2	2.1	
	from Flash	Internal clock (HSI)	64 MHz	49.7	54.4	55.4	56.3	24.5	27.2	27.4	28.1	
			48 MHz	37.9	42.2	43.0	43.5	18.9	21.4	21.5	21.6	
			32 MHz	25.8	29.2	29.2	30.0	12.7	14.2	14.6	15.2	
			24 MHz	19.7	22.3	22.6	23.2	6.7	7.7	7.9	8.5	- mA
			8 MHz	6.9	7.8	8.3	8.8	3.5	4.0	4.4	5.0	
I _{DD}			72 MHz	60.8	66.2 ⁽²⁾	69.7	70.4 ⁽²⁾	27.4	31.7 ⁽²⁾	32.2	32.5 ⁽²⁾	
			64 MHz	54.3	59.1	62.2	63.3	24.3	28.3	28.7	28.8	
		External	48 MHz	41.0	45.6	47.3	47.9	18.3	21.6	21.9	22.1	
		clock (HSE	32 MHz	27.6	32.4	32.4	32.9	12.3	15.0	15.2	15.4	
	Supply	bypass)	24 MHz	20.8	23.9	24.3	25.0	9.3	11.3	11.4	12.0	
	current in		8 MHz	6.9	7.8	8.7	9.0	3.1	3.7	4.2	4.9	
	Run mode, executing		1 MHz	0.9	1.2	1.5	2.3	0.4	0.6	1.0	1.8	
	from RAM		64 MHz	49.2	53.9	55.2	57.4	23.9	27.8	28.2	28.4	
			48 MHz	37.3	40.8	41.4	44.1	18.2	21.0	21.6	21.9	
		Internal clock (HSI)	32 MHz	25.1	27.6	29.1	30.1	12.0	14.0	14.5	15.1	
			24 MHz	19.0	21.6	22.1	22.9	6.3	7.2	7.7	8.1	
			8 MHz	6.4	7.3	7.9	8.4	3.0	3.5	4.0	4.7	



				All	periphe	erals en	abled	All	periphe	erals dis	abled	
Symbol	Parameter	Conditions	f _{HCLK}	_	м	ax @ T	A ⁽¹⁾	Turn	м	Unit		
				Тур	25 °C	85 °C	105 °C	Тур	25 °C	85 °C	105 °C	
			72 MHz	44.0	48.4	49.4	50.5	6.6	7.5	7.9	8.7	
			64 MHz	39.2	43.3	44.0	45.2	6.0	6.8	7.2	7.9	
		External	48 MHz	29.6	32.7	33.3	34.3	4.5	5.2	5.6	6.3	- mA
	Supply	clock (HSE bypass)	32 MHz	19.7	23.3	23.3	23.5	3.1	3.5	4.0	4.8	
	Supply current in		24 MHz	14.9	17.6	17.8	18.3	2.4	2.8	3.3	3.9	
I	Sleep mode,		8 MHz	4.9	5.7	6.1	6.9	0.8	1.0	1.4	2.2	
I _{DD}	executing		1 MHz	0.6	0.9	1.2	2.1	0.1	0.3	0.6	1.5	
	from Flash or RAM		64 MHz	34.2	38.1	39.2	40.3	5.7	6.3	6.8	7.5	
			48 MHz	25.8	28.7	29.6	30.3	4.3	4.8	5.2	5.9	-
		Internal clock (HSI)	32 MHz	17.4	19.4	19.9	20.7	2.9	3.2	3.7	4.5	
			24 MHz	13.2	15.1	15.6	15.9	1.5	1.8	2.2	2.9	
			8 MHz	4.5	5.0	5.6	6.2	0.7	0.9	1.2	2.1]

Table 30. Typical and maximum current consumption from V_{DD} supply at V_{DD} = 3.6V (continued)

1. Data based on characterization results, not tested in production unless otherwise specified.

2. Data based on characterization results and tested in production with code executing from RAM.

					V _{DDA}	= 2.4 V			V _{DDA}	= 3.6 \	/	
Symbol	Parameter	Conditions (1)	f _{HCLK}	Turn	Max @ T _A ⁽²⁾				М	Unit		
				Тур	25 °C	85 °C	105 °C	Тур	25 °C	85 °C	105 °C	
			72 MHz	225	276	289	297	245	302	319	329	
			64 MHz	198	249	261	268	216	270	284	293	
	Supply current in Run/Sleep	HSE bypass	48 MHz	149	195	204	211	159	209	222	230	
			32 MHz	102	145	152	157	110	154	162	169	
			24 MHz	80	119	124	128	86	126	131	135	
1	mode,		8 MHz	2	3	4	6	3	4	5	9	
I _{DDA}	code executing		1 MHz	2	3	5	7	3	4	6	9	μA
	from Flash		64 MHz	270	323	337	344	299	354	371	381	
	or RAM		48 MHz	220	269	280	286	244	293	309	318	
		HSI clock	32 MHz	173	218	228	233	193	239	251	257	
			24 MHz	151	194	200	204	169	211	219	225	
			8 MHz	73	97	99	103	88	105	110	116	

1. Current consumption from the V_{DDA} supply is independent of whether the peripherals are on or off. Furthermore when the PLL is off, I_{DDA} is independent from the frequency.

2. Data based on characterization results, not tested in production.



Symbol	Parameter	Conditions		Тур (@V _{DD} ((V _{DD} =\						
			2.0 V	2.4 V	2.7 V	3.0 V	3.3 V	3.6 V	T _A = 25 °C	T _A = 85 °C	T _A = 105 °C	Unit
I _{DD} Supply current	Supply	Regulator in run mode, all oscillators OFF	20.05	20.33	20.42	20.50	20.67	20.80	44.2 ⁽²⁾	350	735 ⁽²⁾	
	Stop mode	Regulator in low-power mode, all oscillators OFF	7.63	7.77	7.90	8.07	8.17	8.33	30.6 ⁽²⁾	335	720 ⁽²⁾	μA
	1- 1- 2	LSI ON and IWDG ON	0.80	0.96	1.09	1.23	1.37	1.51	-	-	-	I.
		LSI OFF and IWDG OFF	0.60	0.74	0.83	0.93	1.02	1.11	5.0 ⁽²⁾	7.8	13.3 ⁽²⁾	

Table 32. Typical and maximum V _{DD}	consumption in Stop and Standby modes

1. Data based on characterization results, not tested in production unless otherwise specified.

2. Data based on characterization results and tested in production.

			Conditions		Тур @)V _{DD} (V _{DD} =	V _{DDA})			Max ⁽¹⁾		
Symbol	Parameter				2.4 V	2.7 V	3.0 V	3.3 V	3.6 V	T _A = 25 °C	Т _А = 85 °С	T _A = 105 °C	Unit
	Supply		Regulator in run mode, all oscillators OFF	1.81	1.95	2.07	2.20	2.35	2.52	3.7	5.5	8.8	
	current in	bu	Regulator in low-power mode, all oscillators OFF	1.81	1.95	2.07	2.20	2.35	2.52	3.7	5.5	8.8	
			LSI ON and IWDG ON	2.22	2.42	2.59	2.78	3.0	3.24	-	-	-	
	current in Standby mode	V _{DDA}	LSI OFF and IWDG OFF	1.69	1.82	1.94	2.08	2.23	2.40	3.5	5.4	9.2	μA
I _{DDA}	Supply	ЦЦ	Regulator in run mode, all oscillators OFF	1.05	1.08	1.10	1.15	1.22	1.29	-	-	-	μΑ
	Current in Stop mode	oring (Regulator in low-power mode, all oscillators OFF	1.05	1.08	1.10	1.15	1.22	1.29	-	-	-	
			LSI ON and IWDG ON	1.44	1.52	1.60	1.71	1.84	1.98	-	-	-	
	current in Standby Standby mode	LSI OFF and IWDG OFF	0.93	0.95	0.98	1.02	1.08	1.15	-	-	-		

Table 33. Typical and maximum V_{DDA} consumption in Stop and Standby modes

1. Data based on characterization results, not tested in production.

Note: The total consumption is the sum of IDD and IDDA.



Symbol	Para	Conditions				Тур @'	/ _{BAT}				Max @V _{BAT} = 3.6 V		Unit	
Symbol	meter	(1)	1.65V	1.8V	2V	2.4V	2.7V	3V	3.3V	3.6V	T _A = 25°C	Т _А = 85°С		Unit
	Backup domain	LSE & RTC ON; "Xtal mode" lower driving capability; LSEDRV[1: 0] = '00'	0.48	0.50	0.52	0.58	0.65	0.72	0.80	0.90	1.1	1.5	2.0	
IDD_VBAT	supply current	LSE & RTC ON; "Xtal mode" higher driving capability; LSEDRV[1: 0] = '11'	0.83	0.86	0.90	0.98	1.03	1.10	1.20	1.30	1.5	2.2	2.9	μA

Table 34. Typical and maximum current consumption from V_{BAT} supply

1. Crystal used: Abracon ABS07-120-32.768 kHz-T with a CL of 6 pF for typical values.

2. Data based on characterization results, not tested in production.



Figure 12. Typical V_{BAT} current consumption (LSE and RTC ON/LSEDRV[1:0] = '00')



Typical current consumption

The MCU is placed under the following conditions:

- V_{DD} = V_{DDA} = 3.3 V
- All I/O pins available on each package are in analog input configuration
- The Flash access time is adjusted to f_{HCLK} frequency (0 wait states from 0 to 24 MHz, 1 wait state from 24 to 48 MHz and 2 wait states from 48 MHz to 72 MHz), and Flash prefetch is ON
- When the peripherals are enabled, $f_{APB1} = f_{AHB/2}$, $f_{APB2} = f_{AHB}$
- PLL is used for frequencies greater than 8 MHz
- AHB prescaler of 2, 4, 8,16 and 64 is used for the frequencies 4 MHz, 2 MHz, 1 MHz, 500 kHz and 125 kHz respectively.

Table 35. Typical current consumption in Run mode, code with data processing running from Flash

				Т	ур	
Symbol	Parameter	Conditions	fhclk	Peripherals enabled	Peripherals disabled	Unit
			72 MHz	61.3	28.0	
			64 MHz	54.8	25.4	
			48 MHz	41.9	19.3	
			32 MHz	28.5	13.3	
			24 MHz	21.8	10.4	
	Supply current in Run mode from		16 MHz	14.9	7.2	mA
I _{DD}	V _{DD} supply		8 MHz	7.7	3.9	
			4 MHz	4.5	2.5	
			2 MHz	2.8	1.7	
			1 MHz	1.9	1.3	
		Running from HSE	500 kHz	1.4	1.1	
		crystal clock 8 MHz,	125 kHz	1.1	0.9	
		code executing from	72 MHz	240.3	239.5	
		Flash	64 MHz	210.9	210.3	
			48 MHz	155.8	155.6	
			32 MHz	105.7	105.6	
			24 MHz	82.1	82.0	
I _{DDA} ^{(1) (2)}	Supply current in Run mode from		16 MHz	58.8	58.8	μA
'DDA`´``	V _{DDA} supply		8 MHz	2.4	2.4	- μΑ
	DDA		4 MHz	2.4	2.4	
			2 MHz	2.4	2.4	1
			1 MHz	2.4	2.4	1
			500 kHz	2.4	2.4	1
			125 kHz	2.4	2.4	1

1. V_{DDA} monitoring is ON.

2. When peripherals are enabled, the power consumption of the analog part of peripherals such as ADC, DAC, Comparators, OpAmp etc. is not included. Refer to the tables of characteristics in the subsequent sections.



				Ţ	/p		
Symbol	Parameter	Conditions f _{HCLK}		Peripherals enabled	Peripherals disabled	Unit	
			72 MHz	44.1	7.0		
			64 MHz	39.7	6.3		
			48 MHz	30.3	4.9		
			32 MHz	20.5	3.5		
			24 MHz	15.4	2.8		
	Supply current in		16 MHz	10.6	2.0	- m A	
I _{DD}	Sleep mode from V _{DD} supply		8 MHz	5.4	1.1	– mA	
			4 MHz	3.2	1.0		
			2 MHz	2.1	0.9		
			1 MHz	1.5	0.8		
		Running from HSE	500 kHz	1.2	0.8		
		crystal clock 8 MHz,	125 kHz	1.0	0.8		
		code executing from	72 MHz	239.7	238.5		
		Flash or RAM	64 MHz	210.5	209.6		
			48 MHz	155.0	155.6		
			32 MHz	105.3	105.2		
			24 MHz	81.9	81.8		
I _{DDA} ^{(1) (2)}	Supply current in Sleep mode from		16 MHz	58.7	58.6		
^I DDA` / ` /	V _{DDA} supply		8 MHz	2.4	2.4	- μΑ	
			4 MHz	2.4	2.4		
			2 MHz	2.4	2.4	1	
			1 MHz	2.4	2.4	1	
			500 kHz	2.4	2.4		
			125 kHz	2.4	2.4	1	

Table 36. Typical current cons	umption in Sleep mode.	, code running from Flash or RAM

1. V_{DDA} monitoring is ON.

2. When peripherals are enabled, the power consumption of the analog part of peripherals such as ADC, DAC, Comparators, OpAmp etc. is not included. Refer to the tables of characteristics in the subsequent sections.



I/O system current consumption

The current consumption of the I/O system has two components: static and dynamic.

I/O static current consumption

All the I/Os used as inputs with pull-up generate current consumption when the pin is externally held low. The value of this current consumption can be simply computed by using the pull-up/pull-down resistors values given in *Table 54: I/O static characteristics*.

For the output pins, any external pull-down or external load must also be considered to estimate the current consumption.

Additional I/O current consumption is due to I/Os configured as inputs if an intermediate voltage level is externally applied. This current consumption is caused by the input Schmitt trigger circuits used to discriminate the input value. Unless this specific configuration is required by the application, this supply current consumption can be avoided by configuring these I/Os in analog mode. This is notably the case of ADC input pins which should be configured as analog inputs.

Caution: Any floating input pin can also settle to an intermediate voltage level or switch inadvertently, as a result of external electromagnetic noise. To avoid current consumption related to floating pins, they must either be configured in analog mode, or forced internally to a definite digital value. This can be done either by using pull-up/down resistors or by configuring the pins in output mode.

I/O dynamic current consumption

In addition to the internal peripheral current consumption (see *Table 38: Peripheral current consumption*), the I/Os used by an application also contribute to the current consumption. When an I/O pin switches, it uses the current from the MCU supply voltage to supply the I/O pin circuitry and to charge/discharge the capacitive load (internal or external) connected to the pin:

$$I_{SW} = V_{DD} \times f_{SW} \times C$$

where

 I_{SW} is the current sunk by a switching I/O to charge/discharge the capacitive load

V_{DD} is the MCU supply voltage

 f_{SW} is the I/O switching frequency

C is the total capacitance seen by the I/O pin: C = C_{INT} + C_{EXT} + C_S

The test pin is configured in push-pull output mode and is toggled by software at a fixed frequency.



STM32F302xB STM32F302xC

Symbol	Parameter	Conditions ⁽¹⁾	l/O toggling frequency (f _{SW})	Тур	Unit
			2 MHz	Typ 0.90 0.93 1.16 1.60 2.51 2.97 0.93 1.06 1.47 2.26 3.39 5.99 1.03 1.30 1.79 3.01 5.99 1.10 1.30 1.79 3.01 5.99 1.10 1.30 1.54 2.06 3.47 8.35 1.20 1.54 2.46 4.51 9.98	
	Parameter I/O current consumption		4 MHz	0.93	
		$V_{DD} = 3.3 V$	8 MHz	ggling hcy (f _{SW}) Typ AHz 0.90 AHz 0.93 AHz 1.16 MHz 1.60 MHz 2.51 MHz 0.93 MHz 1.60 MHz 2.51 MHz 2.97 AHz 1.06 MHz 2.97 AHz 1.06 MHz 2.97 AHz 1.06 MHz 3.39 MHz 3.39 MHz 1.03 AHz 1.03 AHz 1.30 AHz 1.79 MHz 3.01 MHz 5.99 AHz 1.10 AHz 1.31 MHz 3.47 MHz 3.47 MHz 1.20 AHz 1.54 AHz 1.54	
		$C_{ext} = 0 \text{ pr}^2$ $C = C_{INT} + C_{EXT} + C_S$	18 MHz	1.60	
			36 MHz	0.90 0.93 1.16 1.60 2.51 2.97 0.93 1.06 1.47 2.26 3.39 5.99 1.03 1.30 1.79 3.01 5.99 1.03 1.30 1.79 3.01 5.99 1.10 1.31 2.06 3.47 8.35 1.20 1.54 2.46 4.51	
			48 MHz		
	SW I/O current C = C _{INT} + C _E) $V_{DD} = 3.3$ $C_{ext} = 0 \text{ p}$ $C = C_{INT} + C_{E}$ $V_{DD} = 3.3$ $C_{ext} = 10 \text{ p}$ $C = C_{INT} + C_{E}$ $V_{DD} = 3.3$ $C_{ext} = 22 \text{ p}$ $C = C_{INT} + C_{E}$ $V_{DD} = 3.3$ $C_{ext} = 33 \text{ p}$ $C = C_{INT} + C_{E}$ $V_{DD} = 3.3$ $C_{ext} = 33 \text{ p}$ $C = C_{INT} + C_{E}$		2 MHz	0.93	
		4 MHz	1.06		
		$V_{DD} = 3.3 V$	4 MHz 1.06 3 V 8 MHz 1.47 pF 18 MHz 2.26 36 MHz 3.39 48 MHz 5.99 2 MHz 1.03	8 MHz 1.4	
		$C = C_{INT} + C_{EXT} + C_S$	18 MHz	2.26	
			36 MHz	0.90 0.93 1.16 1.60 2.51 2.97 0.93 1.06 1.47 2.26 3.39 5.99 1.03 1.30 1.79 3.01 5.99 1.10 1.31 2.06 3.47 8.35 1.20 1.54 2.46 4.51]
			48 MHz	5.99	
			2 MHz	1.03	
I _{SW}		V סס = 3.3 V	4 MHz	1.30	mA
		C _{ext} = 22 pF	8 MHz	0.90 0.93 1.16 1.60 2.51 2.97 0.93 1.06 1.47 2.26 3.39 5.99 1.03 1.30 1.79 3.01 5.99 1.10 1.31 2.06 3.47 8.35 1.20 1.54 2.46 4.51	
		$C = C_{INT} + C_{EXT} + C_{S}$	18 MHz	3.01	
			36 MHz	ryp ryp or MHz 0.90 MHz 0.93 MHz 1.16 MHz 1.60 MHz 2.51 MHz 0.93 MHz 2.51 MHz 0.93 MHz 2.97 MHz 0.93 MHz 1.06 MHz 1.47 MHz 1.266 MHz 1.47 MHz 1.03 MHz 1.03 MHz 1.03 MHz 1.03 MHz 1.30 m MHz 1.10 MHz 1.10 MHz 1.31 m m MHz 1.31 m m MHz 1.31 m m MHz 1.206 m m MHz 1.20 m m MHz 1.54 m m MHz 1.54 m m	
			2 MHz		
		V _{DD} = 3.3 V	4 MHz	1.31	
		C _{ext} = 33 pF	8 MHz	2.06	
		$C = C_{INT} + C_{EXT} + C_{S}$	18 MHz	3.47	
			36 MHz	1.03 1.30 1.79 3.01 5.99 1.10 1.31 2.06 3.47	
			2 MHz	1.20]
		V _{DD} = 3.3 V	4 MHz	1.54	
		C _{ext} = 47 pF	8 MHz	2.46	
		$C = C_{INT} + C_{EXT} + C_S$	18 MHz	0.93 1.16 1.60 2.51 2.97 0.93 1.06 1.47 2.26 3.39 5.99 1.03 1.30 1.79 3.01 5.99 1.10 1.31 2.06 3.47 8.35 1.20 1.54 2.46 4.51	
			36 MHz	9.98	

Table 37. Switching output I/O current consumption

1. CS = 5 pF (estimated value).



On-chip peripheral current consumption

The MCU is placed under the following conditions:

- all I/O pins are in analog input configuration
- all peripherals are disabled unless otherwise mentioned
- the given value is calculated by measuring the current consumption
 - with all peripherals clocked off
 - with only one peripheral clocked on
- ambient operating temperature at 25°C and $V_{DD} = V_{DDA} = 3.3$ V.

Table 38. Peripheral current consumption

Derinherel	Typical consumption ⁽¹⁾	Unit
Peripheral -	I _{DD}	
BusMatrix ⁽²⁾	12.6	
DMA1	7.6	
DMA2	6.1	
CRC	2.1	
GPIOA	10.0	
GPIOB	10.3	
GPIOC	2.2	
GPIOD	8.8	
GPIOE	3.3	
GPIOF	3.0	
TSC	5.5	
ADC1&2	17.3	
APB2-Bridge ⁽³⁾	3.6	
SYSCFG	7.3	μΑ/MHz
TIM1	40.0	
SPI1	8.8	
USART1	23.3	
TIM15	17.1	
TIM16	10.1	
TIM17	11.0	
APB1-Bridge ⁽³⁾	6.1	
TIM2	49.1	
TIM3	38.8	
TIM4	38.3	

Typical consumption ⁽¹⁾									
Peripheral	Typical consumption ⁽¹⁾	Unit							
. on phone.	I _{DD}								
TIM6	9.7								
WWDG	6.4								
SPI2	40.4								
SPI3	40.0								
USART2	41.9								
USART3	40.2								
UART4	36.5								
UART5	30.8	µA/MHz							
I2C1	10.5								
I2C2	10.4								
USB	26.2								
CAN	33.4								
PWR	5.7								
DAC	15.4								

Table 38. Peripheral current consumption (continued)

1. The power consumption of the analog part (I_{DDA}) of peripherals such as ADC, DAC, Comparators, OpAmp etc. is not included. Refer to the tables of characteristics in the subsequent sections.

2. BusMatrix is automatically active when at least one master is ON (CPU, DMA1 or DMA2).

3. The APBx bridge is automatically active when at least one peripheral is ON on the same bus.



6.3.6 Wakeup time from low-power mode

The wakeup times given in *Table 39* are measured starting from the wakeup event trigger up to the first instruction executed by the CPU:

- For Stop or Sleep mode: the wakeup event is WFE.
- WKUP1 (PA0) pin is used to wakeup from Standby, Stop and Sleep modes.

All timings are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 24*.

						- 5	-			
Gumbal	Deremeter	Conditions	Typ @Vdd, V _{DD} = V _{DDA}					Мах	Unit	
Symbol	Parameter	Conditions	2.0 V	2.4 V	2.7 V	3 V	3.3 V	3.6 V	wax	Unit
	Wakeup from	Regulator in run mode	4.1	3.9	3.8	3.7	3.6	3.5	4.5	
^t wustop	Stop mode	Regulator in low-power mode	7.9	6.7	6.1	5.7	5.4	5.2	9	μs
twustandby ⁽¹⁾	Wakeup from Standby mode	LSI and IWDG OFF	69.2	60.3	56.4	53.7	51.7	50	100	
t _{WUSLEEP}	Wakeup from Sleep mode	-			6	6			-	CPU clock cycles

Table 39. Low-power mode wakeup timings

1. Data based on characterization results, not tested in production.



6.3.7 External clock source characteristics

High-speed external user clock generated from an external source

In bypass mode the HSE oscillator is switched off and the input pin is a standard GPIO. The external clock signal has to respect the I/O characteristics in *Section 6.3.14*. However, the recommended clock input waveform is shown in *Figure 13*.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _{HSE_ext}	User external clock source frequency ⁽¹⁾		1	8	32	MHz
V _{HSEH}	OSC_IN input pin high level voltage		$0.7V_{DD}$	-	V _{DD}	V
V _{HSEL}	OSC_IN input pin low level voltage	-	V_{SS}	-	$0.3V_{DD}$	
t _{w(HSEH)} t _{w(HSEL)}	OSC_IN high or low time ⁽¹⁾		15	-	-	ns
t _{r(HSE)} t _{f(HSE)}	OSC_IN rise or fall time ⁽¹⁾		-	-	20	115

1. Guaranteed by design, not tested in production.



Figure 13. High-speed external clock source AC timing diagram



Low-speed external user clock generated from an external source

In bypass mode the LSE oscillator is switched off and the input pin is a standard GPIO. The external clock signal has to respect the I/O characteristics in *Section 6.3.14*. However, the recommended clock input waveform is shown in *Figure 14*

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _{LSE_ext}	User External clock source frequency ⁽¹⁾		-	32.768	1000	kHz
V _{LSEH}	OSC32_IN input pin high level voltage		0.7V _{DD}	-	V _{DD}	V
V _{LSEL}	OSC32_IN input pin low level voltage	-	V _{SS}	-	0.3V _{DD}	v
t _{w(LSEH)} t _{w(LSEL)}	OSC32_IN high or low time ⁽¹⁾		450	-	-	20
t _{r(LSE)} t _{f(LSE)}	OSC32_IN rise or fall time ⁽¹⁾		-	-	50	ns

 Table 41. Low-speed external user clock characteristics

1. Guaranteed by design, not tested in production.



Figure 14. Low-speed external clock source AC timing diagram


High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 32 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on design simulation results obtained with typical external components specified in *Table 42*. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

Symbol	Parameter	Conditions ⁽¹⁾	Min ⁽²⁾	Тур	Max ⁽²⁾	Unit
f _{OSC_IN}	Oscillator frequency	-	4	8	32	MHz
R _F	Feedback resistor	-	-	200		kΩ
		During startup ⁽³⁾	-	-	8.5	
		V _{DD} =3.3 V, Rm= 30Ω CL=10 pF@8 MHz	-	0.4	-	
	HSE current consumption	V _{DD} =3.3 V, Rm= 45Ω CL=10 pF@8 MHz	-	0.5	-	
I _{DD}		V _{DD} =3.3 V, Rm= 30Ω CL=5 pF@32 MHz	-	0.8	-	mA
		V _{DD} =3.3 V, Rm= 30Ω CL=10 pF@32 MHz	-	1	-	
		V _{DD} =3.3 V, Rm= 30Ω CL=20 pF@32 MHz	-	1.5	-	
9 _m	Oscillator transconductance	Startup	10	-	-	mA/V
t _{SU(HSE)} ⁽⁴⁾	Startup time	V _{DD} is stabilized	-	2	-	ms

1. Resonator characteristics given by the crystal/ceramic resonator manufacturer.

2. Guaranteed by design, not tested in production.

3. This consumption level occurs during the first 2/3 of the $t_{SU(HSE)}$ startup time.

 t_{SU(HSE)} is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.



For C_{L1} and C_{L2}, it is recommended to use high-quality external ceramic capacitors in the 5 pF to 25 pF range (typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator (see *Figure 15*). C_{L1} and C_{L2} are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of C_{L1} and C_{L2}. PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing C_{L1} and C_{L2}.

Note: For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website <u>www.st.com</u>.





1. R_{EXT} value depends on the crystal characteristics.



Low-speed external clock generated from a crystal/ceramic resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on design simulation results obtained with typical external components specified in *Table 43*. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

Symbol	Parameter	Conditions ⁽¹⁾	Min ⁽²⁾	Тур	Max ⁽²⁾	Unit	
		LSEDRV[1:0]=00 lower driving capability	-	0.5	0.9		
		LSEDRV[1:0]=01 medium low driving capability	-	-	1		
I _{DD}	LSE current consumption	LSEDRV[1:0]=10 medium high driving capability	-	-	1.3	μA	
		LSEDRV[1:0]=11 higher driving capability	-	-	1.6		
	Oscillator transconductance	LSEDRV[1:0]=00 lower driving capability	5	-	-		
a		LSEDRV[1:0]=01 medium low driving capability	8	-	-		
9 _m		LSEDRV[1:0]=10 medium high driving capability	15	-	-	μΑ/V	
		LSEDRV[1:0]=11 higher driving capability	25	-	-		
t _{SU(LSE)} ⁽³⁾	Startup time	V _{DD} is stabilized	-	2	-	s	

Table 43. LSE oscillator characteristics (f_{LSE} = 32.768 kHz)

1. Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for ST microcontrollers".

2. Guaranteed by design, not tested in production.

3. t_{SU(LSE)} is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal and it can vary significantly with the crystal manufacturer.

Note: For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website <u>www.st.com</u>.





Figure 16. Typical application with a 32.768 kHz crystal

Note:

An external resistor is not required between OSC32_IN and OSC32_OUT and it is forbidden to add one.



6.3.8 Internal clock source characteristics

The parameters given in *Table 44* are derived from tests performed under ambient temperature and supply voltage conditions summarized in *Table 24*.

High-speed internal (HSI) RC oscillator

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
f _{HSI}	Frequency	-	-	8	-	MHz		
TRIM	HSI user trimming step	-	-	-	1 ⁽²⁾	%		
DuCy _(HSI)	Duty cycle	-	45 ⁽²⁾	-	55 ⁽²⁾	%		
	ACC _{HSI} Accuracy of the HSI oscillator	T _A = -40 to 105°C	-2.8 ⁽³⁾	-	3.8 ⁽³⁾			
		T _A = -10 to 85°C	-1.9 ⁽³⁾	-	2.3 ⁽³⁾	%		
ACC _{HSI}		T _A = 0 to 85°C	-1.9 ⁽³⁾	-	2 ⁽³⁾			
		$T_A = 0$ to $70^{\circ}C$	-1.3 ⁽³⁾	-	2 ⁽³⁾			
		T _A = 0 to 55°C	-1 ⁽³⁾	-	2 ⁽³⁾			
		$T_A = 25^{\circ}C^{(4)}$	-1	-	1			
t _{su(HSI)}	HSI oscillator startup time	-	1 ⁽²⁾	-	2 ⁽²⁾	μs		
I _{DDA(HSI)}	HSI oscillator power consumption	-	-	80	100 ⁽²⁾	μA		

Table 44. HSI oscillator characteristics⁽¹⁾

1. V_{DDA} = 3.3 V, T_A = –40 to 105 $^\circ C$ unless otherwise specified.

2. Guaranteed by design, not tested in production.

3. Data based on characterization results, not tested in production.

4. Factory calibrated, parts not soldered.



Figure 17. HSI oscillator accuracy characterization results for soldered parts



Low-speed internal (LSI) RC oscillator

Table 45. LSI oscillator cha	aracteristics
------------------------------	---------------

Symbol	Parameter	Min	Тур	Max	Unit
f _{LSI}	f _{LSI} Frequency		40	50	kHz
t _{su(LSI)} ⁽²⁾	LSI oscillator startup time	-	-	85	μs
I _{DD(LSI)} ⁽²⁾			0.75	1.2	μΑ

1. V_{DDA} = 3.3 V, T_A = –40 to 105 $^\circ\text{C}$ unless otherwise specified.

2. Guaranteed by design, not tested in production.

6.3.9 PLL characteristics

The parameters given in *Table 46* are derived from tests performed under ambient temperature and supply voltage conditions summarized in *Table 24*.

Symbol	Parameter		Unit					
		Min	Тур	Мах	Unit			
f	PLL input clock ⁽¹⁾	1 ⁽²⁾	-	24 ⁽²⁾	MHz			
f _{PLL_IN}	PLL input clock duty cycle	40 ⁽²⁾	-	60 ⁽²⁾	%			
f _{PLL_OUT}	PLL multiplier output clock	16 ⁽²⁾	-	72	MHz			
t _{LOCK}	PLL lock time	-	-	200 ⁽²⁾	μs			
Jitter	Cycle-to-cycle jitter	-	-	300 ⁽²⁾	ps			

Table 46. PLL characteristics

1. Take care of using the appropriate multiplier factors so as to have PLL input clock values compatible with the range defined by f_PLL_OUT.

2. Guaranteed by design, not tested in production.



6.3.10 Memory characteristics

Flash memory

The characteristics are given at T_{A} = –40 to 105 $^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max ⁽¹⁾	Unit
t _{prog}	16-bit programming time	T _A = -40 to +105 °C	40	53.5	60	μs
t _{ERASE} P	Page (2 KB) erase time	$T_A = -40$ to +105 °C	20	-	40	ms
t _{ME}	Mass erase time	$T_A = -40$ to +105 °C	20	-	40	ms
	Supply current	Write mode	-	-	10	mA
IDD		Erase mode	-	-	12	mA

Table 47. Flash memory characteristics

1. Guaranteed by design, not tested in production.

0h.e.l	Parameter	O and it is an	Value	11 14
Symbol		Conditions	Min ⁽¹⁾	Unit
N _{END}	Endurance	$T_A = -40$ to +85 °C (6 suffix versions) $T_A = -40$ to +105 °C (7 suffix versions)	10	kcycles
		1 kcycle ⁽²⁾ at T _A = 85 °C	30	
t _{RET}	Data retention	1 kcycle ⁽²⁾ at T _A = 105 °C	10	Years
		10 kcycles ⁽²⁾ at T _A = 55 °C	20	

Table 48. Flash memory endurance and data retention

1. Data based on characterization results, not tested in production.

2. Cycling performed over the whole temperature range.



6.3.11 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports). the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- Electrostatic discharge (ESD) (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- FTB: A Burst of Fast Transient voltage (positive and negative) is applied to V_{DD} and V_{SS} through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in *Table 49*. They are based on the EMS levels and classes defined in application note AN1709.

Symbol	Parameter	Conditions	Level/ Class
V _{FESD}	Voltage limits to be applied on any I/O pin to induce a functional disturbance	V_{DD} = 3.3 V, LQFP100, T _A = +25°C, f _{HCLK} = 72 MHz conforms to IEC 61000-4-2	3B
V _{EFTB}	Fast transient voltage burst limits to be applied through 100 pF on V_{DD} and V_{SS} pins to induce a functional disturbance	V_{DD} = 3.3 V, LQFP100, T _A = +25°C, f _{HCLK} = 72 MHz conforms to IEC 61000-4-4	4A

Table 49. EMS characteristics

Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

Software recommendations

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)



Prequalification trials

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

Electromagnetic Interference (EMI)

The electromagnetic field emitted by the device are monitored while a simple application is executed (toggling 2 LEDs through the I/O ports). This emission test is compliant with IEC 61967-2 standard which specifies the test board and the pin loading.

	Symbol	Parameter	Conditions	Monitored frequency band	Max vs. [f _{HSE} /f _{HCLK}] 8/72 MHz	Unit
ſ		V 0.0.V.T. 05.00	0.1 to 30 MHz	7		
	S	Peak level	V _{DD} = 3.6 V, T _A = 25 °C, LQFP100 package	30 to 130 MHz	20	dBµV
	S _{EMI}		compliant with IEC 61967-2	130 MHz to 1GHz	27	
				SAE EMI Level	4	-

Table 50. EMI characteristics

6.3.12 Electrical sensitivity characteristics

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts \times (n+1) supply pins). This test conforms to the JESD22-A114/C101 standard.

Symbol	Ratings	Conditions	Class	Maximum value ⁽¹⁾	Unit
V _{ESD(HBM)}	Electrostatic discharge voltage (human body model)	$T_A = +25 \degree C$, conforming to JESD22-A114	2	2000	
V _{ESD(CDM)}	Electrostatic discharge voltage (charge device model)	T _A = +25 °C, conforming to ANSI/ESD STM5.3.1	II	500	V

 Table 51. ESD absolute maximum ratings

1. Data based on characterization results, not tested in production.



Static latch-up

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply overvoltage is applied to each power supply pin
- A current injection is applied to each input, output and configurable I/O pin

These tests are compliant with EIA/JESD 78A IC latch-up standard.

Table	52.	Electrical	sensitivities
Table	JZ.	LIECUICAI	36113111411163

Symbol	Parameter	Conditions	Class	
LU	Static latch-up class	$T_A = +105$ °C conforming to JESD78A	II level A	

6.3.13 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below V_{SS} or above V_{DD} (for standard, 3 V-capable I/O pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (higher than 5 LSB TUE), out of conventional limits of induced leakage current on adjacent pins (out of $-5 \mu A/+0 \mu A$ range), or other functional failure (for example reset occurrence or oscillator frequency deviation).

The test results are given in Table 53.



		Functional s	usceptibility	
Symbol	Description	Negative injection	Positive injection	Unit
	Injected current on BOOT0	- 0	NA	
	Injected current on PC0, PC1, PC2, PC3, PF2, PA0, PA1, PA2, PA3, PF4, PA4, PA5, PA6, PA7, PC4, PC5, PB2 with induced leakage current on other pins from this group less than -50 μ A	- 5	-	
I _{INJ}	Injected current on PB0, PB1, PE7, PE8, PE9, PE10, PE11, PE12, PE13, PE14, PE15, PB12, PB13, PB14, PB15, PD8, PD9, PD10, PD11, PD12, PD13, PD14 with induced leakage current on other pins from this group less than -50 µA	- 5	-	mA
	Injected current on PC0, PC1, PC2, PC3, PF2, PA0, PA1, PA2, PA3, PF4, PA4, PA5, PA6, PA7, PC4, PC5, PB2, PB0, PB1, PE7, PE8, PE9, PE10, PE11, PE12, PE13, PE14, PE15, PB12, PB13, PB14, PB15, PD8, PD9, PD10, PD11, PD12, PD13, PD14 with induced leakage current on other pins from this group less than 400 μ A	-	+5	
	Injected current on any other FT and FTf pins	- 5	NA	
	Injected current on any other pins	- 5	+5	

Note: It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.



6.3.14 I/O port characteristics

General input/output characteristics

Unless otherwise specified, the parameters given in *Table 54* are derived from tests performed under the conditions summarized in *Table 24*. All I/Os are CMOS and TTL compliant.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit	
		TC and TTa I/O	-	-	0.3 V _{DD} +0.07 ⁽¹⁾		
	Low level input	FT and FTf I/O	-	-	$0.475 V_{DD}$ - 0.2 ⁽¹⁾		
V_{IL}	voltage	BOOT0	-	-	0.3 V _{DD} -0.3 ⁽¹⁾		
		All I/Os except BOOT0	-	-	0.3 V _{DD} ⁽²⁾	v	
		TC and TTa I/O	0.445 V _{DD} +0.398 ⁽¹⁾	-	-	v	
V	High level input	FT and FTf I/O	0.5 V _{DD} +0.2 ⁽¹⁾	-	-		
V _{IH}	voltage	BOOT0	0.2 V _{DD} +0.95 ⁽¹⁾	-	-		
		All I/Os except BOOT0	0.7 V _{DD} ⁽²⁾	-	-		
	Schmitt trigger hysteresis	TC and TTa I/O	-	200 (1)	-		
V _{hys}		FT and FTf I/O	-	100 (1)	-	mV	
		BOOT0	-	300 (1)	-		
	Input leakage current ⁽³⁾	TC, FT and FTf I/O TTa I/O in digital mode V _{SS} ≤V _{IN} ≤V _{DD}	-	-	±0.1		
l _{lkg}		TTa I/O in digital mode V _{DD} ≤V _{IN} ≤V _{DDA}	-	-	1	μA	
3		TTa I/O in analog mode V _{SS} ≤V _{IN} ≤V _{DDA}	-	-	±0.2		
		FT and FTf I/O ⁽⁴⁾ V _{DD} ≤V _{IN} ≤5 V	-	-	10		
R _{PU}	Weak pull-up equivalent resistor ⁽⁵⁾	$V_{IN} = V_{SS}$	25	40	55	kΩ	
R _{PD}	Weak pull-down equivalent resistor ⁽⁵⁾	$V_{IN} = V_{DD}$	25	40	55	kΩ	
C _{IO}	I/O pin capacitance	-	-	5	-	pF	

Table 54. I/O stati	ic characteristics
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1. Data based on design simulation.

2. Tested in production.

3. Leakage could be higher than the maximum value. if negative current is injected on adjacent pins. Refer to Table 53: I/O current injection susceptibility.

4. To sustain a voltage higher than V_{DD} +0.3 V, the internal pull-up/pull-down resistors must be disabled.

5. Pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This PMOS/NMOS contribution to the series resistance is minimum (~10% order).



All I/Os are CMOS and TTL compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters. The coverage of these requirements is shown in *Figure 18* and *Figure 19* for standard I/Os.



Figure 18. TC and TTa I/O input characteristics - CMOS port









Figure 20. Five volt tolerant (FT and FTf) I/O input characteristics - CMOS port







Output driving current

The GPIOs (general purpose input/outputs) can sink or source up to +/-8 mA, and sink or source up to +/- 20 mA (with a relaxed V_{OL}/V_{OH}).

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in *Section 6.2*:

- The sum of the currents sourced by all the I/Os on V_{DD}, plus the maximum Run consumption of the MCU sourced on V_{DD}, cannot exceed the absolute maximum rating ΣI_{VDD} (see *Table 22*).
- The sum of the currents sunk by all the I/Os on V_{SS} plus the maximum Run consumption of the MCU sunk on V_{SS} cannot exceed the absolute maximum rating ΣI_{VSS} (see *Table 22*).

Output voltage levels

Unless otherwise specified, the parameters given in *Table 55* are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 24*. All I/Os (FT, TTa and TC unless otherwise specified) are CMOS and TTL compliant.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{OL} ⁽¹⁾	Output low level voltage for an I/O pin	CMOS port ⁽²⁾	-	0.4	
V _{OH} ⁽³⁾	Output high level voltage for an I/O pin	I _{IO} = +8 mA 2.7 V < V _{DD} < 3.6 V	V _{DD} -0.4	-	
V _{OL} ⁽¹⁾	Output low level voltage for an I/O pin	TTL port ⁽²⁾	-	0.4	
V _{OH} ⁽³⁾	Output high level voltage for an I/O pin	I _{IO} = +8 mA 2.7 V < V _{DD} < 3.6 V	2.4	-	
V _{OL} ⁽¹⁾⁽⁴⁾	Output low level voltage for an I/O pin	I _{IO} = +20 mA	-	1.3	V
V _{OH} ⁽³⁾⁽⁴⁾	Output high level voltage for an I/O pin	2.7 V < V _{DD} < 3.6 V	V _{DD} -1.3	-	
V _{OL} ⁽¹⁾⁽⁴⁾	Output low level voltage for an I/O pin	I _{IO} = +6 mA	-	0.4	
V _{OH} ⁽³⁾⁽⁴⁾	Output high level voltage for an I/O pin	2 V < V _{DD} < 2.7 V	V _{DD} -0.4	-	
V _{OLFM+} ⁽¹⁾⁽⁴⁾	Output low level voltage for an FTf I/O pin in FM+ mode	I _{IO} = +20 mA 2.7 V < V _{DD} < 3.6 V	-	0.4	

Table 55.	Output voltage	characteristics
	o alpat follago	

1. The I_{IO} current sunk by the device must always respect the absolute maximum rating specified in *Table 22* and the sum of I_{IO} (I/O ports and control pins) must not exceed $\Sigma I_{IO(PIN)}$.

2. TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.

3. The I_{IO} current sourced by the device must always respect the absolute maximum rating specified in *Table 22* and the sum of I_{IO} (I/O ports and control pins) must not exceed $\Sigma I_{IO(PIN)}$.

4. Data based on design simulation.



Input/output AC characteristics

The definition and values of input/output AC characteristics are given in *Figure 22* and *Table 56*, respectively.

Unless otherwise specified, the parameters given are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 24*.

OSPEEDRy [1:0] value ⁽¹⁾	Symbol	Parameter	Conditions	Min	Мах	Unit	
	f _{max(IO)out}	Maximum frequency ⁽²⁾	C_{L} = 50 pF, V_{DD} = 2 V to 3.6 V	-	2 ⁽³⁾	MHz	
x0	t _{f(IO)out}	Output high to low level fall time	-C _L = 50 pF, V _{DD} = 2 V to 3.6 V	-	125 ⁽³⁾	ns	
	t _{r(IO)out}	Output low to high level rise time	-CL - 30 μr, ν _{DD} - 2 ν to 3.0 ν	-	125 ⁽³⁾	115	
	f _{max(IO)out}	Maximum frequency ⁽²⁾	C_{L} = 50 pF, V_{DD} = 2 V to 3.6 V	-	10 ⁽³⁾	MHz	
01	t _{f(IO)out}	Output high to low level fall time		-	25 ⁽³⁾	20	
	t _{r(IO)out}	Output low to high level rise time	-C _L = 50 pF, V _{DD} = 2 V to 3.6 V		25 ⁽³⁾	ns	
	f _{max(IO)out}		C _L = 30 pF, V _{DD} = 2.7 V to 3.6 V		50 ⁽³⁾	MHz	
		Maximum frequency ⁽²⁾	C_{L} = 50 pF, V_{DD} = 2.7 V to 3.6 V	-	30 ⁽³⁾	MHz	
			C_{L} = 50 pF, V_{DD} = 2 V to 2.7 V	-	20 ⁽³⁾	MHz	
			C_{L} = 30 pF, V_{DD} = 2.7 V to 3.6 V	-	5 ⁽³⁾		
11	t _{f(IO)out}	Output high to low level fall time	C_{L} = 50 pF, V_{DD} = 2.7 V to 3.6 V	-	8 ⁽³⁾		
			C_L = 50 pF, V_{DD} = 2 V to 2.7 V	-	12 ⁽³⁾		
			C_{L} = 30 pF, V_{DD} = 2.7 V to 3.6 V	-	5 ⁽³⁾	ns	
	t _{r(IO)out}	Output low to high level rise time	C_{L} = 50 pF, V_{DD} = 2.7 V to 3.6 V	-	8 ⁽³⁾		
			C_{L} = 50 pF, V_{DD} = 2 V to 2.7 V	-	12 ⁽³⁾		
	f _{max(IO)out}	Maximum frequency ⁽²⁾		-	2 ⁽⁴⁾	MHz	
FM+ configuration ⁽⁴⁾	t _{f(IO)out}	Output high to low level fall time	C _L = 50 pF, V _{DD} = 2 V to 3.6 V	-	12 ⁽⁴⁾	20	
	t _{r(IO)out}	Output low to high level rise time		-	34 ⁽⁴⁾	ns	
-	t _{EXTIpw}	Pulse width of external signals detected by the EXTI controller	-	10 ⁽³⁾	-	ns	

Table	56.	I/O	AC	characteristics ⁽¹⁾
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1. The I/O speed is configured using the OSPEEDRx[1:0] bits. Refer to the RM0365 reference manual for a description of GPIO Port configuration register.

2. The maximum frequency is defined in *Figure 22*.

3. Guaranteed by design, not tested in production.

4. The I/O speed configuration is bypassed in FM+ I/O mode. Refer to the STM32F302xx STM32F312xx reference manual RM0365 for a description of FM+ I/O mode configuration.





Figure 22. I/O AC characteristics definition

6.3.15 NRST pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor, R_{PU} (see *Table 54*).

Unless otherwise specified, the parameters given in *Table 57* are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 24*.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{IL(NRST)} ⁽¹⁾	NRST Input low level voltage	-	-	-	0.3V _{DD} + 0.07 ⁽¹⁾	v
V _{IH(NRST)} ⁽¹⁾	NRST Input high level voltage	-	0.445V _{DD} + 0.398 ⁽¹⁾	-	-	v
V _{hys(NRST)}	NRST Schmitt trigger voltage hysteresis	-	-	200	-	mV
R _{PU}	Weak pull-up equivalent resistor ⁽²⁾	$V_{IN} = V_{SS}$	25	40	55	kΩ
V _{F(NRST)} ⁽¹⁾	NRST Input filtered pulse	-	-	-	100 ⁽¹⁾	ns
V _{NF(NRST)} ⁽¹⁾	NRST Input not filtered pulse	-	500 ⁽¹⁾	-	-	ns

Table 57. NRST pin characteristics

1. Guaranteed by design, not tested in production.

2. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance must be minimum (~10% order).





Figure 23. Recommended NRST pin protection

1. The reset network protects the device against parasitic resets.

 The user must ensure that the level on the NRST pin can go below the V_{IL(NRST)} max level specified in Table 57. Otherwise the reset will not be taken into account by the device.

6.3.16 Timer characteristics

The parameters given in *Table 58* are guaranteed by design.

Refer to Section 6.3.14: I/O port characteristics for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

Symbol	Parameter	Conditions	Min	Мах	Unit	
		-	1	-	t _{TIMxCLK}	
t _{res(TIM)}	Timer resolution time	f _{TIMxCLK} = 72 MHz	13.9	-	ns	
163(1111)		f _{TIM1CLK} = 144 MHz	6.95	-	ns	
f	Timer external clock	-	0	f _{TIMxCLK} /2	MHz	
f _{EXT}	frequency on CH1 to CH4	f _{TIMxCLK} = 72 MHz	0	36	MHz	
Dee	Timer resolution	TIMx (except TIM2)	-	16	bit	
Res _{TIM}		TIM2	-	32		
		-	1	65536	t _{TIMxCLK}	
t _{COUNTER}	16-bit counter clock period	f _{TIMxCLK} = 72 MHz	0.0139	910	μs	
COUNTER		f _{TIM1CLK} = 144 MHz	0.0069	455	μs	
		-	-	65536 × 65536	t _{TIMxCLK}	
t _{MAX_COUNT}	Maximum possible count	f _{TIMxCLK} = 72 MHz	-	59.65	S	
	with 32-bit counter	f _{TIM1CLK} = 144 MHz	-	29.825	s	

Table 58. TIMx⁽¹⁾⁽²⁾ characteristics

1. TIMx is used as a general term to refer to the TIM1, TIM2, TIM3, TIM4, TIM15, TIM16 and TIM17 timers.

2. Guaranteed by design, not tested in production.



Prescaler divider	PR[2:0] bits	Min timeout (ms) RL[11:0]= 0x000	Max timeout (ms) RL[11:0]= 0xFFF
/4	0	0.1	409.6
/8	1	0.2	819.2
/16	2	0.4	1638.4
/32	3	0.8	3276.8
/64	4	1.6	6553.6
/128	5	3.2	13107.2
/256	7	6.4	26214.4

Table 59. IWDG min/max timeout period at 40 kHz (LSI) ⁽¹⁾

1. These timings are given for a 40 kHz clock but the microcontroller's internal RC frequency can vary from 30 to 60 kHz. Moreover, given an exact RC oscillator frequency, the exact timings still depend on the phasing of the APB interface clock versus the LSI clock so that there is always a full RC period of uncertainty.

Table 60. WWDG min-max timeout value @72 Mł	Iz (PCLK) ⁽¹⁾
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Prescaler	WDGTB	Min timeout value	Max timeout value
1	0	0.05687	3.6409
2	1	0.1137	7.2817
4	2	0.2275	14.564
8	3	0.4551	29.127

1. Guaranteed by design, not tested in production.



6.3.17 Communications interfaces

I²C interface characteristics

The I²C interface meets the timings requirements of the I²C-bus specification and user manual rev.03 for:

- Standard-mode (Sm) : with a bit rate up to 100 Kbits/s
- Fast-mode (Fm) : with a bit rate up to 400 Kbits/s
- Fast-mode Plus (Fm+) : with a bit rate up to 1Mbits/s

The I^2C timings requirements are guaranteed by design when the I^2C peripheral is properly configured (refer to Reference manual).

The SDA and SCL I/O requirements are met with the following restrictions: the SDA and SCL I/O pins are "true" open-drain. When configured as open-drain, the PMOS connected between the I/O pin and VDDIOx is disabled, but is still present. Only FTf I/O pins support Fm+ low level output current maximum requirement. Refer to *Section 6.3.14: I/O port characteristics*.

All I²C I/Os embed an analog filter. refer to the *Table 62: I2C analog filter characteristics*.

Symbol	Parameter	Standard mode		Fast mode		Fast Mode Plus		Unit
Symbol	Falameter	Min	Max	Min	Max	Min	Max	Unit
f _{SCL}	SCL clock frequency	0	100	0	400	0	1000	KHz
t _{LOW}	Low period of the SCL clock	4.7	-	1.3	-	0.5	-	μs
t _{HIGH}	High Period of the SCL clock	4		0.6		0.26	-	μs
t _r	Rise time of both SDA and SCL signals	-	1000	-	300	-	120	ns
t _f	Fall time of both SDA and SCL signals	-	300	-	300	-	120	ns
t _{HD;DAT}	Data hold time	0	-	0	-	0	-	μs
t _{VD;DAT}	Data valid time	-	3.45 ⁽²⁾	-	0.9 ⁽²⁾	-	0.45 ⁽²⁾	μs
t _{VD;ACK}	Data valid acknowledge time	-	3.45 ⁽²⁾	-	0.9 ⁽²⁾	-	0.45 ⁽²⁾	μs
t _{SU;DAT}	Data setup time	250	-	100	-	50	-	ns
t _{HD:STA}	Hold time (repeated) START condition	4.0	-	0.6	-	0.26	-	μs
t _{SU:STA}	Set-up time for a repeated START condition	4.7	-	0.6	-	0.26		μs
t _{SU:STO}	Set-up time for STOP condition	4.0	-	0.6	-	0.26	-	μs
t _{BUF}	Bus free time between a STOP and START condition	4.7	-	1.3	-	0.5	-	μs
C _b	Capacitive load for each bus line	-	400	-	400	-	550	pF
t _{SP}	Pulse width of spikes that are suppressed by the analog filter for Standard and Fast mode	0	50 ⁽³⁾	0	50 ⁽³⁾	-	-	ns

Table 61, I20	C timings specificat	tion (see I2C specifi	cation, rev.03, June 2007) ⁽¹⁾
	s unnings speemeau		<i>Sation, review, value 2001</i>



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- The I2C characteristics are the requirements from I2C bus specification rev03. They are guaranteed by design when I2Cx_TIMING register is correctly programmed (Refer to the RM0365 reference manual). These characteristics are not tested in production.
- 2. The maximum tHD;DAT could be 3.45 µs, 0.9 µs and 0.45 µs for standard mode, fast mode and fast mode plus, but must be less than the maximum of tVD;DAT or tVD;ACK by a transition time.
- 3. The minimum width of the spikes filtered by the analog filter is above $t_{SP}(max)$.

Symbol	Parameter	Min	Max	Unit		
t _{AF}	Pulse width of spikes that are suppressed by the analog filter	50	260	ns		

Table 62. I2C analog filter characteristics⁽¹⁾

1. Guaranteed by design, not tested in production.



Figure 24. I²C bus AC waveforms and measurement circuit

1. Rs: Series protection resistors, Rp: Pull-up resistors, VDD_I2C: I2C bus supply.



SPI/I²S characteristics

Unless otherwise specified, the parameters given in *Table 63* for SPI or in *Table 64* for I²S are derived from tests performed under ambient temperature, f_{PCLKx} frequency and V_{DD} supply voltage conditions summarized in *Table 24*.

Refer to Section 6.3.14: I/O port characteristics for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI and WS, CK, SD for I²S).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	Master mode, SPI1 2.7 <v<sub>DD<3.6</v<sub>				24	
f _{scк}		Slave mode, SPI1 2.7 <v<sub>DD<3.6</v<sub>			24	
1/t _{c(SCK)}	SPI clock frequency	Master mode, SPI1/2/3 2 <v<sub>DD<3.6</v<sub>		-	18	MHz
		Slave mode, SPI1/2/3 2 <v<sub>DD<3.6</v<sub>			18	
DuCy(scк)	Duty cycle of SPI clock frequency	Slave mode	30	50	70	%
t _{su(NSS)}	NSS setup time	Slave mode, SPI presc = 2	4*Tpclk	-	-	
t _{h(NSS)}	NSS hold time	Slave mode, SPI presc = 2	2*Tpclk	-	-	
t _{w(SCKH)} t _{w(SCKL)}	SCK high and low time	Master mode	Tpclk-2	Tpclk	Tpclk+2	
t _{su(MI)}	Dete innut estur time	Master mode	5.5	-	-	
t _{su(SI)}	Data input setup time	Slave mode	6.5	-	-	
t _{h(MI)}	Data innut hald time	Master mode	5	-	-	
t _{h(SI)}	Data input hold time	Slave mode	5	-	-	ns
t _{a(SO)}	Data output access time	Slave mode	0	-	4*Tpclk	115
t _{dis(SO)}	Data output disable time	Slave mode	0	-	24	
	Slave mode	Slave mode	-	12	27	
t _{v(SO)}	Data output valid time	Slave mode, SPI1 2.7 <v<sub>DD<3.6V</v<sub>	-	12	18	
t _{v(MO)}		Master mode	-	1.5	3	
t _{h(SO)}	Data output hold time	Slave mode	11	-	-	
t _{h(MO)}		Master mode	0	-	-	

Table	63.	SPI	characte	eristics ⁽¹⁾
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1. Data based on characterization results, not tested in production.





Figure 25. SPI timing diagram - slave mode and CPHA = 0





1. Measurement points are done at $0.5V_{DD}$ and with external C_L = 30 pF.





Figure 27. SPI timing diagram - master mode⁽¹⁾

1. Measurement points are done at $0.5V_{DD}$ and with external C_L = 30 pF.



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Symbol	Parameter	Conditions	Min	Max	Unit
f _{CK}	I ² S clock frequency	Master data: 16 bits, audio freq=48 kHz	1.496	1.503	MHz
1/t _{c(CK)}		Slave	0	12.288	
t _{r(CK)} t _{f(CK)}	I ² S clock rise and fall time	Capacitive load C _L = 30 pF	-	8	
t _{w(CKH)}	I ² S clock high time	Master f _{PCLK} = 36 MHz,	331	-	
t _{w(CKL)}	I ² S clock low time	audio frequency = 48 kHz	332	-	
t _{v(WS)}	WS valid time	Master mode	4	-	ns
t _{h(WS)}	WS hold time	Master mode	4	-	
t _{su(WS)}	WS setup time	Slave mode	4	-	
t _{h(WS)}	WS hold time	Slave mode	0	-	
Duty Cycle	I ² S slave input clock duty cycle	Slave mode	30	70	%
$t_{su(SD_MR)}$	Data input setup time	Master receiver	9	-	
$t_{su(SD_SR)}$	Data input setup time	Slave receiver	2	-	
t _{h(SD_MR)}	 Data input hold time 	Master receiver	0	-	
t _{h(SD_SR)}		Slave receiver	0	-	
$t_{v(SD_ST)}$	Data output valid time	Slave transmitter (after enable edge)	-	29	ns
$t_{h(SD_ST)}$	Data output hold time	Slave transmitter (after enable edge)	12	-	
$t_{v(SD_MT)}$	Data output valid time	Master transmitter (after enable edge)	-	3	
t _{h(SD_MT)}	Data output hold time	Master transmitter (after enable edge)	2	-	

Table 64. I²S characteristics⁽¹⁾

1. Data based on characterization results, not tested in production.





Figure 28. I²S slave timing diagram (Philips protocol)⁽¹⁾

- 1. Measurement points are done at 0.5V $_{\text{DD}}$ and with external C $_{\text{L}}$ =30 pF.
- 2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.



Figure 29. I²S master timing diagram (Philips protocol)⁽¹⁾

- 1. Measurement points are done at $0.5V_{DD}$ and with external C_L=30 pF.
- 2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.



USB characteristics

Symbol	Parameter	Max	Unit
t _{STARTUP} ⁽¹⁾	USB transceiver startup time	1	μs

1. Guaranteed by design, not tested in production.

Symbol	Parameter	Conditions	Min. ⁽¹⁾	Max. ⁽¹⁾	Unit					
Input levels										
V _{DD}	USB operating voltage ⁽²⁾	3.0 ⁽³⁾	3.6	V						
V _{DI} ⁽⁴⁾	Differential input sensitivity	I(USB_DP, USB_DM)	0.2	-						
V _{CM} ⁽⁴⁾	Differential common mode range	Includes V _{DI} range	0.8	2.5	V					
$V_{SE}^{(4)}$	Single ended receiver threshold	-	1.3	2.0						
Output levels										
V _{OL}	Static output level low	$\rm R_L$ of 1.5 k\Omega to 3.6 $\rm V^{(5)}$	-	0.3	v					
V _{OH}	Static output level high	${\sf R}_{\sf L}$ of 15 k Ω to ${\sf V}_{\sf SS}{}^{(5)}$	2.8	3.6						

1. All the voltages are measured from the local ground potential.

2. To be compliant with the USB 2.0 full-speed electrical specification, the USB_DP (D+) pin should be pulled up with a 1.5 k Ω resistor to a 3.0-to-3.6 V voltage range.

3. The STM32F302xB/STM32F302xC USB functionality is ensured down to 2.7 V but not the full USB electrical characteristics which are degraded in the 2.7-to-3.0 V V_{DD} voltage range.

- 4. Guaranteed by design, not tested in production.
- 5. R_L is the load connected on the USB drivers.

Figure 30. USB timings: definition of data signal rise and fall time





0												
Symbol	Parameter	Conditions	Min	Тур	Max	Unit						
Driver characteristics												
t _r	Rise time ⁽²⁾	C _L = 50 pF	4	-	20	ns						
t _f	Fall time ⁽²⁾	C _L = 50 pF	4	-	20	ns						
t _{rfm}	Rise/ fall time matching	t _r /t _f	90	-	110	%						
V _{CRS}	Output signal crossover voltage	-	1.3	-	2.0	V						
Output driver Impedance ⁽³⁾	Z _{DRV}	driving high and low	28	40	44	Ω						

Table 67. USB: Full-speed electrical characteristics⁽¹⁾

1. Guaranteed by design, not tested in production.

Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).

3. No external termination series resistors are required on USB_DP (D+) and USB_DM (D-), the matching impedance is already included in the embedded driver.

CAN (controller area network) interface

Refer to Section 6.3.14: I/O port characteristics for more details on the input/output alternate function characteristics (CAN_TX and CAN_RX).



6.3.18 ADC characteristics

Unless otherwise specified, the parameters given in *Table 68* to *Table 70* are guaranteed by design, with conditions summarized in *Table 24*.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DDA}	Analog supply voltage for ADC	-	2	-	3.6	V
		Single-ended mode, 5 MSPS	-	907	1033.0	
		Single-ended mode, 1 MSPS	-	194	285.5	
1	ADC current consumption on	Single-ended mode, 200 KSPS	-	51.5	70	
I _{DDA}	VDDA pin (see <i>Figure 31</i>)	Differential mode, 5 MSPS	-	887.5	1009	μA
		Differential mode, 1 MSPS	-	212	285	
		Differential mode, 200 KSPS	-	51	69.5	
V _{REF+}	Positive reference voltage	-	2	-	V _{DDA}	V
	ADC current consumption on VREF+ pin (see <i>Figure 32</i>)	Single-ended mode, 5 MSPS	-	104	139	
		Single-ended mode, 1 MSPS	-	20.4	37	
		Single-ended mode, 200 KSPS	-	3.3	11.3	
I _{REF}		Differential mode, 5 MSPS	-	174	235	μA
		Differential mode, 1 MSPS	-	34.6	52.6	
		Differential mode, 200 KSPS	-	6	13.6	
f _{ADC}	ADC clock frequency	-	0.14	-	72	MHz
		Resolution = 12 bits, Fast Channel	0.01	-	5.14	
f _S ⁽¹⁾	Sampling rate	Resolution = 10 bits, Fast Channel	0.012	-	6	MSPS
'S` ′		Resolution = 8 bits, Fast Channel	0.014	-	7.2	
		Resolution = 6 bits, Fast Channel	0.0175	-	9	
f _{TRIG} ⁽¹⁾	External trigger frequency	f _{ADC} = 72 MHz Resolution = 12 bits	-	-	5.14	MHz
-		Resolution = 12 bits	-	-	14	1/f _{ADC}

Table	68.	ADC	characteristics
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		b. ADC characteristics	, <i>,</i>			
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{AIN}	Conversion voltage range ⁽²⁾	-	0	-	V _{REF+}	V
R _{AIN} ⁽¹⁾	External input impedance	-	-	-	100	kΩ
C _{ADC} ⁽¹⁾	Internal sample and hold capacitor	-	-	5	-	pF
t _{STAB} ⁽¹⁾	Power-up time	-	0	0	1	μs
+ (1)	Calibration time	f _{ADC} = 72 MHz		1.56		μs
t _{CAL} ⁽¹⁾		-		112		1/f _{ADC}
	Trigger conversion latency	CKMODE = 00	1.5	2	2.5	1/f _{ADC}
+ (1)	Regular and injected channels without conversion abort	CKMODE = 01	-	-	2	1/f _{ADC}
t _{latr} (1)		CKMODE = 10	-	-	2.25	1/f _{ADC}
		CKMODE = 11	-	-	2.125	1/f _{ADC}
		CKMODE = 00	2.5	3	3.5	1/f _{ADC}
▲ (1)	Trigger conversion latency Injected channels aborting a regular conversion	CKMODE = 01	-	-	3	1/f _{ADC}
t _{latrinj} (1)		CKMODE = 10	-	-	3.25	1/f _{ADC}
		CKMODE = 11	-	-	100 - 1 2.5 2 2.25 2.25 2.125 3.5 3.25 3.125 8.35 601.5 10 8.52 + 12.5 for	1/f _{ADC}
ts ⁽¹⁾	Sampling time	f _{ADC} = 72 MHz	0.021	-	8.35	μs
LS V		-	1.5	-	601.5	1/f _{ADC}
T _{ADCVREG} _STUP ⁽¹⁾	ADC Voltage Regulator Start-up time	-	-	-	10	μs
	Total conversion time	f _{ADC} = 72 MHz Resolution = 12 bits	0.19	-	8.52	μs
t _{CONV} ⁽¹⁾	(including sampling time)	Resolution = 12 bits	14 to 614 (t _S for sampling + 12.5 for successive approximation)			1/f _{ADC}

Table 68. ADC characteristics (continued)

1. Data guaranteed by design, not tested in Production.

2. V_{REF+} can be internally connected to V_{DDA} and V_{REF-} can be internally connected to V_{SSA} , depending on the package. Refer to Section 4: Pinouts and pin description for further details.





Figure 31. ADC typical current consumption on VDDA pin







	Sampling	Sampling		R _{AIN} max (kΩ)				
Resolution	cycle @ 72 MHz	time [ns] @ 72 MHz	Fast channels ⁽²⁾	Slow channels	Other channels ⁽³⁾			
	1.5	20.83	0.018	NA	NA			
	2.5	34.72	0.150	NA	0.022			
12 bits	4.5	62.50	0.470	0.220	0.180			
	7.5	104.17	0.820	0.560	0.470			
	19.5	270.83	2.70	1.80	1.50			
	61.5	854.17	8.20	6.80	4.70			
	181.5	2520.83	22.0	18.0	15.0			
	601.5	8354.17	82.0	68.0	47.0			
	1.5	20.83	0.082	NA	NA			
	2.5	34.72	0.270	0.082	0.100			
	4.5	62.50	0.560	0.390	0.330			
	7.5	104.17	1.20	0.82	0.68			
10 bits	19.5	270.83	3.30	2.70	2.20			
	61.5	854.17	10.0	8.2	6.8			
	181.5	2520.83	33.0	27.0	22.0			
	601.5	8354.17	100.0	82.0	68.0			
	1.5	20.83	0.150	NA	0.039			
	2.5	34.72	0.390	0.180	0.180			
	4.5	62.50	0.820	0.560	0.470			
0.1.11	7.5	104.17	1.50	1.20	1.00			
8 bits	19.5	270.83	3.90	3.30	2.70			
	61.5	854.17	12.00	12.00	8.20			
	181.5	2520.83	39.00	33.00	27.00			
	601.5	8354.17	100.00	100.00	82.00			
	1.5	20.83	0.270	0.100	0.150			
	2.5	34.72	0.560	0.390	0.330			
	4.5	62.50	1.200	0.820	0.820			
	7.5	104.17	2.20	1.80	1.50			
6 bits	19.5	270.83	5.60	4.70	3.90			
	61.5	854.17	18.0	15.0	12.0			
	181.5	2520.83	56.0	47.0	39.0			
	601.5	8354.17	100.00	100.0	100.0			

Table 69. Maximum ADC $R_{AIN}^{(1)}$

1. Data based on characterization results, not tested in production.



STM32F302xB STM32F302xC

- 2. All fast channels, expect channels on PA2, PA6.
- 3. Channels available on PA2, PA6.

Symbol	Parameter	(Conditions		Min (3)	Тур	Max (3)	Unit
			Oire also sure dis el	Fast channel 5.1 Ms	-	±3.5	±4.5	
гт	Total		Single ended	Slow channel 4.8 Ms	-	±4	±4.5	
ET	unadjusted error		Differential	Fast channel 5.1 Ms	-	±3	# 3	
			Differential	Slow channel 4.8 Ms	-	±3	±3	
			Single ended	Fast channel 5.1 Ms	-	±1	±1.5	
EO	Offset error		Single ended	Slow channel 4.8 Ms	-	±1	±2.5	
LO	Olisetenoi	Differential	Fast channel 5.1 Ms	-	±1	±1.5		
			Dillerential	Slow channel 4.8 Ms	-	±1	±1.5	
			Single ended	Fast channel 5.1 Ms	-	±3	±4	±4
FC		Single ended	Slow channel 4.8 Ms	-	±3.5	±4		
EG Gain error	Differential			Fast channel 5.1 Ms	-	±1.5	±2.5	LSB
			Slow channel 4.8 Ms	-	±2	±2.5		
		ADC clock freq. ≤72 MHz	Fast channel 5.1 Ms	-	±1	±1.5		
-	Differential linearity	Sampling freq. ≤ 5 Msps	Single ended	Slow channel 4.8 Ms	-	±1	±1.5	
ED	error		Differential	Fast channel 5.1 Ms	-	±1	±1	
		100-pin package	Dillerential	Slow channel 4.8 Ms	-	±1	±1	
			Single ended	Fast channel 5.1 Ms	-	±1.5	<u>+2</u>	
EL	Integral		Single ended	Slow channel 4.8 Ms	-	±1.5	±3	
EL	linearity error		Differential	Fast channel 5.1 Ms	-	±1	±1.5	
			Dillerential	Slow channel 4.8 Ms	-	±1	±1.5	
			Single ended	Fast channel 5.1 Ms	10.7	10.8	-	
ENOB ⁽⁴⁾	Effective		Single ended	Slow channel 4.8 Ms	10.7	10.8	-	- bits
ENOR	bits	umber of its	Differential	Fast channel 5.1 Ms	11.2	11.3	-	
			Differential	Slow channel 4.8 Ms	11.1	11.3	-	
	Signal to		Single ended	Fast channel 5.1 Ms	66	67	-	
SINAD ⁽⁴⁾	Signal-to- noise and			Slow channel 4.8 Ms	66	67	-	dB
	distortion ratio		Differential	Fast channel 5.1 Ms	69	70	-	UD
	1410		Differential	Slow channel 4.8 Ms	69	70	-	

Table 70. ADC accuracy - limited test conditions, 100-pin packages ⁽¹⁾⁽²⁾
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Symbol	Parameter	C	Min (3)	Тур	Max (3)	Unit						
			Single ended	Fast channel 5.1 Ms	66	67	-					
	Signal-to-		Single ended	Slow channel 4.8 Ms	66	67	-					
	noise ratio	Sampling freq \leq 5 Msps	Differential	Fast channel 5.1 Ms	69	70	-					
				Slow channel 4.8 Ms	69	70	-	dB				
	Total	harmonic 100-pin package	Single ended	Fast channel 5.1 Ms	-	-76	-76	uВ				
THD ⁽⁴⁾				Slow channel 4.8 Ms	-	-76	-76					
THD	distortion		Differential	Fast channel 5.1 Ms	-	-80	-80					
			Differential	Slow channel 4.8 Ms	-	-80	-80					

Table 70. ADC accuracy - limited test conditions, 100-pin packages ⁽¹⁾⁽²⁾ (continued)

1. ADC DC accuracy values are measured after internal calibration.

 ADC accuracy vs. negative Injection Current: Injecting negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative current. Any positive injection current within the limits specified for I_{INJ(PIN)} and ΣI_{INJ(PIN)} in Section 6.3.14 does not affect the ADC accuracy.

3. Data based on characterization results, not tested in production.

4. Value measured with a -0.5 dB full scale 50 kHz sine wave input signal.



Symbol	Parameter	с	onditions		Min ⁽⁴⁾	Max ⁽⁴⁾	Unit	
			Single	Fast channel 5.1 Ms	-	±6.5		
ст	Total		Ended	Slow channel 4.8 Ms	-	±6.5		
	ET unadjusted error		Differential	Fast channel 5.1 Ms	-	±4		
			Dillerential	Slow channel 4.8 Ms	-	±4		
			Single	Fast channel 5.1 Ms	-	±3		
EO	Offset error		Ended	Slow channel 4.8 Ms	-	±3		
LO	Olisetenoi		Differential	Fast channel 5.1 Ms	-	<u>+2</u>		
			Differential	Slow channel 4.8 Ms	-	<u>+2</u>		
			Single	Fast channel 5.1 Ms	-	±6		
EG	Gain error	ADC clock freq. ≤ 72 MHz,	Ended	Slow channel 4.8 Ms	-	±6	LSB	
LG	Gainentoi			Differential	Fast channel 5.1 Ms	-	±3	LOD
		Sampling freq. ≤ 5 Msps	Dillerential	Slow channel 4.8 Ms	-	±3		
		$2 V \le V_{DDA}$, $V_{REF+} \le 3.6 V$	Single	Fast channel 5.1 Ms	-	±1.5		
ED	Differential linearity	100-pin package		Ended	Slow channel 4.8 Ms	-	±1.5	
ED	error		Differential	Fast channel 5.1 Ms	-	±1.5		
			Dillerential	Slow channel 4.8 Ms	-	±1.5		
			Single	Fast channel 5.1 Ms	-	<u>+2</u>		
EL	Integral linearity		Ended	Slow channel 4.8 Ms	-	±3		
	error		Differential	Fast channel 5.1 Ms	-	<u>+2</u>		
			Dillerential	Slow channel 4.8 Ms	-	<u>+2</u>		
			Single	Single	Fast channel 5.1 Ms	10.4	-	
ENOB	Effective number of		Ended	Slow channel 4.8 Ms	10.2	-	bits	
(5)	bits		Differential	Fast channel 5.1 Ms	10.8	-	DILS	
				Slow channel 4.8 Ms	10.8	-		

Table 71. ADC accuracy, 100-pin packages⁽¹⁾⁽²⁾⁽³⁾



Symbol	Parameter	C	onditions		Min ⁽⁴⁾	Max ⁽⁴⁾	Unit
	Circulto		Single	Fast channel 5.1 Ms	64	-	
SINAD noise and (5) distortion	Signal-to- noise and		Ended	Slow channel 4.8 Ms	63	-	
		Differential	Fast channel 5.1 Ms	67	-		
	ratio Dif	Differential	Slow channel 4.8 Ms	67	-		
	NR ⁽⁵⁾ Signal-to- noise ratio	Total 2 V \leq V _{DDA} , V _{REF+} \leq 3.6 V 100-pin package	Single	Fast channel 5.1 Ms	64	-	
SNID(5)			Ended	Slow channel 4.8 Ms	64	-	dB
SINK' /			Differential	Fast channel 5.1 Ms	67	-	uБ
				Slow channel 4.8 Ms	67	-	
			Single	Fast channel 5.1 Ms	-	-74	
THD ⁽⁵⁾	Total harmonic		Ended	Slow channel 4.8 Ms	-	-74	
י ישרוי	distortion		Differential	Fast channel 5.1 Ms	-	-78	
			Differential	Slow channel 4.8 Ms	-	-76	

Table 71. ADC accuracy, 100-pin packages⁽¹⁾⁽²⁾⁽³⁾ (continued)

1. ADC DC accuracy values are measured after internal calibration.

 ADC accuracy vs. negative Injection Current: Injecting negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative current. Any positive injection current within the limits specified for I_{INJ(PIN)} and ΣI_{INJ(PIN)} in Section 6.3.14 does not affect the ADC accuracy.

3. Better performance may be achieved in restricted V_{DDA} , frequency and temperature ranges.

4. Data based on characterization results, not tested in production.

5. Value measured with a -0.5 dB full scale 50 kHz sine wave input signal.


Symbol	Parameter	C	Conditions		Min (3)	Тур	Max (3)	Unit
			Cingle ended	Fast channel 5.1 Ms	-	±4	±4.5	
CT.	Total		Single ended	Slow channel 4.8 Ms	-	±5.5	±6	
ET	unadjusted error		Differential	Fast channel 5.1 Ms	-	±3.5	±4	
			Differential	Slow channel 4.8 Ms	-	±3.5	±4	
				Fast channel 5.1 Ms	-	±2	±2	
50	Offeet error		Single ended	Slow channel 4.8 Ms	-	±1.5	±2	
EO	Offset error		Differential	Fast channel 5.1 Ms	-	±1.5	±2	
			Differential	Slow channel 4.8 Ms	-	±1.5	±2	
				Fast channel 5.1 Ms	-	±3	±4	
50	0		Single ended	Slow channel 4.8 Ms	-	±5	±5.5	
EG	Gain error		Differential	Fast channel 5.1 Ms	-	±3	±3	LSB
			Differential	Slow channel 4.8 Ms	-	±3	±3.5	
Differential	ADC clock freq. \leq 72 MHz	0	Fast channel 5.1 Ms	-	±1	±1		
	Sampling freq. \leq 5 Msps	Single ended	Slow channel 4.8 Ms	-	±1	±1		
ED	linearity error	V _{DDA} = 3.3 V 25°C	Differential	Fast channel 5.1 Ms	-	±1	±1	
		64-pin package	Differential	Slow channel 4.8 Ms	-	±1	±1	
				Fast channel 5.1 Ms	-	±1.5	±2	
-	Integral		Single ended	Slow channel 4.8 Ms	-	±2	±3	
EL	linearity error		Differential	Fast channel 5.1 Ms	-	±1.5	±1.5	
			Differential	Slow channel 4.8 Ms	-	±1.5	±2	
			Cingle and d	Fast channel 5.1 Ms	10.8	10.8	-	
ENOB	Effective		Single ended	Slow channel 4.8 Ms	10.8	10.8	-	L. 14
(4)	number of bits		Differential	Fast channel 5.1 Ms	11.2	11.3	-	bit
		Differential	Slow channel 4.8 Ms	11.2	11.3	-		
				Fast channel 5.1 Ms	66	67	-	
SINAD	Signal-to- noise and		Single ended	Slow channel 4.8 Ms	66	67	-	d٦
(4)	distortion		Differential	Fast channel 5.1 Ms	69	70	-	dB
	ratio		Differential	Slow channel 4.8 Ms	69	70	-	

Table 72. ADC accuracy - limited test conditions, 64-pin packages⁽¹⁾⁽²⁾



Symbol	Parameter	C	Min (3)	Тур	Max (3)	Unit		
SNR ⁽⁴⁾ Signal-to- noise ratio			Single ended	Fast channel 5.1 Ms	66	67	-	
			Slow channel 4.8 Ms	66	67	-		
	ADC clock freq. \leq 72 MHz	Differential	Fast channel 5.1 Ms	69	70	-		
		Sampling freq \leq 5 Msps	Dillerential	Slow channel 4.8 Ms	69	70	-	dB
		V _{DDA} = 3.3 V 25°C	Single ended	Fast channel 5.1 Ms	-	-80	-80	uВ
THD ⁽⁴⁾ Total harmonic distortion		64-pin package	Single ended	Slow channel 4.8 Ms	-	-78	-77	
			Differential	Fast channel 5.1 Ms	-	-83	-82	
		Differential	Slow channel 4.8 Ms	-	-81	-80		

Table 72. ADC accuracy - limited test conditions, 64-pin packages⁽¹⁾⁽²⁾ (continued)

1. ADC DC accuracy values are measured after internal calibration.

 ADC accuracy vs. negative Injection Current: Injecting negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative current. Any positive injection current within the limits specified for I_{INJ(PIN)} and ΣI_{INJ(PIN)} in Section 6.3.14 does not affect the ADC accuracy.

3. Data based on characterization results, not tested in production.

4. Value measured with a -0.5 dB full scale 50 kHz sine wave input signal.



Symbol	Parameter	C	Conditions		Min ⁽⁴⁾	Max (4)	Unit
			Single ended	Fast channel 5.1 Ms	-	±6.5	
ET	Total		Single ended	Slow channel 4.8 Ms	-	±6.5	
	unadjusted error		Differential	Fast channel 5.1 Ms	-	±4	
			Differential	Slow channel 4.8 Ms	-	±4.5	
			Single and d	Fast channel 5.1 Ms	-	±3	
ГО	Offect error		Single ended	Slow channel 4.8 Ms	-	±3	
EO	EO Offset error		Differential	Fast channel 5.1 Ms	_	±2.5	
			Differential	Slow channel 4.8 Ms	-	±2.5	
			Cingle and d	Fast channel 5.1 Ms	-	±6	
50			Single ended	Slow channel 4.8 Ms	_	±6	
EG Gain error		Differential	Fast channel 5.1 Ms	_	±3.5	LSB	
			Differential	Slow channel 4.8 Ms	-	±4	
	Differential ADC clock freq. ≤ 72 MHz Sampling freq. ≤ 5 Msps	Oin als suds d	Fast channel 5.1 Ms	-	±1.5		
50		Sampling freq. \leq 5 Msps	Single ended	Slow channel 4.8 Ms	-	±1.5	
ED	linearity error	$2.0 V \le V_{DDA} \le 3.6 V$	Differential	Fast channel 5.1 Ms	_	±1.5	
		64-pin package Differ	Differential	Slow channel 4.8 Ms	-	±1.5	
			Cinalo ondod	Fast channel 5.1 Ms	-	±3	
-	Integral		Single ended	Slow channel 4.8 Ms	_	±3.5	
EL	linearity error		Differential	Fast channel 5.1 Ms	-	±2	
			Differential	Slow channel 4.8 Ms	-	±2.5	
			Cinalo ondod	Fast channel 5.1 Ms	10.4	-	
ENOB	Effective		Single ended	Slow channel 4.8 Ms	10.4	-	h:to
(5)	number of bits		Differential	Fast channel 5.1 Ms	10.8	-	bits
			Differential	Slow channel 4.8 Ms	10.8	-	
	Signal to		Single and d	Fast channel 5.1 Ms	64	-	
SINAD	Signal-to- noise and		Single ended	Slow channel 4.8 Ms	63	-	dB
(5)	distortion ratio		Differential	Fast channel 5.1 Ms	67	-	uв
	Tallo		Dincretitual	Slow channel 4.8 Ms	67	-	

Table 73. ADC accuracy, 64-pin packages⁽¹⁾⁽²⁾⁽³⁾



Symbol	Parameter	C	Min ⁽⁴⁾	Max (4)	Unit		
SNR ⁽⁵⁾ Signal-to- noise ratio			Single ended	Fast channel 5.1 Ms	64	-	
		Single ended	Slow channel 4.8 Ms	64	-		
	ADC clock freq. \leq 72 MHz,	Differential	Fast channel 5.1 Ms	67	-		
		Sampling freq \leq 5 Msps,	Dillerential	Slow channel 4.8 Ms	67	-	٩D
		$2 \text{ V} \leq \text{V}_{\text{DDA}} \leq 3.6 \text{ V}$	Cincle ended	Fast channel 5.1 Ms	-	-75	dB
THD ⁽⁵⁾ Total harmonic distortion		64-pin package	Single ended	Slow channel 4.8 Ms	-	-75	
			Differential	Fast channel 5.1 Ms	-	-79	
			Differential	Slow channel 4.8 Ms	-	-78	

Table 73. ADC accuracy, 64-pin packages⁽¹⁾⁽²⁾⁽³⁾ (continued)

1. ADC DC accuracy values are measured after internal calibration.

 ADC accuracy vs. negative Injection Current: Injecting negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative current. Any positive injection current within the limits specified for I_{INJ(PIN)} and ΣI_{INJ(PIN)} in Section 6.3.14 does not affect the ADC accuracy.

- 3. Better performance may be achieved in restricted V_{DDA}, frequency and temperature ranges.
- 4. Data based on characterization results, not tested in production.
- 5. Value measured with a -0.5 dB full scale 50 kHz sine wave input signal.

Symbol	Parameter	Test conditions		Тур	Max ⁽³⁾	Unit
ET	Total upadjusted error		Fast channel	±2.5	±5	
	Total unadjusted error		Slow channel	±3.5	±5	
FO	Sa Sa		Fast channel	±1	±2.5	
LO		ADC Freq ≤ 72 MHz	Slow channel	±1.5	±2.5	
EG		Sampling Freq ≤ 1MSPS	Fast channel	±2	±3	LSB
LG	Gainento	$2.4 \text{ V} \le \text{V}_{\text{DDA}} = \text{V}_{\text{REF+}} \le 3.6 \text{ V}$	Slow channel	±3	±4	LOD
ED	Differential linearity error	Single-ended mode	Fast channel	±0.7	±2	
	ED Differential inleanty error		Slow channel	±0.7	±2	
	EL Integral linearity error		Fast channel	±1	±3	
			Slow channel	±1.2	±3	

1. ADC DC accuracy values are measured after internal calibration.

 ADC accuracy vs. negative Injection Current: Injecting negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative current. Any positive injection current within the limits specified for IINJ(PIN) and ∑IINJ(PIN) in Section 6.3.14: I/O port characteristics does not affect the ADC accuracy.

3. Data based on characterization results, not tested in production.





Figure 33. ADC accuracy characteristics





1. Refer to Table 68 for the values of RAIN.

 $C_{parasitic}$ represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (roughly 7 pF). A high $C_{parasitic}$ value will downgrade conversion accuracy. To remedy this, f_{ADC} should be reduced. 2.

General PCB design guidelines

Power supply decoupling should be performed as shown in Figure 10. The 10 nF capacitor should be ceramic (good quality) and it should be placed as close as possible to the chip.



6.3.19 DAC electrical specifications

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{DDA}	Analog supply voltage	DAC output buffer ON	2.4	-	3.6	V
$R_{LOAD}^{(1)}$	Resistive load	DAC output buffer ON	5	-	-	kΩ
$R_0^{(1)}$	Output impedance	DAC output buffer ON	-	-	15	kΩ
C _{LOAD} ⁽¹⁾	Capacitive load	DAC output buffer ON	-	-	50	pF
V _{DAC_OUT} ⁽¹⁾	Voltage on DAC_OUT output	Corresponds to 12-bit input code (0x0E0) to (0xF1C) at V_{DDA} = 3.6 V and (0x155) and (0xEAB) at V_{DDA} = 2.4 V DAC output buffer ON.	0.2	-	V _{DDA} – 0.2	V
		DAC output buffer OFF	-	0.5	V _{DDA} - 1LSB	mV
I _{DDA} ⁽³⁾	DAC DC current consumption in quiescent	With no load, middle code (0x800) on the input.	-	-	380	μA
'DDA` ´	mode (Standby mode) ⁽²⁾	With no load, worst code (0xF1C) on the input.	-	-	480	μA
DN H (3)	Differential non linearity	Given for a 10-bit input code	-	-	±0.5	LSB
DNL ⁽³⁾	Difference between two consecutive code-1LSB)	Given for a 12-bit input code	-	-	±2	LSB
	Integral non linearity	Given for a 10-bit input code	-	-	±1	LSB
INL ⁽³⁾	(difference between measured value at Code i and the value at Code i on a line drawn between Code 0 and last Code 4095)	Given for a 12-bit input code	-	-	±4	LSB
		-	-	-	±10	mV
Offset ⁽³⁾	Offset error (difference between measured value at Code (0x800) and the ideal	Given for a 10-bit input code at V _{DDA} = 3.6 V	-	-	±3	LSB
	value = V _{DDA} /2)	Given for a 12-bit input code at V _{DDA} = 3.6 V	-	-	±12	LSB
Gain error ⁽³⁾	Gain error	Given for a 12-bit input code	-	-	±0.5	%
t _{SETTLING} ⁽³⁾	Settling time (full scale: for a 12-bit input code transition between the lowest and the highest input codes when DAC_OUT reaches final value ±1LSB	C _{LOAD} ≰50 pF, R _{LOAD} ≥ 5 kΩ	-	3	4	μs
Update rate ⁽³⁾	Max frequency for a correct DAC_OUT change when small variation in the input code (from code i to i+1LSB)	C _{LOAD} ≰50 pF, R _{LOAD} ≥ 5 kΩ	-	-	1	MS/s

Table 75. DAC characteristics



			,			
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
t _{WAKEUP} ⁽³⁾	DAC Control register)	C _{LOAD} ⊴50 pF, R _{LOAD} ≥ 5 kΩ	-	6.5	10	μs
PSRR+ ⁽¹⁾	Power supply rejection ratio (to V _{DDA}) (static DC measurement	C _{LOAD} = 50 pF, No R _{LOAD} ≥ 5 kΩ,	-	-67	-40	dB

 Table 75. DAC characteristics (continued)

1. Guaranteed by design, not tested in production.

2. Quiescent mode refers to the state of the DAC a keeping steady value on the output, so no dynamic consumption is involved.

3. Data based on characterization results, not tested in production.



Figure 35. 12-bit buffered /non-buffered DAC

 The DAC integrates an output buffer that can be used to reduce the output impedance and to drive external loads directly without the use of an external operational amplifier. The buffer can be bypassed by configuring the BOFFx bit in the DAC_CR register.



6.3.20 Comparator characteristics

Symbol	Parameter	Condit	ions	Min	Тур	Мах	Unit
V _{DDA}	Analog supply voltage	-		2	-	3.6	
V _{IN}	Comparator input voltage range	-		0	-	V _{DDA}	V
V _{BG}	Scaler input voltage	-		-	1.2	-	
V _{SC}	Scaler offset voltage	-		-	±5	±10	mV
t _{s_sc}	V _{REFINT} scaler startup time from power down	First V _{REFINT} scaler activation after device power on		-	-	1 ⁽²⁾	s
		Next activ	vations	-	-	0.2	ms
t _{START}	Comparator startup time	Startup time to reach propagation delay specification		-	-	60	μs
		Ultra-low-power mode	v-power mode		2	4.5	
	Propagation delay for	Low-power mode Medium power mode		-	0.7	1.5	μs
	200 mV step with 100 mV			-	0.3	0.6	
	overdrive		$V_{DDA} \ge 2.7 V$	-	50	100	μs
4		High speed mode	V_{DDA} < 2.7 V	-	100	240	
t _D		Ultra-low-power mode		-	2	7	
	Propagation delay for full	Low-power mode		-	0.7	2.1	μs
	range step with 100 mV	Medium power mode		-	0.3	1.2	
	overdrive	Lligh aroud mode	$V_{DDA} \ge 2.7 V$	-	90	180	mV s ms µs us ns
		High speed mode	V _{DDA} < 2.7 V	-	110	300	ns
V _{offset}	Comparator offset error	-		-	±4	±10	mV
dV _{offset} /dT	Offset error temperature coefficient	-		-	18	-	
		Ultra-low-power mode		-	1.2	1.5	
	COMP current	Low-power mode		-	3	5	
I _{DD(COMP)}	consumption	Medium power mode		-	10	15	μA
		High speed mode		-	75	100	1

Table 76. Comparator characteristics⁽¹⁾



Symbol	Parameter	Conditio	ons	Min	Тур	Max	Unit
		No hysteresis (COMPxHYST[1:0]=00)	-	-	0	-	
		Low hysteresis	High speed mode	3		- 13 10 26	
		(COMPxHYST[1:0]=01)	All other power modes	5	8	10	
V _{hys}	Comparator hysteresis	Madium byotorogia	High speed mode	7		26	mV
		Medium hysteresis (COMPxHYST[1:0]=10)	All other power modes	9	15	19	
		High hysteresis	High speed mode	18		49	
		(COMPxHYST[1:0]=11)	All other power modes	19	31	40	

Table 76. Co	omparator	characteristics ⁽¹⁾	(continued)
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1. Data guaranteed by design, not tested in production.

2. For more details and conditions, see Figure 36 Maximum V_{REFINT} scaler startup time from power down.



Figure 36. Maximum V_{REFINT} scaler startup time from power down



6.3.21 Operational amplifier characteristics

Symbol	Paramete	er	Condition	Min	Тур	Max	Unit
V _{DDA}	Analog supply voltage	е	-	2.4	-	3.6	V
CMIR	Common mode input	range	-	0	-	V _{DDA}	V
		laximum	25°C, No Load on output.	-	-	4	
\ <i>4</i>		alibration ange	All voltage/Temp.	-	-	6	
VI _{OFFSET}	voltage At	fter offset	25°C, No Load on output.	-	-	1.6	mV
	Ca	alibration	All voltage/Temp.	-	-	3	
ΔVI_{OFFSET}	Input offset voltage d	nput offset voltage drift		-	5	-	µV/°C
I _{LOAD}	Drive current		-	-	-	500	μA
IDDOPAMP	Consumption	onsumption f		-	690	1450	μA
TS_OPAMP_VOUT	ADC sampling time w the OPAMP output.	DC sampling time when reading e OPAMP output.		400	-	-	ns
CMRR	Common mode rejection ratio		-	-	90	-	dB
PSRR	Power supply rejection ratio		DC	73	117	-	dB
GBW	Bandwidth		-	-	8.2	-	MHz
SR	Slew rate		-	-	4.7	-	V/µs
R _{LOAD}	Resistive load		-	4	_	-	kΩ
C _{LOAD}	Capacitive load		-	-	-	50	pF
VOH		20	R _{load} = min, Input at V _{DDA} .	-	-	100	
VOH _{SAT}	High saturation voltage		R _{load} = 20K, Input at V _{DDA} .	-	-	20	
VOL	Low saturation voltag	10	Rload = min, input at 0V	-	-	100	mV
VOL _{SAT}	Low Saturation Voltag	je	Rload = 20K, input at 0V.	-	-	20	
φm	Phase margin		-	-	62	-	0
tofftrim	Offset trim time: durir minimum time neede two steps to have 1 n	d between	-	-	-	2	ms
t _{wakeup}	Wake up time from O	OFF state.	$\begin{array}{l} C_{LOAD} \leq \!\! 50 \mbox{ pf}, \\ R_{LOAD} \geq 4 \mbox{ k}\Omega, \\ Follower \\ configuration \end{array}$	-	2.8	5	μs

Table 77. Operational amplifier cha	aracteristics ⁽¹⁾
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Symbol	Parameter	Condition	Min	Тур	Max	Unit
			-	2	-	-
	Non inverting gain value		-	4	-	-
PGA gain	Non inverting gain value	-	-	8	-	-
			-	16	-	-
		Gain=2	-	5.4/5.4	-	
	R2/R1 internal resistance values in	Gain=4	-	16.2/5.4	-	ko
R _{network}	PGA mode ⁽²⁾	Gain=8	-	37.8/5.4	-	kΩ
		Gain=16	-	40.5/2.7	-	
PGA gain error	PGA gain error	-	-1%	-	1%	
I _{bias}	OPAMP input bias current	-	-	-	±0.2 ⁽³⁾	μA
		PGA Gain = 2, Cload = 50pF, Rload = 4 KΩ	-	4	-	
PGA BW	PGA bandwidth for different non inverting gain	PGA Gain = 4, Cload = 50pF, Rload = 4 KΩ	-	2	-	MHz
PGA BW		PGA Gain = 8, Cload = 50pF, Rload = 4 KΩ	-	1	-	
		PGA Gain = 16, Cload = 50pF, Rload = 4 KΩ	-	0.5	-	
		 @ 1KHz, Output loaded with 4 KΩ 	-	109	-	
en	Voltage noise density	@ 10KHz, Output loaded with 4 KΩ	-	43	-	$\frac{nV}{\sqrt{Hz}}$

Table 77. Operational amplifier characteristics⁽¹⁾ (continued)

1. Guaranteed by design, not tested in production.

 R2 is the internal resistance between OPAMP output and OPAMP inverting input. R1 is the internal resistance between OPAMP inverting input and ground. The PGA gain =1+R2/R1

3. Mostly TTa I/O leakage, when used in analog mode.





Figure 37. OPAMP voltage noise versus frequency



6.3.22 Temperature sensor characteristics

Symbol	Parameter	Min	Тур	Max	Unit			
T _L ⁽¹⁾	V _{SENSE} linearity with temperature	-	±1	<u>+2</u>	°C			
Avg_Slope ⁽¹⁾	Average slope	4.0	4.3	4.6	mV/°C			
V ₂₅	Voltage at 25 °C	1.34	1.43	1.52	V			
t _{START} ⁽¹⁾	Startup time	4	-	10	μs			
T _{S_temp} ⁽¹⁾⁽²⁾	ADC sampling time when reading the temperature	2.2	-	-	μs			

Table 78. TS characteristics

1. Guaranteed by design, not tested in production.

2. Shortest sampling time can be determined in the application by multiple iterations.

Calibration value name	Description	Memory address
TS_CAL1	TS ADC raw data acquired at temperature of 30 °C, V _{DDA} = 3.3 V	0x1FFF F7B8 - 0x1FFF F7B9
TS_CAL2	TS ADC raw data acquired at temperature of 110 °C V _{DDA} = 3.3 V	0x1FFF F7C2 - 0x1FFF F7C3

6.3.23 V_{BAT} monitoring characteristics

Symbol	Parameter	Min	Тур	Мах	Unit				
R	Resistor bridge for V _{BAT}	-	50	-	KΩ				
Q	Ratio on V _{BAT} measurement	-	2	-					
Er ⁽¹⁾	Error on Q	-1	-	+1	%				
T _{S_vbat} ⁽¹⁾⁽²⁾	ADC sampling time when reading the V_{BAT} 1mV accuracy	2.2	-	-	μs				

Table 80. V_{BAT} monitoring characteristics

1. Guaranteed by design, not tested in production.

2. Shortest sampling time can be determined in the application by multiple iterations.



7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

7.1 LQFP100 – 14 x 14 mm, low-profile quad flat package information



Figure 38. LQFP100 – 14 x 14 mm, low-profile quad flat package outline

1. Drawing is not to scale.

Table 81. LQPF100 – 14 x 14 mm, low-profile quad flat package mechanical data

Symbol	millimeters		llimeters inche		millimeters		inches ⁽¹⁾	
Symbol	Min	Тур	Max	Min	Тур	Max		
А	-	-	1.60	-	-	0.063		
A1	0.05	-	0.15	0.002	-	0.0059		



Symbol		millimeters		inches ⁽¹⁾		
	Min	Тур	Мах	Min	Тур	Max
A2	1.35	1.40	1.45	0.0531	0.0551	0.0571
b	0.17	0.22	0.27	0.0067	0.0087	0.0106
С	0.09	-	0.2	0.0035	-	0.0079
D	15.80	16.00	16.2	0.622	0.6299	0.6378
D1	13.80	14.00	14.2	0.5433	0.5512	0.5591
D3	-	12.00	-	-	0.4724	-
Е	15.80	16.00	16.2	0.622	0.6299	0.6378
E1	13.80	14.00	14.2	0.5433	0.5512	0.5591
E3	-	12.00	-	-	0.4724	-
е	-	0.50	-	-	0.0197	-
L	0.45	0.60	0.75	0.0177	0.0236	0.0295
L1	-	1.00	-	-	0.0394	-
K	0°	3.5°	7°	0°	3.5°	7°
CCC	-	-	0.08	-	-	0.0031

Table 81. LQPF100 – 14 x 14 mm, low-profile guad flat package mechanical data (continued)

1. Values in inches are converted from mm and rounded to 4 decimal digits.





1. Dimensions are in millimeters.



Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.





 Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.



7.2 LQFP64 – 10 x 10 mm, low-profile quad flat package information



Figure 41. LQFP64 – 10 x 10 mm, low-profile quad flat package outline

1. Drawing is not to scale.

Table 82. LQFP64 – 10 x 10 mm, low-profile quad flat package mechanical	
data	

Symbol		millimeters			inches ⁽¹⁾		
Symbol	Min	Тур	Max	Min	Тур	Max	
А	-	-	1.60	-	-	0.0630	
A1	0.05	-	0.15	0.0020	-	0.0059	
A2	1.350	1.40	1.45	0.0531	0.0551	0.0571	
b	0.17	0.22	0.27	0.0067	0.0087	0.0106	
с	0.09	-	0.20	0.0035		0.0079	
D	-	12.00	-	-	0.4724	-	
D1	-	10.00	-	-	0.3937	-	
D3	-	7.50	-	-	0.2953	-	
E	-	12.00	-	-	0.4724	-	



(continued)								
Cumb al		millimeters			inches ⁽¹⁾			
Symbol	Min	Тур	Max	Min	Тур	Мах		
E1	-	10.00	-	-	0.3937	-		
E3	-	7.50	-	-	0.2953	-		
е	-	0.50	-	-	0.0197	-		
К	0°	3.5°	7°	0°	3.5°	7°		
L	0.45	0.60	0.75	0.0177	0.0236	0.0295		
L1	-	1.00	-	-	0.0394	-		
CCC	-	-	0.08	-	-	0.0031		

Table 82. LQFP64 – 10 x 10 mm, low-profile quad flat package mechanical data (continued)

1. Values in inches are converted from mm and rounded to 4 decimal digits.





1. Dimensions are in millimeters.



Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.





 Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.



7.3 LQFP48 – 7 x 7 mm, low-profile quad flat package information



Figure 44. LQFP48 – 7 x 7 mm, low-profile quad flat package outline

1. Drawing is not to scale.



Symbol		millimeters			inches ⁽¹⁾	
	Min	Тур	Мах	Min	Тур	Мах
А	-	-	1.60	-	-	0.0630
A1	0.05	-	0.15	0.0020	-	0.0059
A2	1.35	1.40	1.45	0.0531	0.0551	0.0571
b	0.17	0.22	0.27	0.0067	0.0087	0.0106
С	0.09	-	0.20	0.0035	-	0.0079
D	8.80	9.00	9.20	0.3465	0.3543	0.3622
D1	6.80	7.00	7.20	0.2677	0.2756	0.2835
D3	-	5.50	-	-	0.2165	-
Е	8.80	9.00	9.20	0.3465	0.3543	0.3622



	()						
Symbol	millimeters			inches ⁽¹⁾			
Symbol	Min	Тур	Max	Min Typ		Мах	
E1	6.80	7.00	7.20	0.2677	0.2756	0.2835	
E3	-	5.50	-	-	0.2165	-	
е	-	0.50	-	-	0.0197	-	
L	0.45	0.60	0.75	0.0177	0.0236	0.0295	
L1	-	1.00	-	-	0.0394	-	
К	0°	3.5°	7°	0°	3.5°	7°	
CCC	-	-	0.08	-	-	0.0031	

Table 83. LQFP48 – 7 x 7 mm, low-profile quad flat package mechanical data (continued)

1. Values in inches are converted from mm and rounded to 4 decimal digits.





1. Dimensions are in millimeters.



Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.





 Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.



7.4 Thermal characteristics

The maximum chip junction temperature (T_J max) must never exceed the values given in *Table 24: General operating conditions on page 56.*

The maximum chip-junction temperature, $T_{\rm J}$ max, in degrees Celsius, may be calculated using the following equation:

$$T_J max = T_A max + (P_D max x \Theta_{JA})$$

Where:

- T_A max is the maximum ambient temperature in °C,
- Θ_{JA} is the package junction-to-ambient thermal resistance, in ° C/W,
- P_D max is the sum of P_{INT} max and P_{I/O} max (P_D max = P_{INT} max + P_{I/O}max),
- P_{INT} max is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.

 $\mathsf{P}_{\mathsf{I}\!/\!\mathsf{O}}$ max represents the maximum power dissipation on output pins where:

 $\mathsf{P}_{\mathsf{I}/\mathsf{O}} \max = \Sigma \; (\mathsf{V}_{\mathsf{OL}} \times \mathsf{I}_{\mathsf{OL}}) + \Sigma ((\mathsf{V}_{\mathsf{DD}} - \mathsf{V}_{\mathsf{OH}}) \times \mathsf{I}_{\mathsf{OH}}),$

taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Symbol	Parameter	Value	Unit
	Thermal resistance junction-ambient LQFP64 - 10 × 10 mm / 0.5 mm pitch	45	
Θ_{JA}	Thermal resistance junction-ambient LQFP48 - 7 × 7 mm	55	°C/W
	Thermal resistance junction-ambient LQFP100 - 14 × 14 mm / 0.5 mm pitch	41	

Table 84. Package thermal characteristics

7.4.1 Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org



7.4.2 Selecting the product temperature range

When ordering the microcontroller, the temperature range is specified in the ordering information scheme shown in *Section 8: Part numbering*.

Each temperature range suffix corresponds to a specific guaranteed ambient temperature at maximum dissipation and, to a specific maximum junction temperature.

As applications do not commonly use the STM32F302xB/STM32F302xC at maximum dissipation, it is useful to calculate the exact power consumption and junction temperature to determine which temperature range will be best suited to the application.

The following examples show how to calculate the temperature range needed for a given application.

Example 1: High-performance application

Assuming the following application conditions:

Maximum ambient temperature $T_{Amax} = 82$ °C (measured according to JESD51-2), $I_{DDmax} = 50$ mA, $V_{DD} = 3.5$ V, maximum 3 I/Os used at the same time in output at low level with $I_{OL} = 8$ mA, $V_{OL} = 0.4$ V and maximum 2 I/Os used at the same time in output at low level with $I_{OL} = 20$ mA, $V_{OL} = 1.3$ V

P_{INTmax} = 50 mA × 3.5 V= 175 mW

P_{IOmax} = 3 × 8 mA × 0.4 V + 2 × 20 mA × 1.3 V = 61.6 mW

This gives: P_{INTmax} = 175 mW and P_{IOmax} = 61.6 mW:

 $P_{Dmax} = 175 + 61.6 = 236.6 \text{ mW}$

Thus: $P_{Dmax} = 236.6 \text{ mW}$

Using the values obtained in *Table 84* T_{Jmax} is calculated as follows:

– For LQFP64, 45°C/W

T_{Jmax} = 82 °C + (45°C/W × 236.6 mW) = 82 °C + 10.65 °C = 92.65 °C

This is within the range of the suffix 6 version parts ($-40 < T_J < 105$ °C).

In this case, parts must be ordered at least with the temperature range suffix 6 (see *Section 8: Part numbering*).



Example 2: High-temperature application

Using the same rules, it is possible to address applications that run at high ambient temperatures with a low dissipation, as long as junction temperature T_J remains within the specified range.

Assuming the following application conditions:

Maximum ambient temperature $T_{Amax} = 115 \text{ °C}$ (measured according to JESD51-2), $I_{DDmax} = 20 \text{ mA}, V_{DD} = 3.5 \text{ V}$, maximum 9 I/Os used at the same time in output at low level with $I_{OL} = 8 \text{ mA}, V_{OL} = 0.4 \text{ V}$ $P_{INTmax} = 20 \text{ mA} \times 3.5 \text{ V} = 70 \text{ mW}$ $P_{IOmax} = 9 \times 8 \text{ mA} \times 0.4 \text{ V} = 28.8 \text{ mW}$ This gives: $P_{INTmax} = 70 \text{ mW}$ and $P_{IOmax} = 28.8 \text{ mW}$: $P_{Dmax} = 70 + 28.8 = 98.8 \text{ mW}$

Thus: P_{Dmax} = 98.8 mW

Using the values obtained in *Table 84* T_{Jmax} is calculated as follows:

- For LQFP100, 41°C/W

This is within the range of the suffix 7 version parts ($-40 < T_J < 125$ °C).

In this case, parts must be ordered at least with the temperature range suffix 7 (see *Section 8: Part numbering*).



8 Part numbering

Example:	STM32	F	302	R	В	Т	6	xxx
Device family								
STM32 = ARM-based 32-bit microcontroller								
Product type								
F = general-purpose								
Device subfamily								
302 = STM32F302xx								
Pin count								
C = 48 pins								
R = 64 pins								
V = 100 pins								
Flash memory size								
B = 128 Kbytes of Flash memory								
C = 256 Kbytes of Flash memory								
Package								
T = LQFP								
Temperature range								
6 = Industrial temperature range, -40 to 85 °C								
7 = Industrial temperature range, -40 to 105 °C								
Options								

Table 85. Ordering information scheme

xxx = programmed parts

TR = tape and reel

For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.



9 Revision history

Date	Revision	Changes
21-Nov-2013	1	Initial release
16-Apr-2014	2	 Updated Table 38: Peripheral current consumption. Updated SRAM size in Table 2: STM32F302xx family device features and peripheral counts, Cover page and description. Updated Section 6.3.17: Communications interfaces I²C interface. Updated Table 50: EMI characteristics conditions :3.3v replaced by 3.6V. Updated Table 77: Operational amplifier characteristics adding TS_OPAMP_VOUT row. Updated Section 3.13: Fast analog-to-digital converter (ADC). updated Table 32: Typical and maximum VDD consumption in Stop and Standby modes with Max value at 85°C and 105°C. Updated Table 70: ADC accuracy - limited test conditions, 100-pin packages and Table 71: ADC accuracy, 100-pin packages for 100-pin package. Added Table 72: ADC accuracy at 1MSPS for 1MSPS sampling frequency. Updated Table 63: SPI characteristics. Updated Table 63: SPI characteristics. Updated Table 63: SPI characteristics. Updated Table 75: DAC characteristics. Updated Table 63: SPI characteristics. Updated Table 63: SPI characteristics. Updated Table 75: DAC characteristics. Updated Table 75: DAC characteristics. Updated Table 75: DAC characteristics.

Table 86.	Document	revision	history
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	Table 86. Document revision history (continued)				
Date	Revision	Changes			
09-Dec-2014	3	Updated core description in cover page. Updated HSI characteristics <i>Table 44: HSI oscillator characteristics</i> and <i>Figure 17: HSI oscillator accuracy characterization results for soldered</i> <i>parts.</i> Updated <i>Table 58: TIMx characteristics.</i> Updated <i>Table 13: STM32F302xB/STM32F302xC pin definitions</i> adding note for I/Os featuring an analog output function (DAC_OUT,OPAMP_OUT). Updated <i>Table 68: ADC characteristics</i> adding IDDA & IREF consumptions. Added <i>Figure 31: ADC typical current consumption on VDDA pin</i> and <i>Figure 32: ADC typical current consumption on VDDA pin</i> and <i>Figure 32: ADC typical current consumption on VREF+ pin.</i> Added section 3.8: Interconnect matrix. Added note after <i>Table 32: Typical and maximum VDD consumption in</i> <i>Stop and Standby modes.</i> Updated Section : In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark. with new LQFP100, LQFP64, LQFP48 package marking. Updated <i>Table 13: STM32F302xB/STM32F302xC pin definitions</i> and alternate functions tables replacing usart_rts by usart_rts_de.			
29-Jan-2015	4	Updated cover page with ADC up to 17 channels. Updated Section 6.3.20: Comparator characteristics modifying ts_sc characteristics in Table 76 and adding Figure 36: Maximum VREFINT scaler startup time from power down. Updated I _{DD} data in Table 42: HSE oscillator characteristics.			
17-Apr-2015	5	Updated <i>Figure 1: STM32F302xB/STM32F302xC block diagram</i> changing 32 KB of SRAM by 40 KB of SRAM. Updated <i>Section 7: Package information</i> : with new package information structure adding 1 sub paragraph for each package. Updated <i>Figure 40: LQFP100 – 14 x 14 mm, low-profile quad flat</i> <i>package top view example</i> removing gate mark. Added note for all package device markings: "the following figure gives an example of topside marking orientation versus pin 1 identifier location". Updated <i>Table 82: LQFP64 – 10 x 10 mm, low-profile quad flat</i> <i>package mechanical data.</i> Updated <i>Table 4: STM32F302xB/STM32F302xC peripheral</i> <i>interconnect matrix</i> removing TIM8 reference and updating note below the table, replacing by a reference to RM0365.			

Table 86	. Document revision	history	(continued)
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